

MFrontier
美思先端

Name: NBP 2750 500nm

Base material: single-crystal silicon

Center wavelength (CWL): 2750±50nm

Half wave width (FWHM): 500±60nm

Peak Transmittance (Tp): >80%

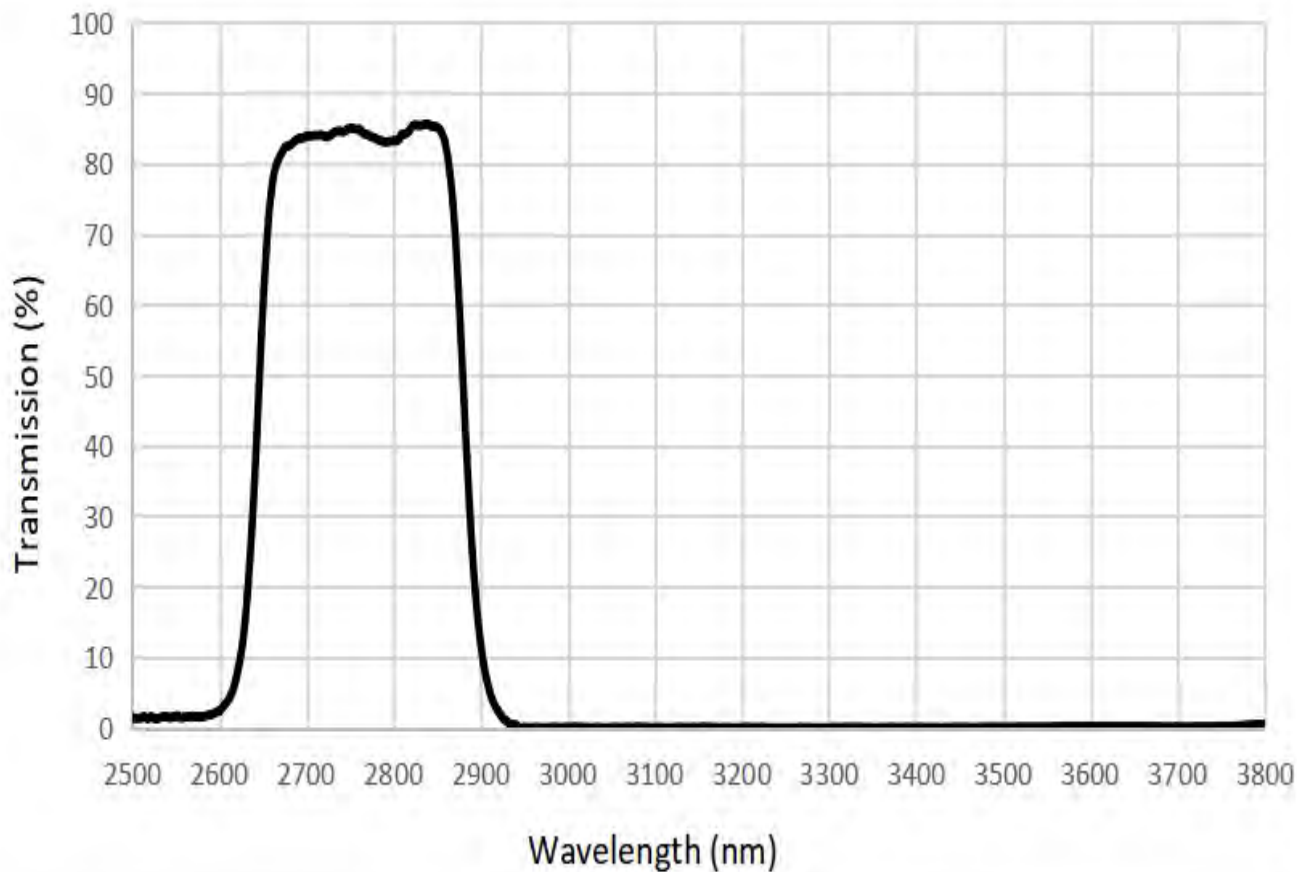
Cutoff range (Except for passband):

400-7000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



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Name: NBP 2775 250nm

Base material: single-crystal silicon

Center wavelength (CWL): 2775 ± 30 nm

Half wave width (FWHM): 250 ± 20 nm

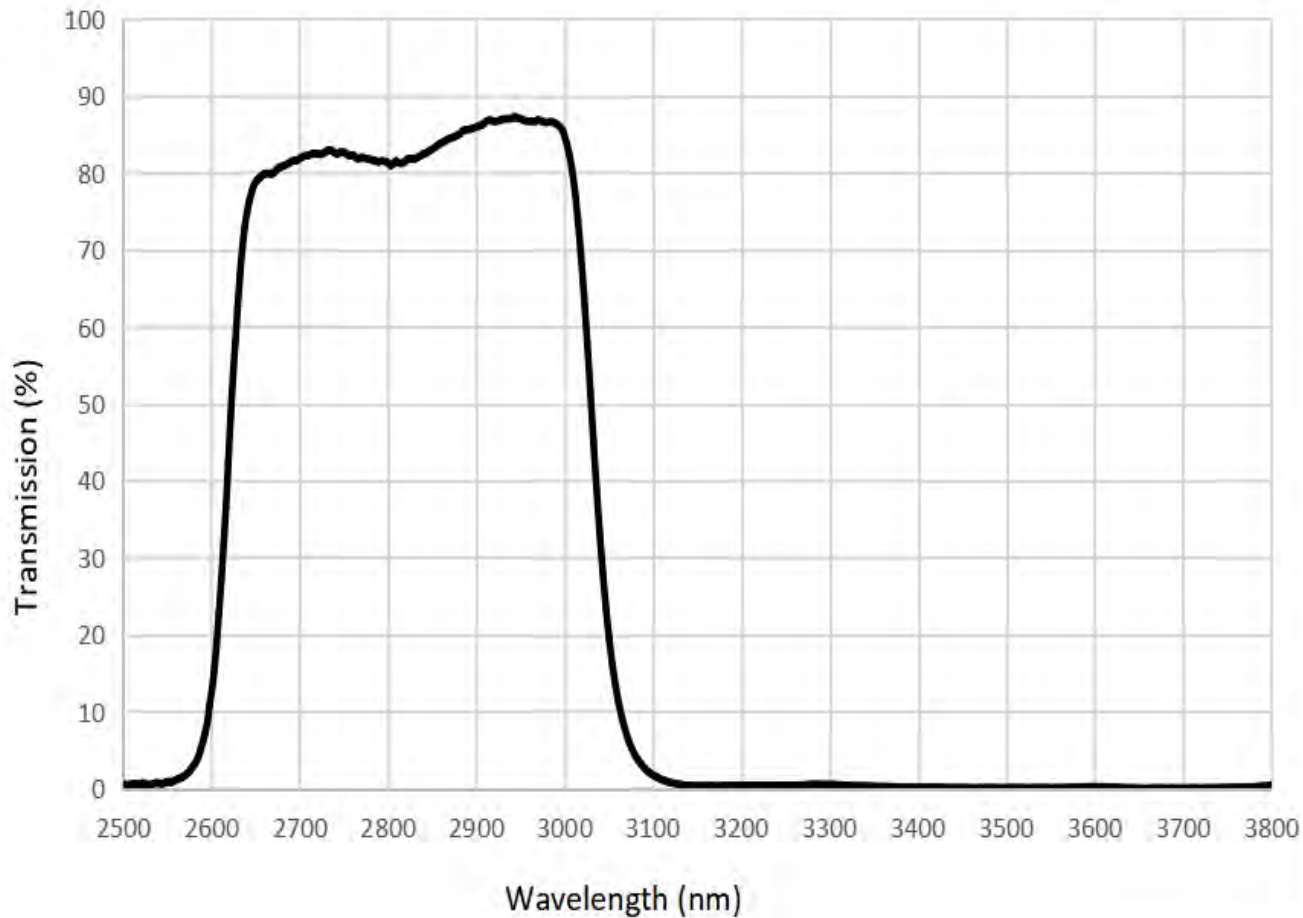
Peak Transmittance (T_p): > 80 %

Cutoff range (Except for passband): 400-7000nm

Cut-off depth: ≤ 1 %

Base material size: $\Phi 100 * 0.5$ mm

Cutting service available.

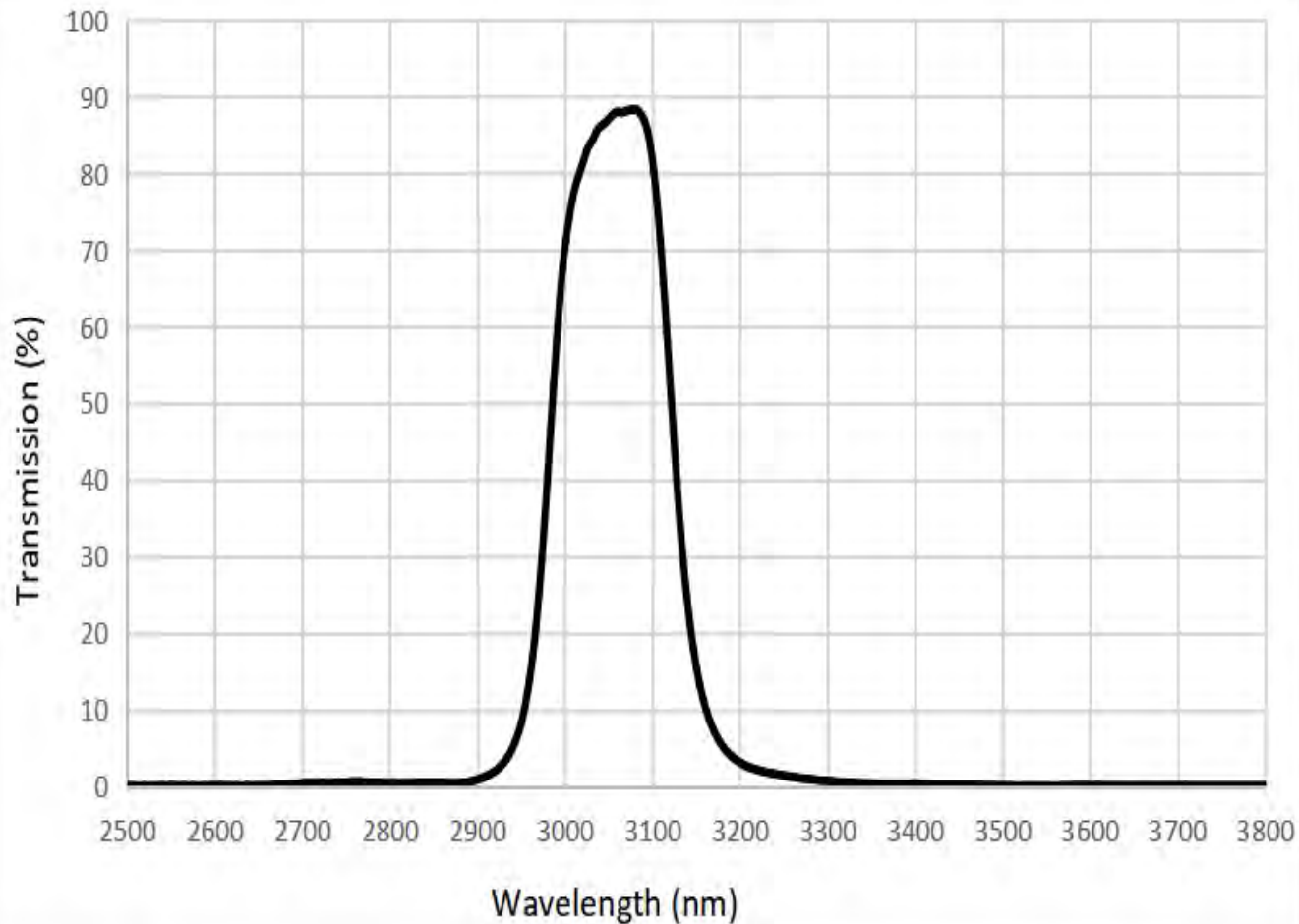


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Name: NBP 2850 400nm
Base material: single-crystal silicon
Center wavelength (CWL): $2850 \pm 40\text{nm}$
Half wave width (FWHM): $400 \pm 30\text{nm}$
Peak Transmittance (T_p): $> 80\%$
cutoff range (Except for passband): 400-7000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5\text{mm}$

Cutting service available.

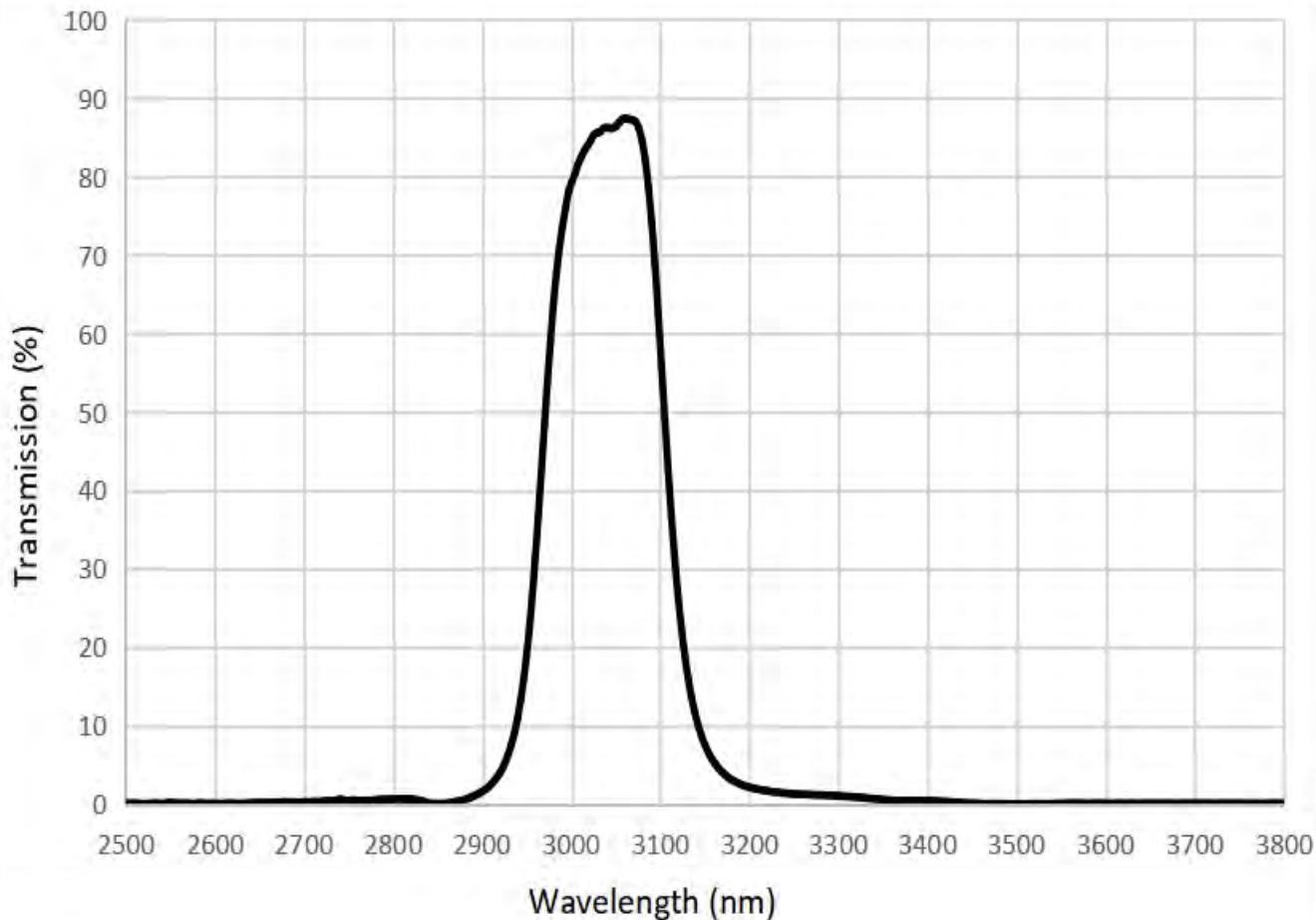


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Name: NBP 3040 140nm
Base material: single-crystal silicon
Center wavelength (CWL): 3040 ±30nm
Half wave width (FWHM): 140±20nm
Peak Transmittance (Tp): >80%
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



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Name: NBP 3040 140nm

Base material: single-crystal silicon

Center wavelength (CWL): 3040 ±30nm

Half wave width (FWHM): 140±20nm

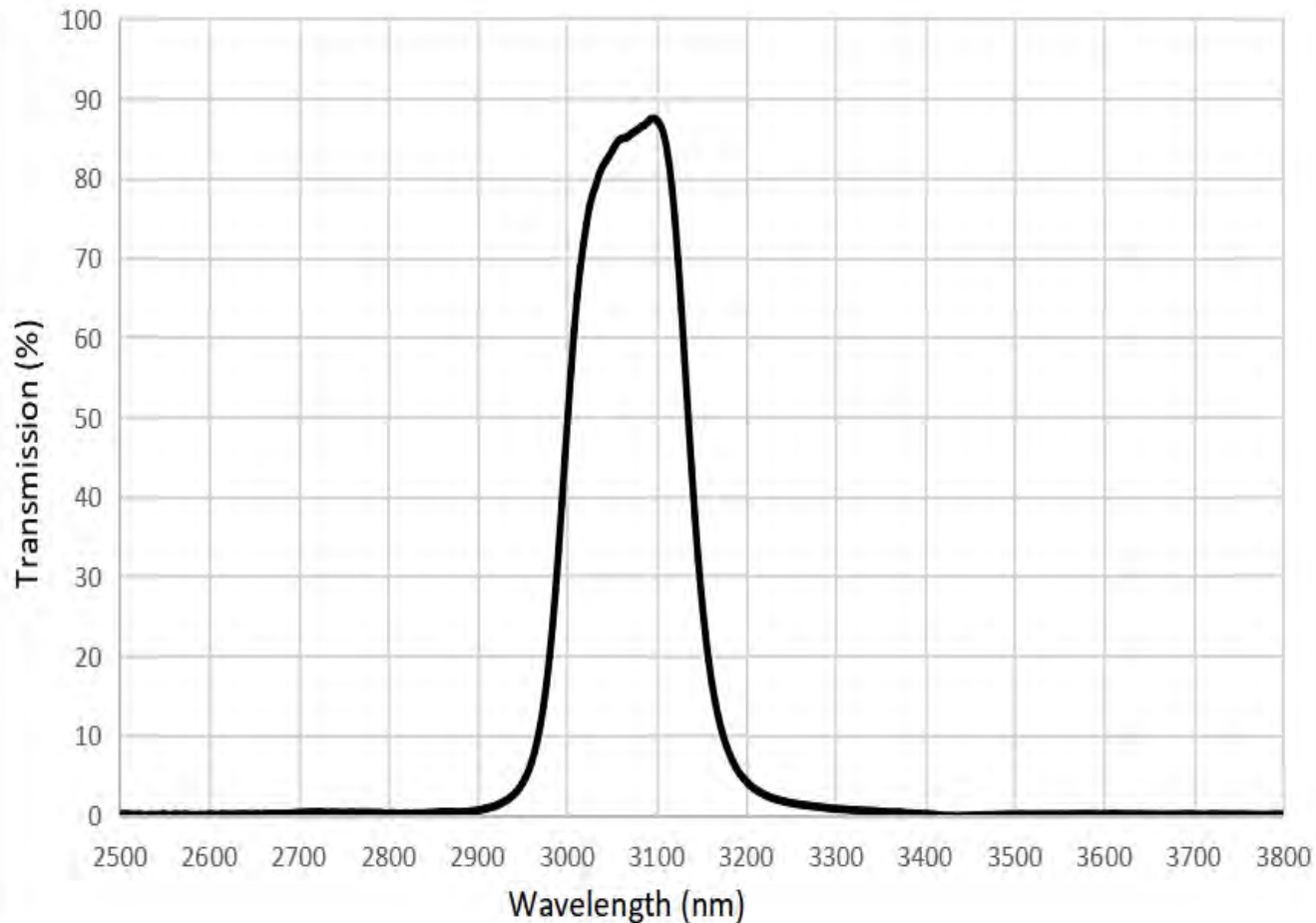
Peak Transmittance (Tp): > 80%

Cutoff range (Except for
passband): 400-11000nm

Cut-off depth: ≤1%

Base material size: Φ25*0.5mm

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Name: NBP 3060 140nm

Base material: single-crystal silicon

Center wavelength (CWL): 3060 ±30nm

Half wave width (FWHM): 140±20nm

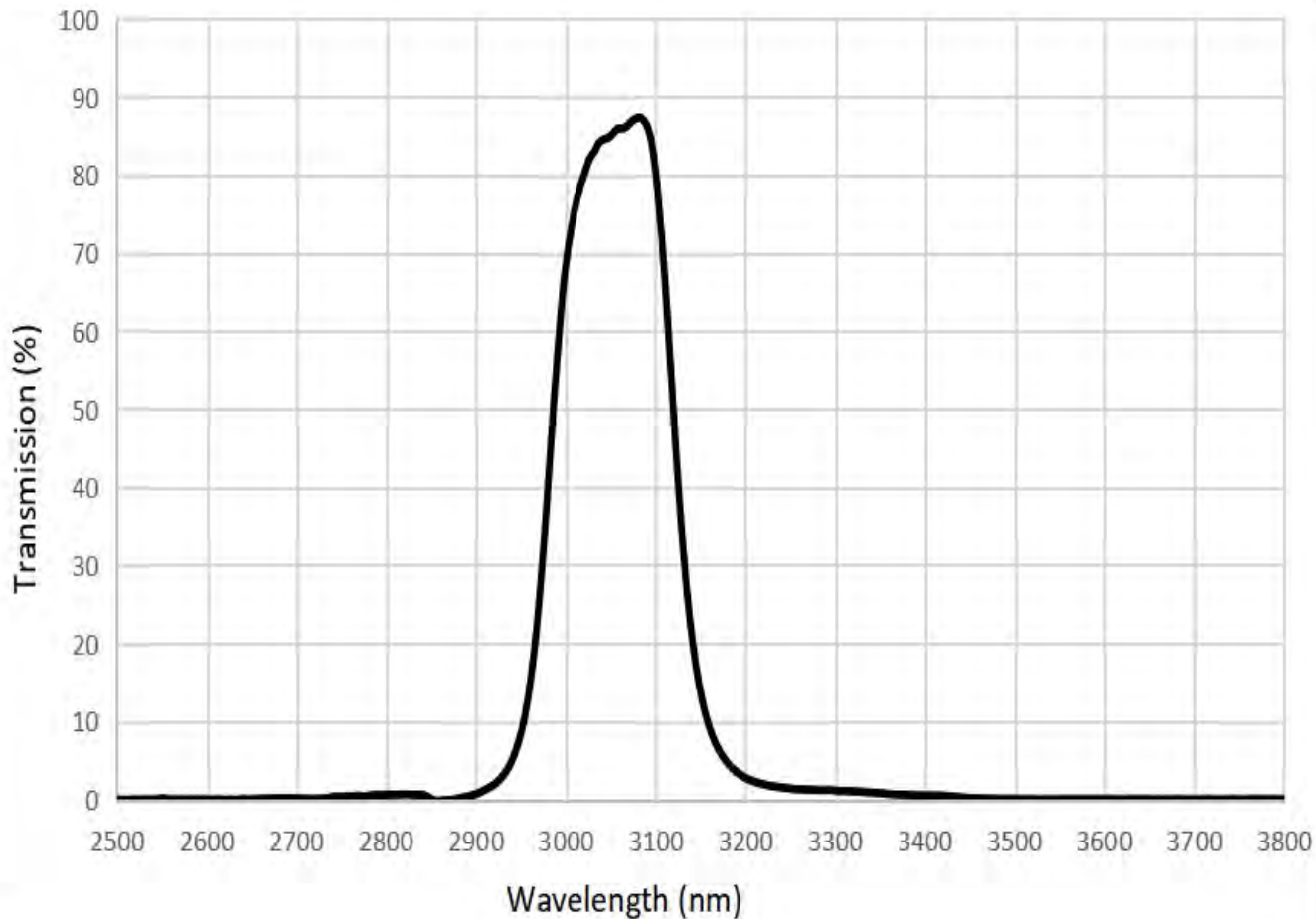
Peak Transmittance (Tp): >80%

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.

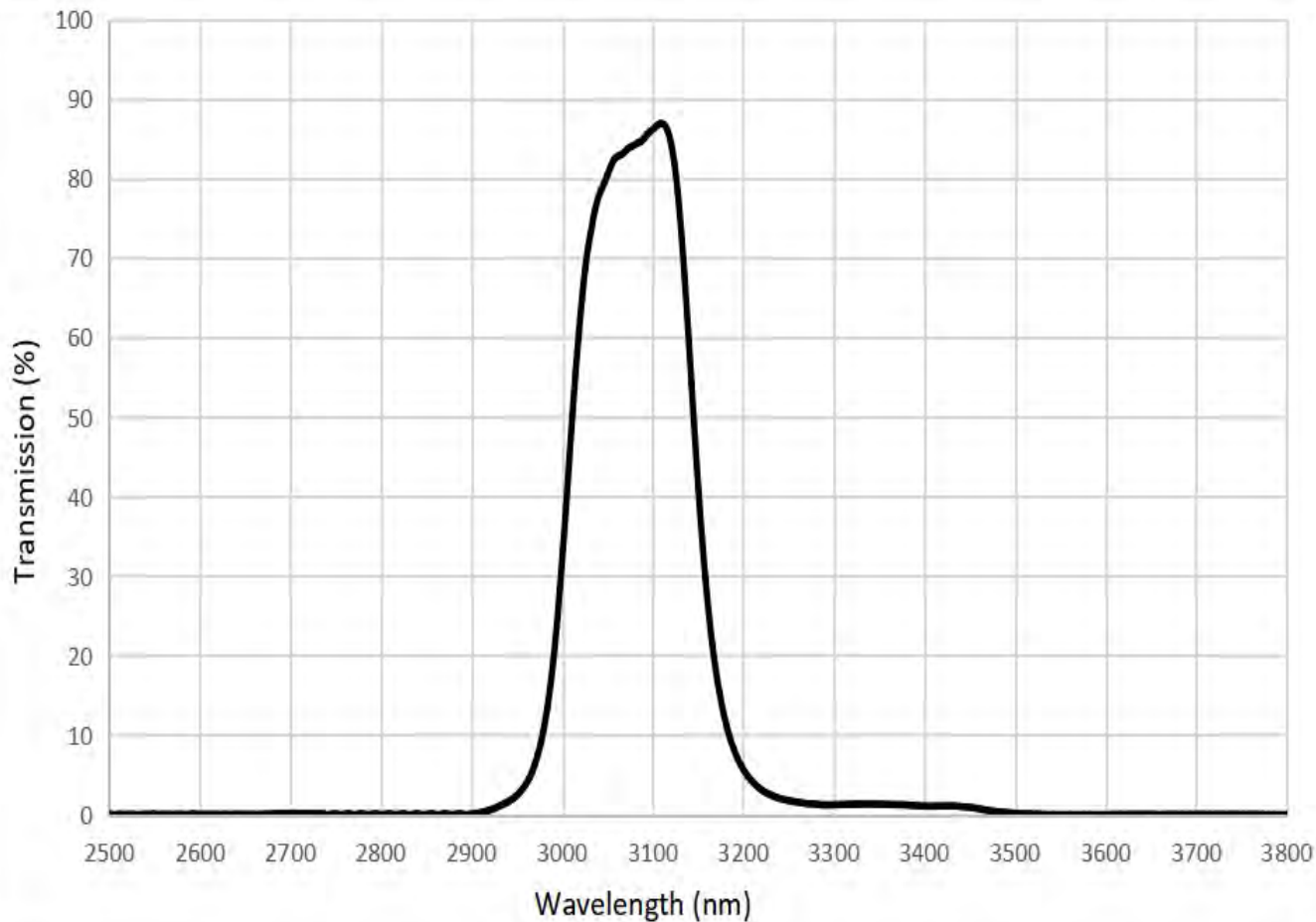


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Name: NBP 3060 140nm
Base material: single-crystal silicon
Center wavelength (CWL): 3060 ±30nm
Half wave width (FWHM): 140±20nm
Peak Transmittance (Tp): > 80%
cutoff range (Except for passband): 400-11000nm
Cut-off depth: ≤1%

Base material size: Φ25*0.5mm

Cutting service available.



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Name: NBP 3080 140nm

Base material: single-crystal silicon

Center wavelength (CWL): 3080 ± 30 nm

Half wave width (FWHM): 140 ± 20 nm

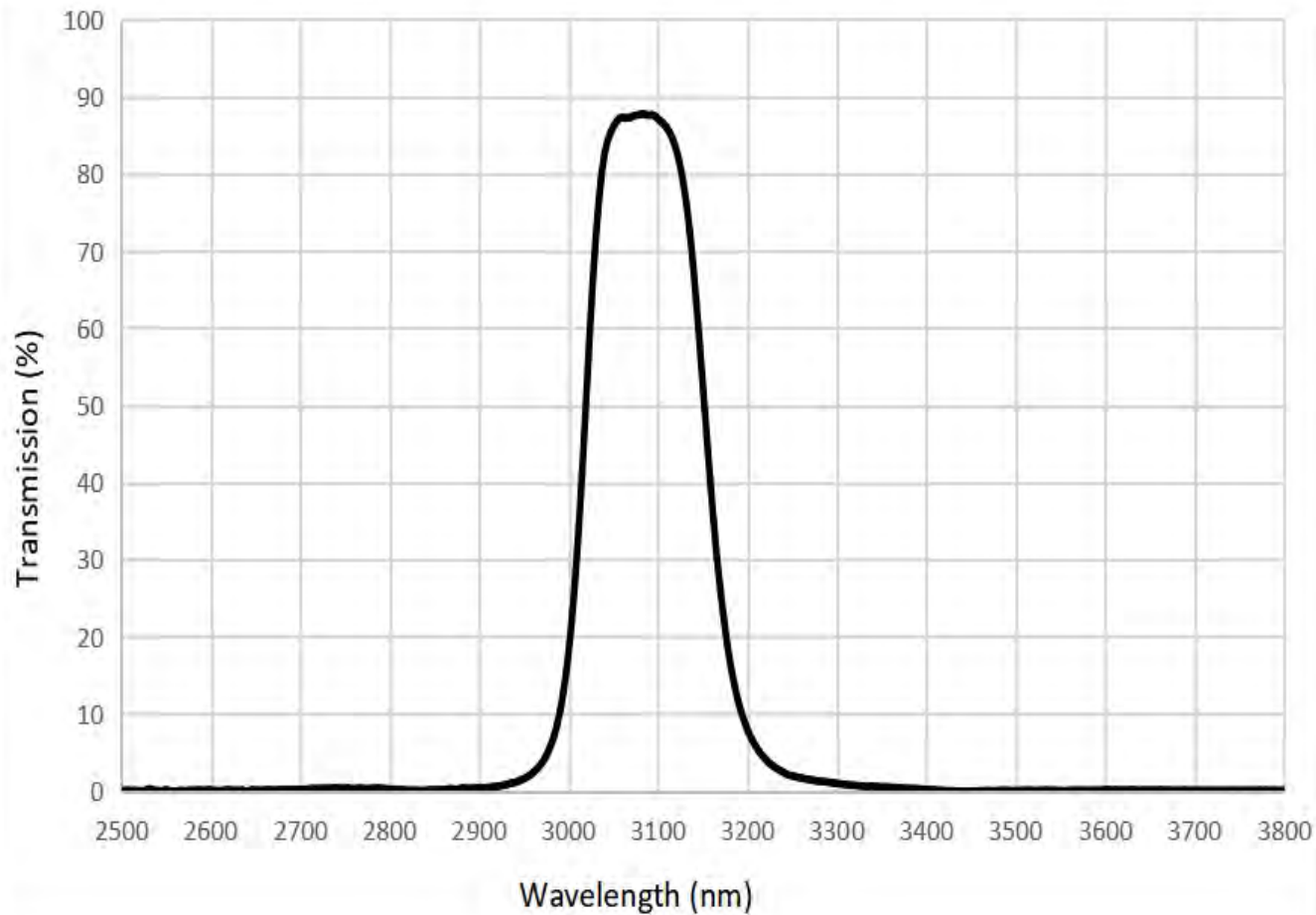
Peak Transmittance (T_p): $> 80\%$

cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.



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Name: NBP 3090 140nm

Base material: single-crystal silicon

Center wavelength (CWL): 3090±30nm

Half wave width (FWHM): 140±20nm

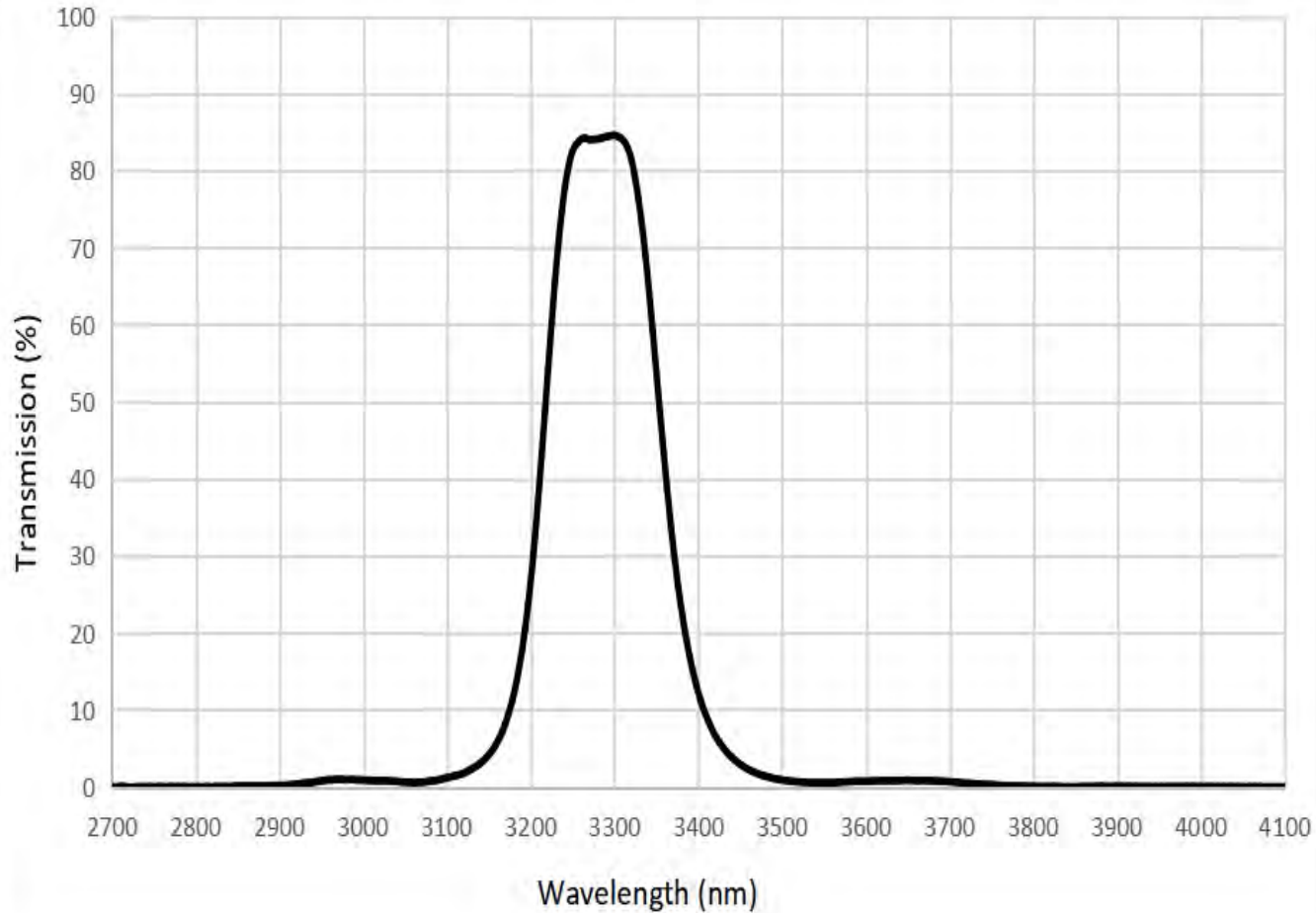
Peak Transmittance (Tp): >80%

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.

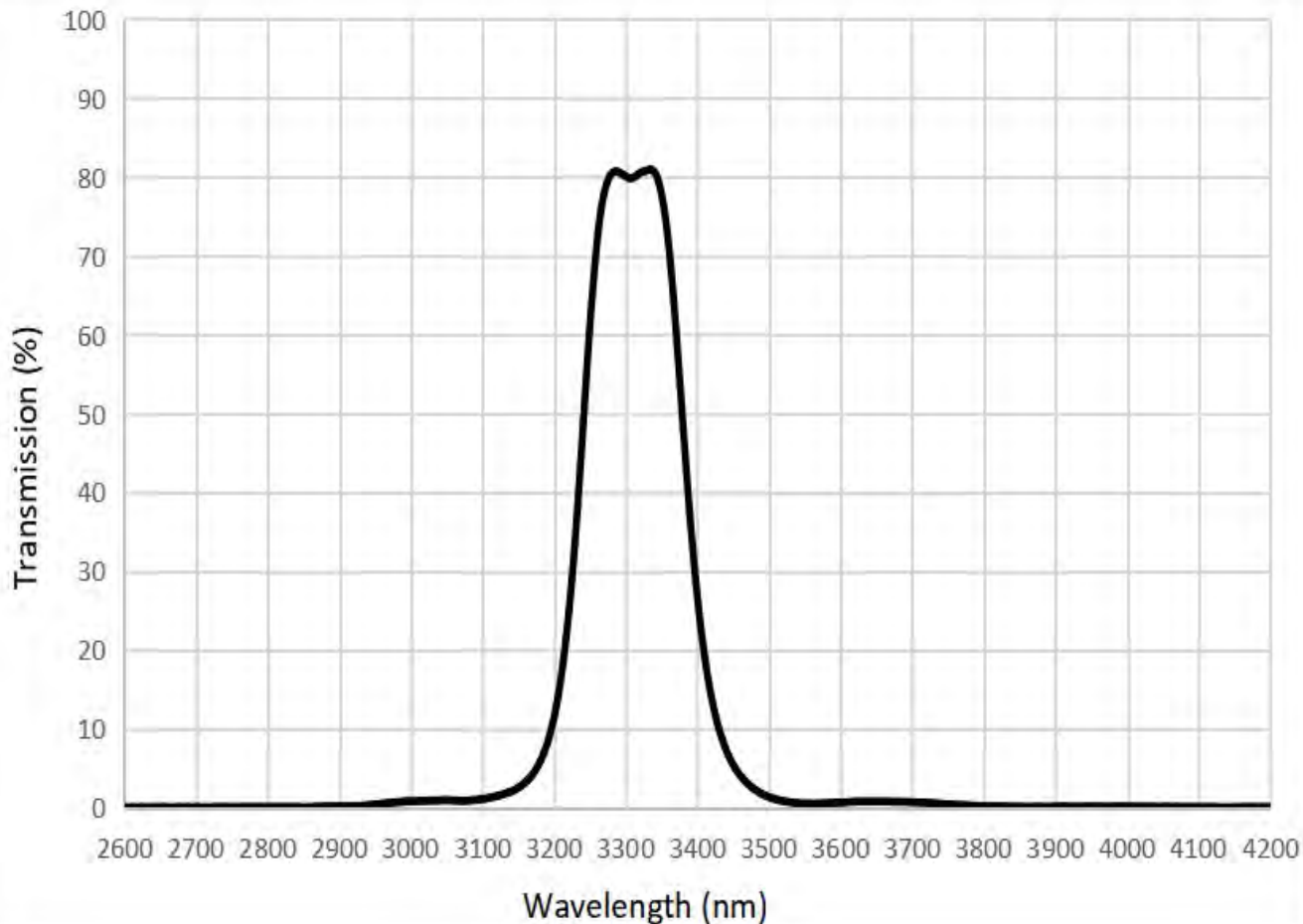


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Name: NBP 3280 160nm
Base material: single-crystal silicon
Center wavelength (CWL): $3280 \pm 30\text{nm}$
Half wave width (FWHM): $160 \pm 20\text{nm}$
Peak Transmittance (T_p): $> 80\%$
cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5\text{mm}$

Cutting service available.



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Name: NBP 3300 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 3300±30nm

Half wave width (FWHM): 160±20nm

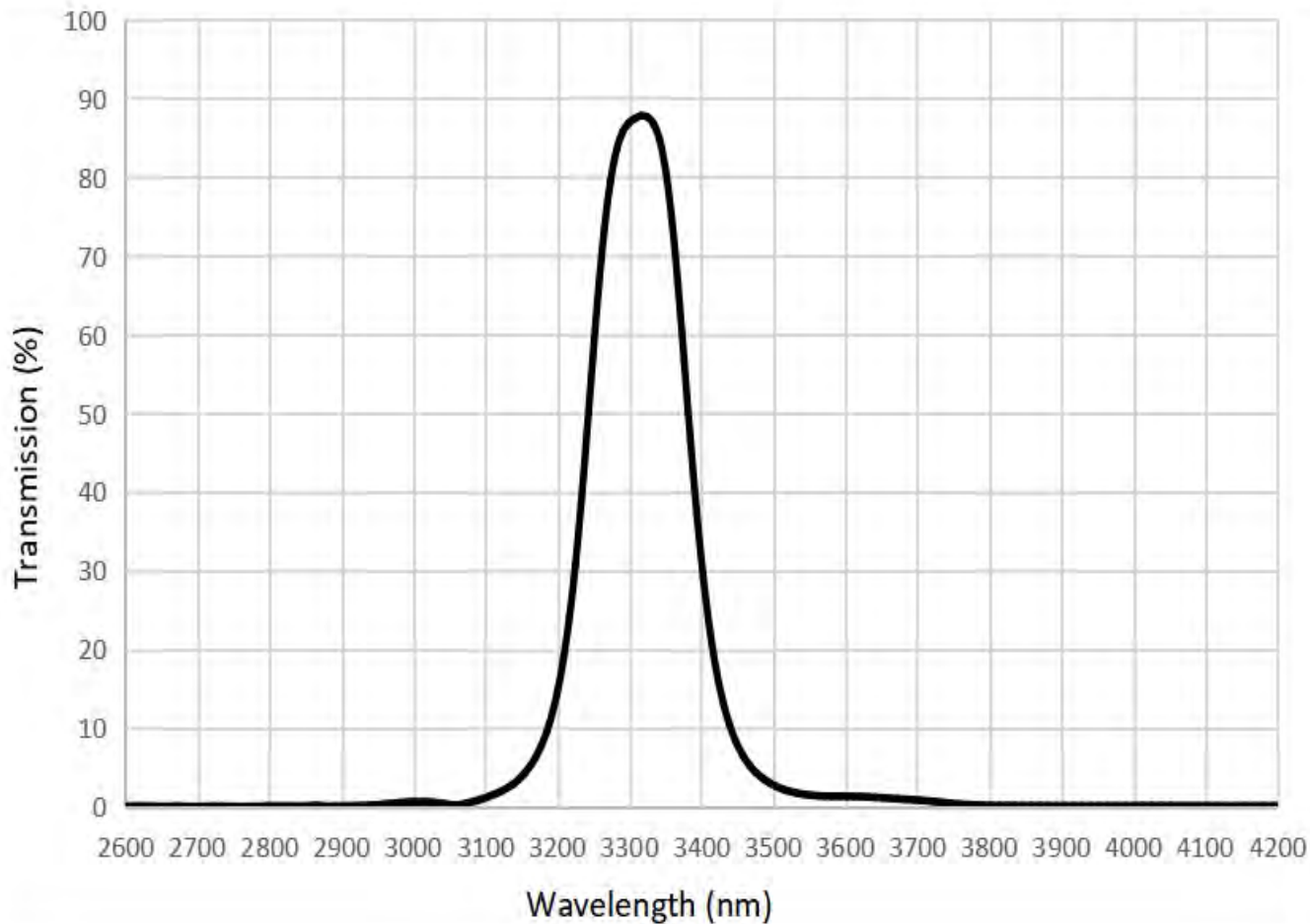
Peak Transmittance (Tp): >80%

cutoff range (Except for
passband): 400-11000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



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Name: NBP 3300 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 3300 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

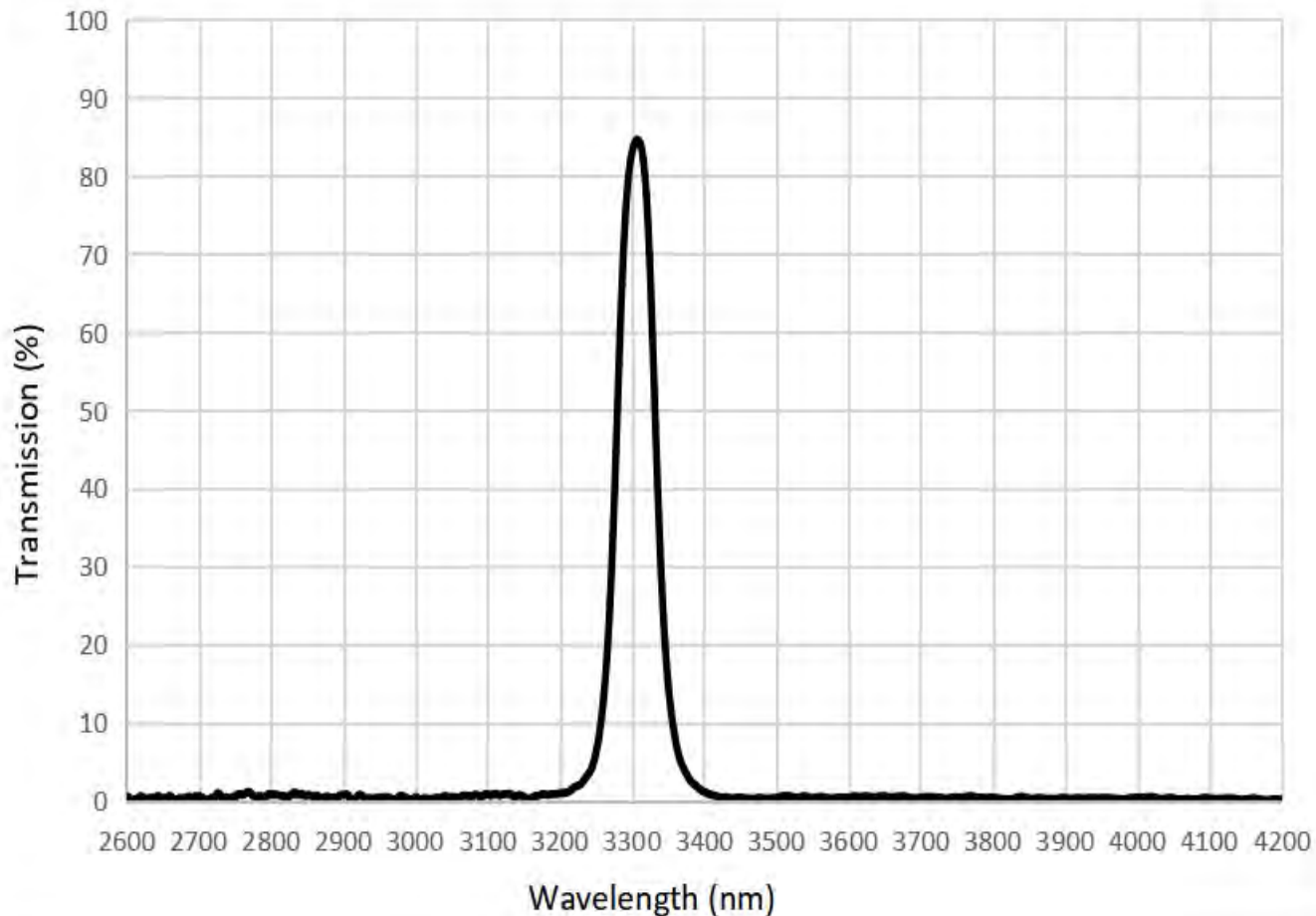
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 * 0.5$ mm

Cutting service available.



Name: NBP 3310 60nm

Base material: single-crystal silicon

Center wavelength (CWL): 3310 ± 10 nm

Half wave width (FWHM): 60 ± 20 nm

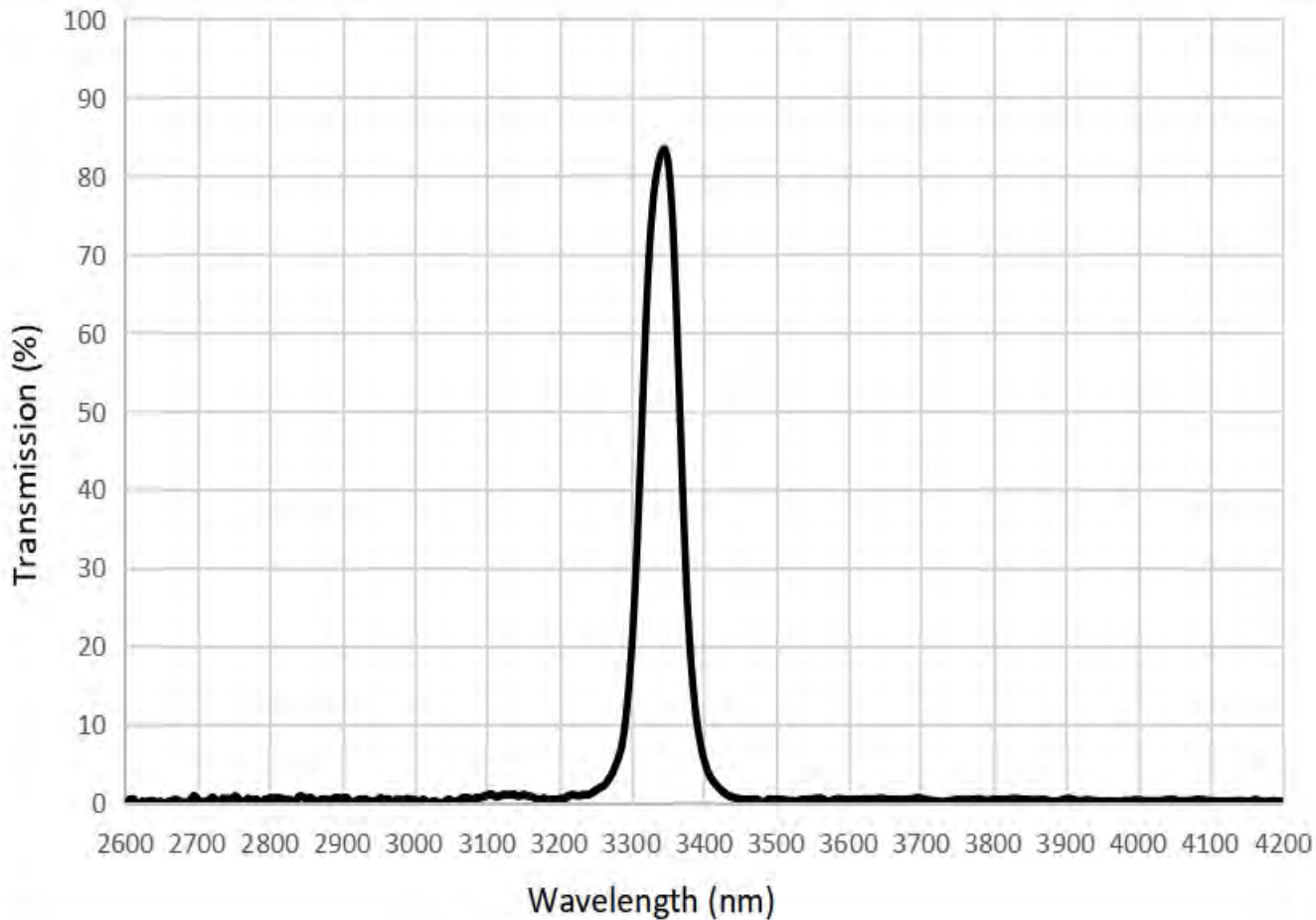
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-4700nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.

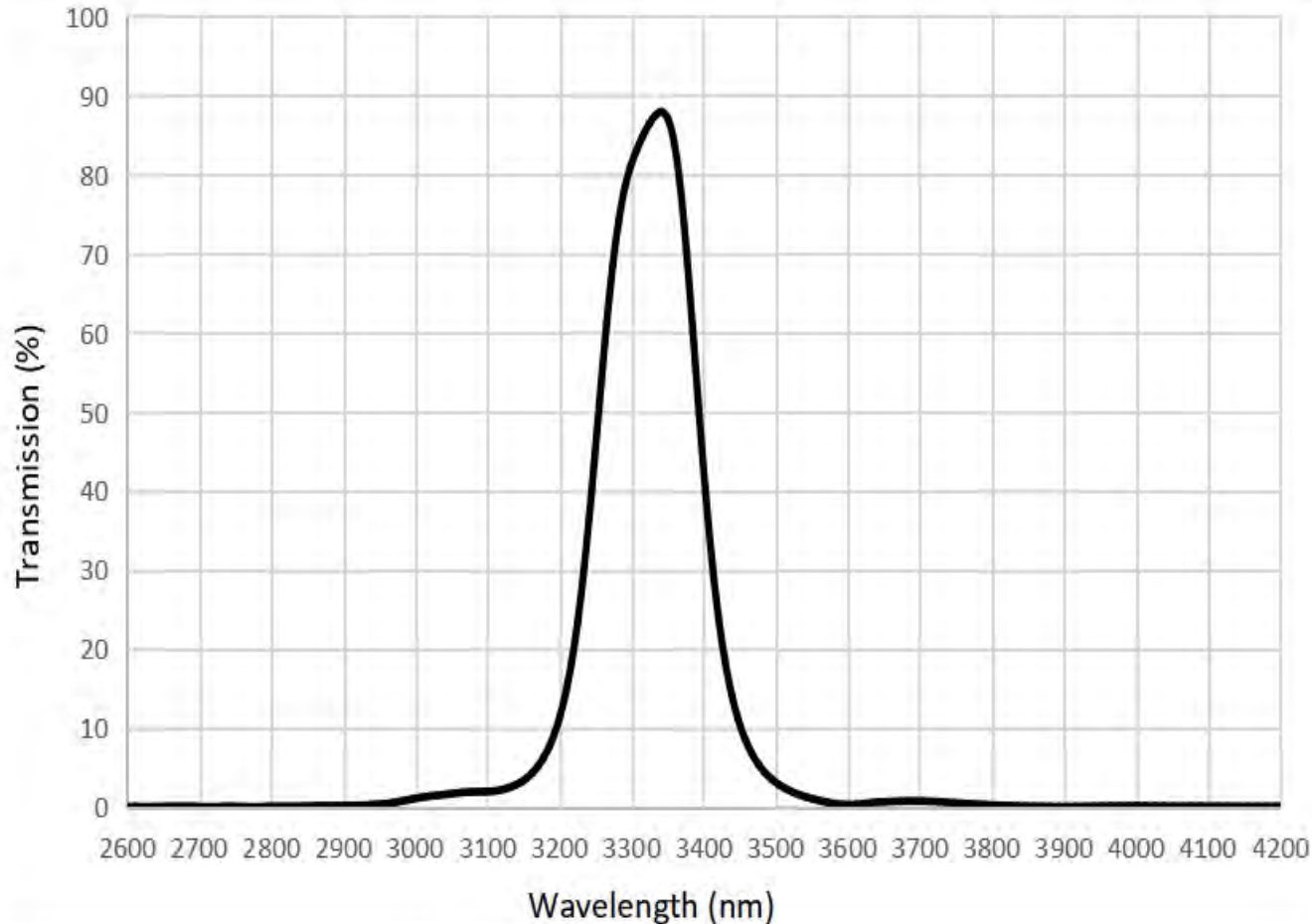


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Name: NBP 3330 60nm
Base material: single-crystal silicon
Center wavelength (CWL): 3330 ± 10 nm
Half wave width (FWHM): 60 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-4700nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 3330 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 3330 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

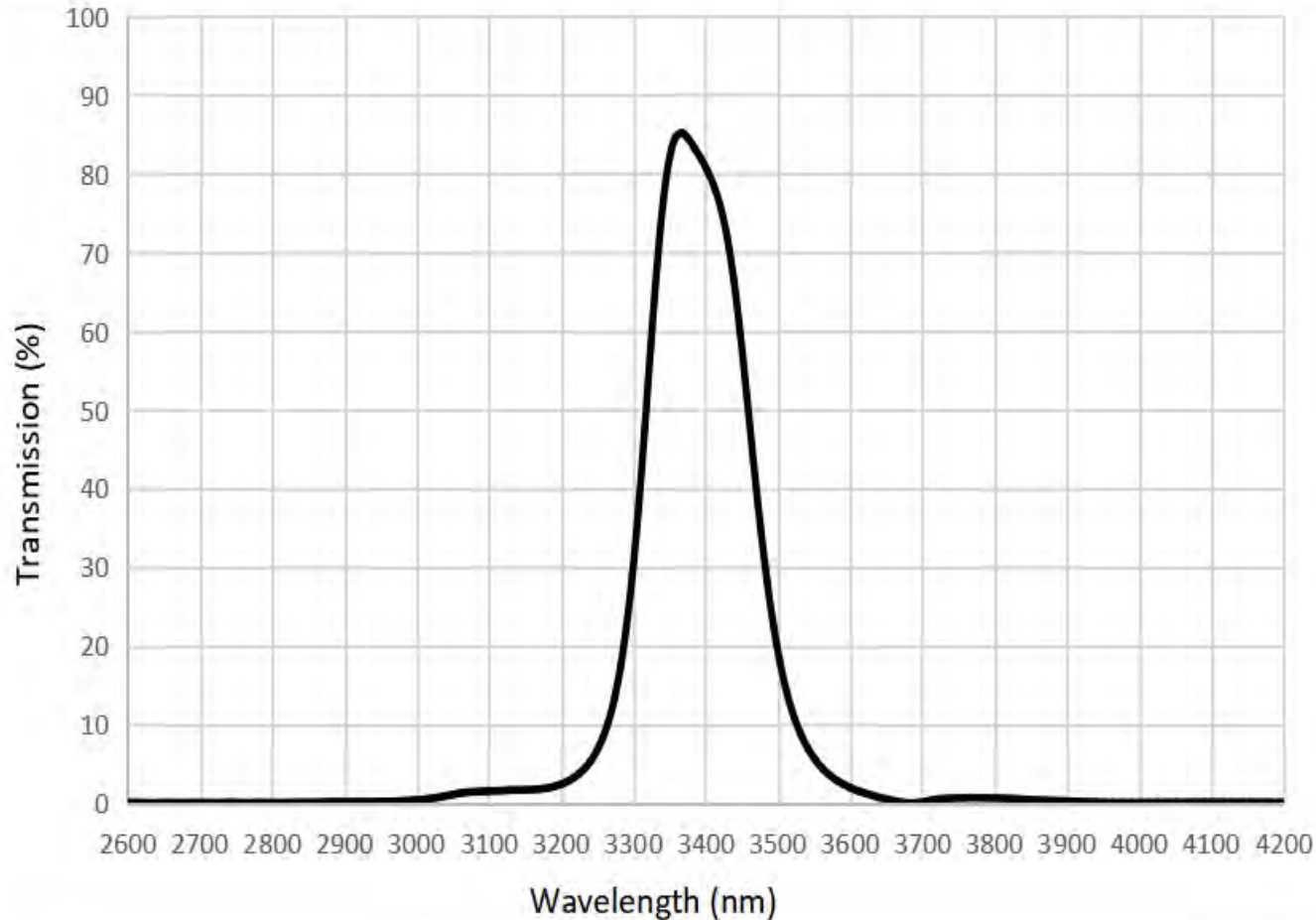
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 3375 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 3375 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

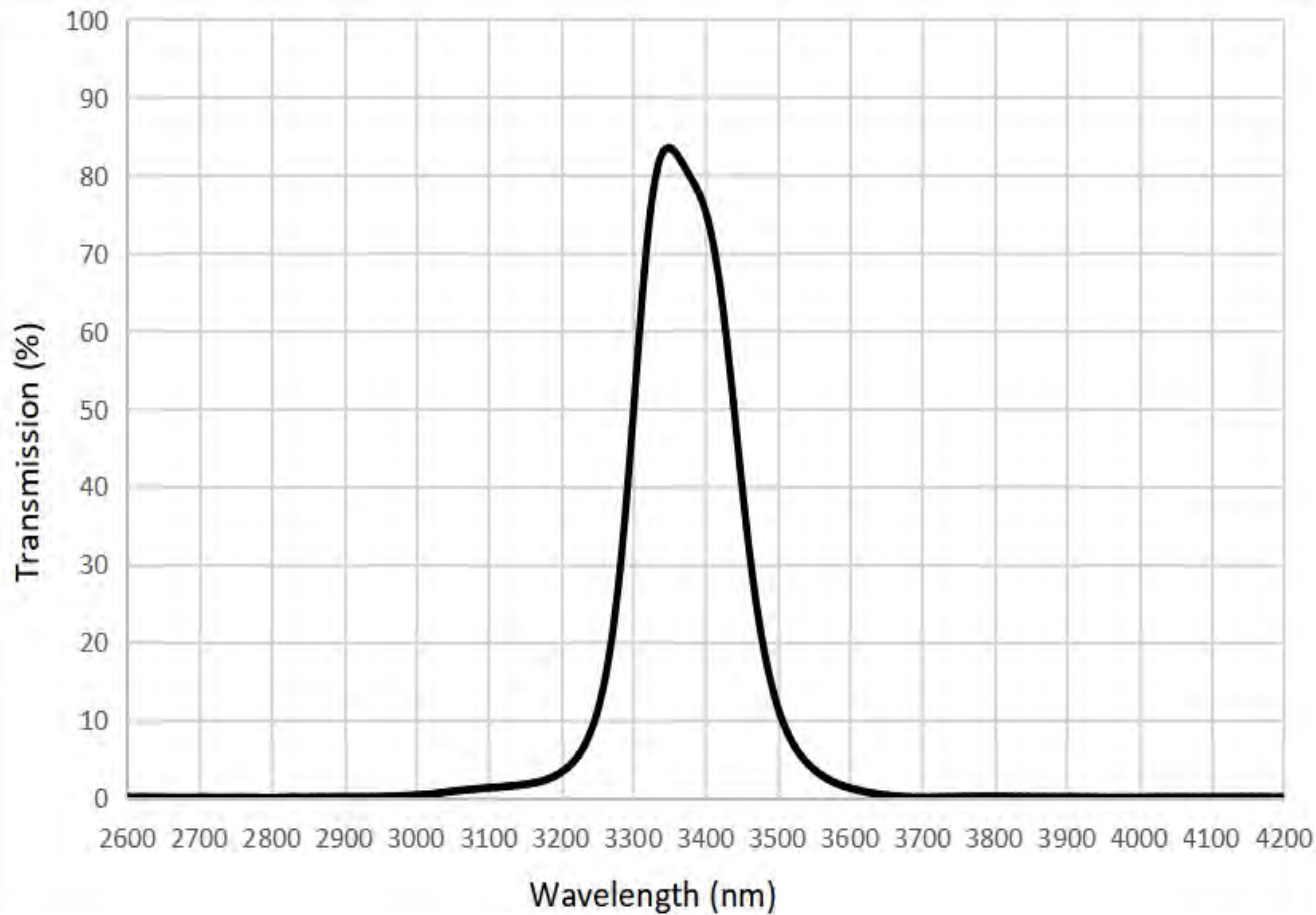
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

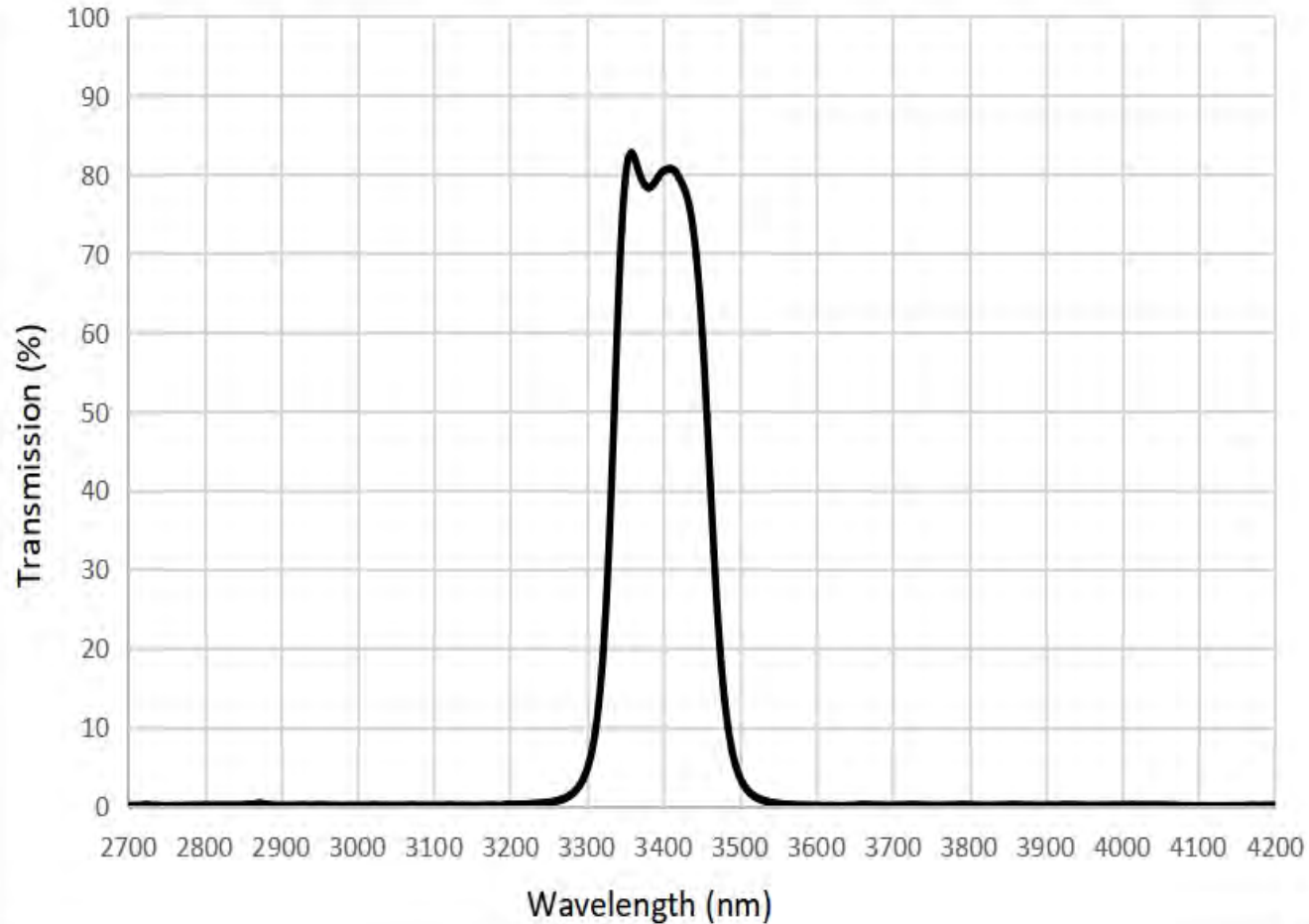
Cutting service available.



Name: NBP 3375 160nm
Base material: single-crystal silicon
Center wavelength (CWL): 3375 ± 30 nm
Half wave width (FWHM): 160 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 * 0.5$ mm

Cutting service available.



Name: NBP 3400 120nm

Base material: single-crystal silicon

Center wavelength (CWL): 3400 ± 30 nm

Half wave width (FWHM): 120 ± 20 nm

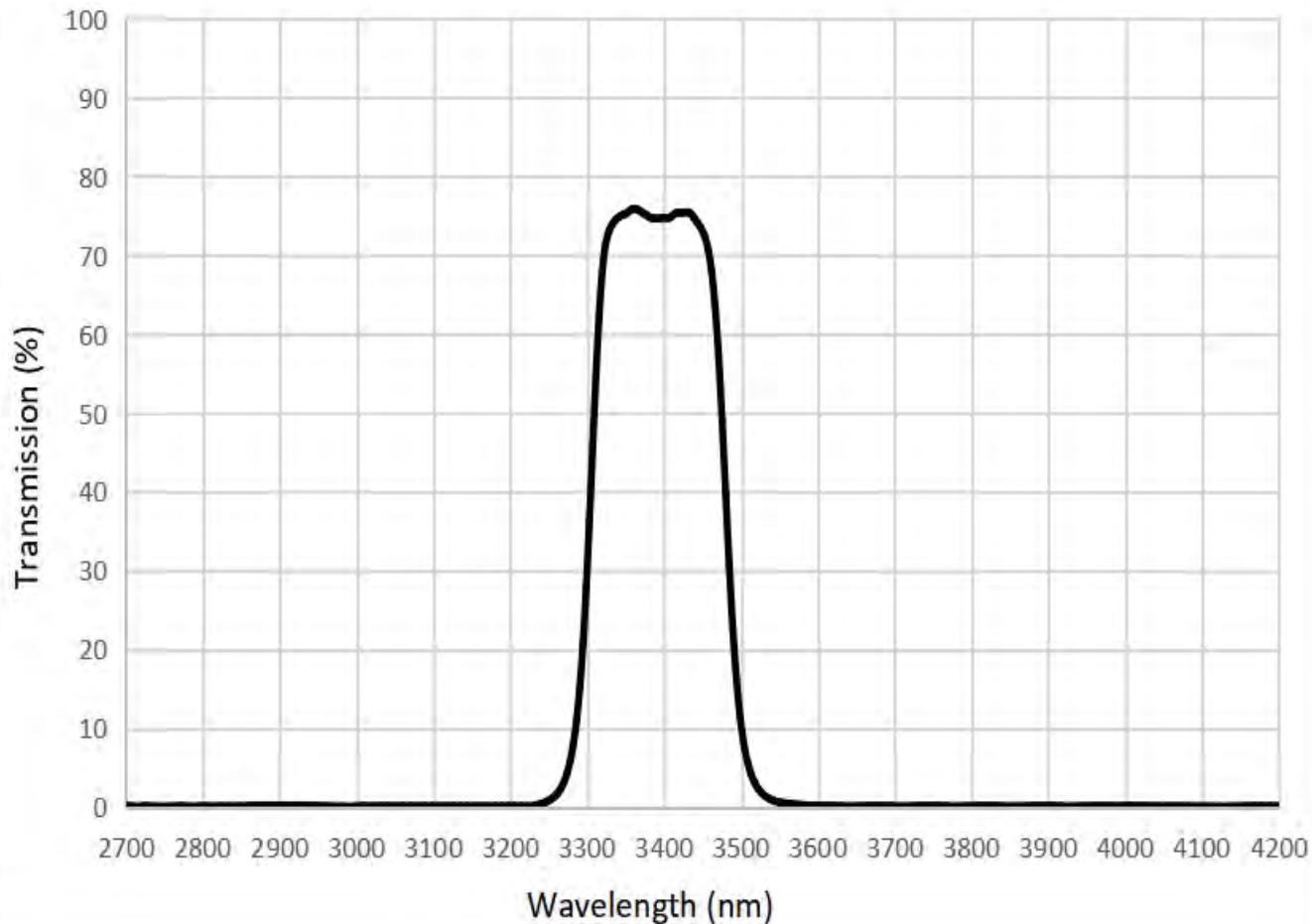
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 * 0.5$ mm

Cutting service available.



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Name: NBP 3400 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 3400 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

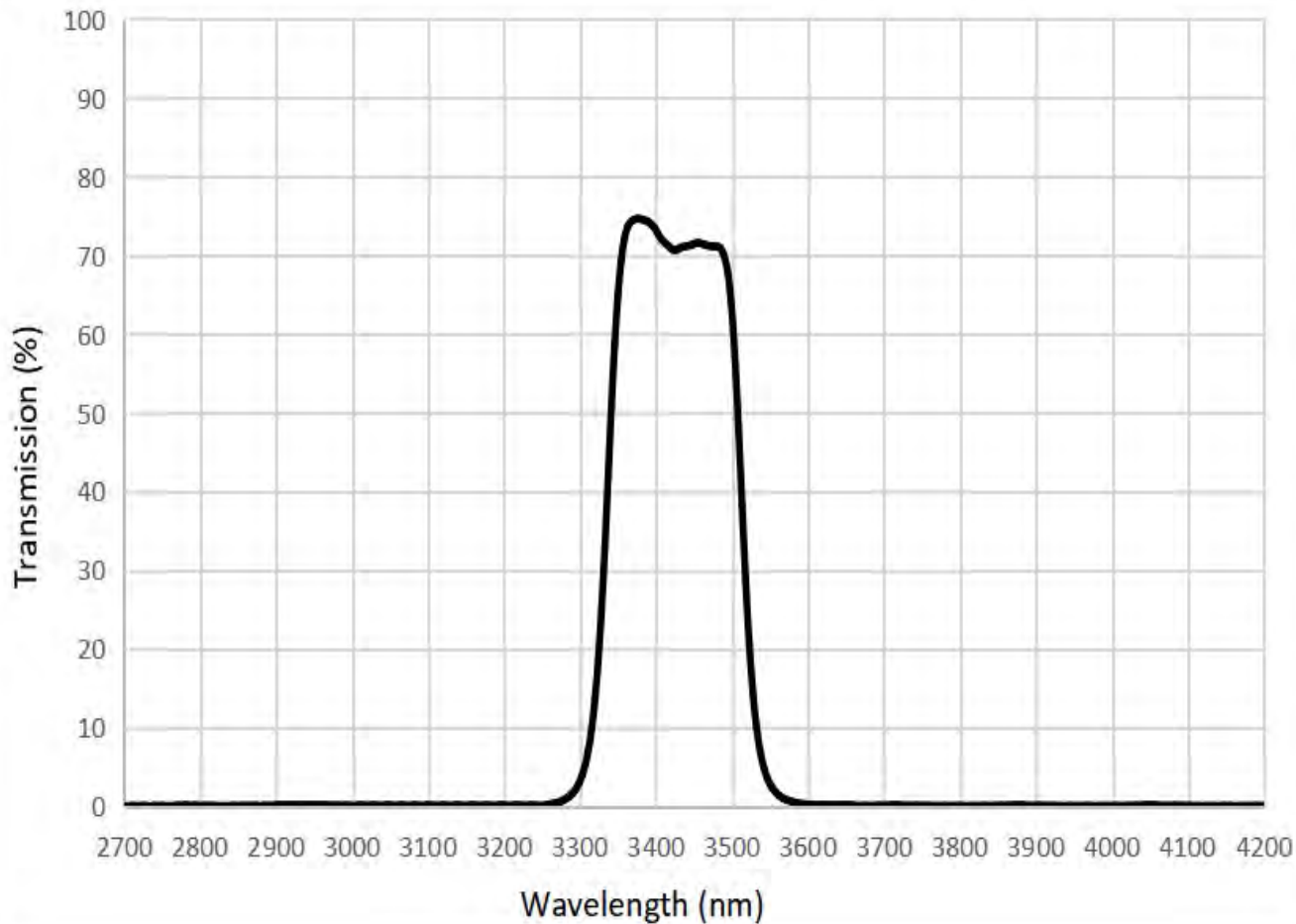
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 3420 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 3420±30nm

Half wave width (FWHM): 180±20nm

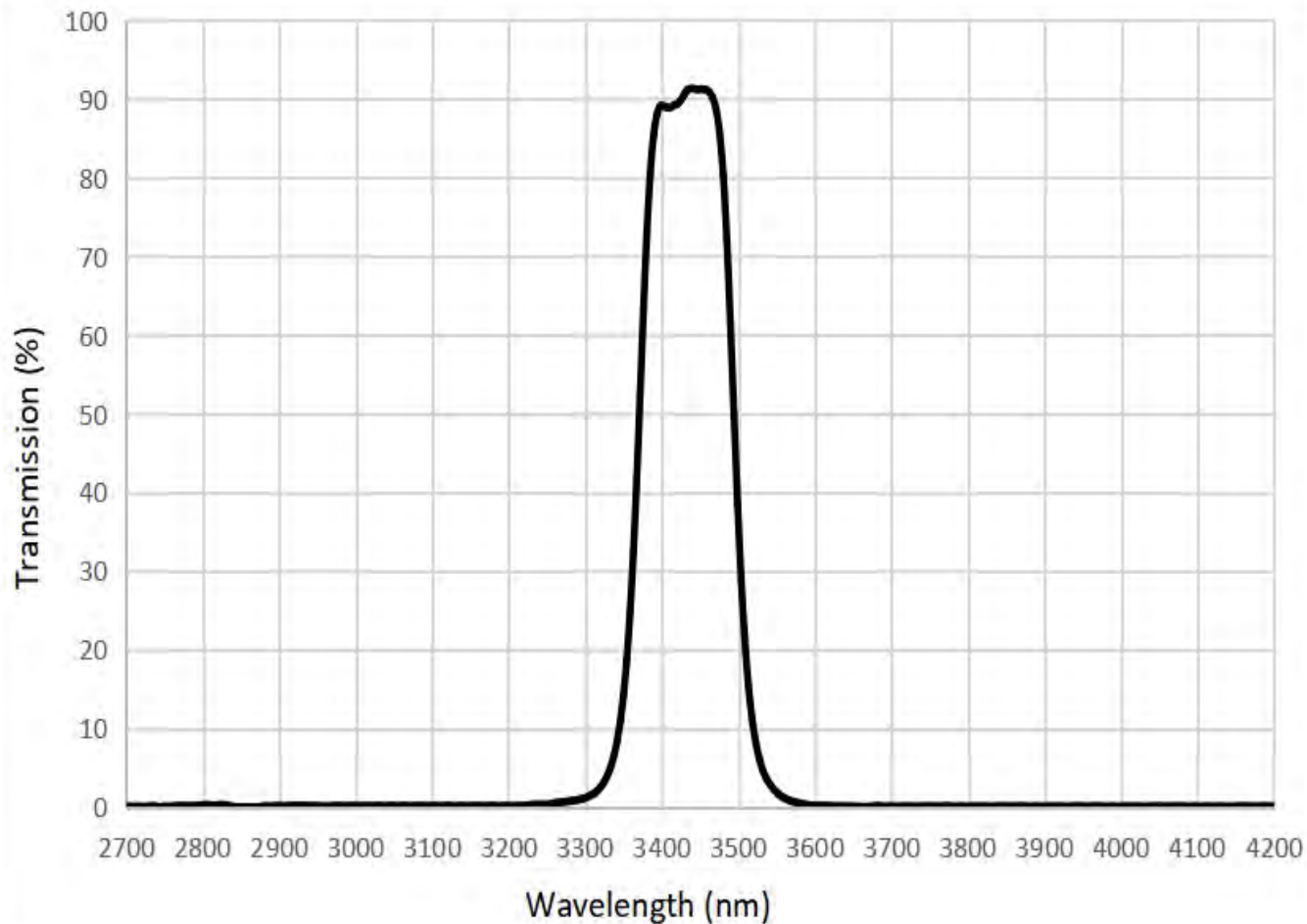
Peak Transmittance (Tp): >75%

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



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Name: NBP 3440 120nm

Base material: sapphire

Center wavelength (CWL): 3440 ± 30 nm

Half wave width (FWHM): 120 ± 20 nm

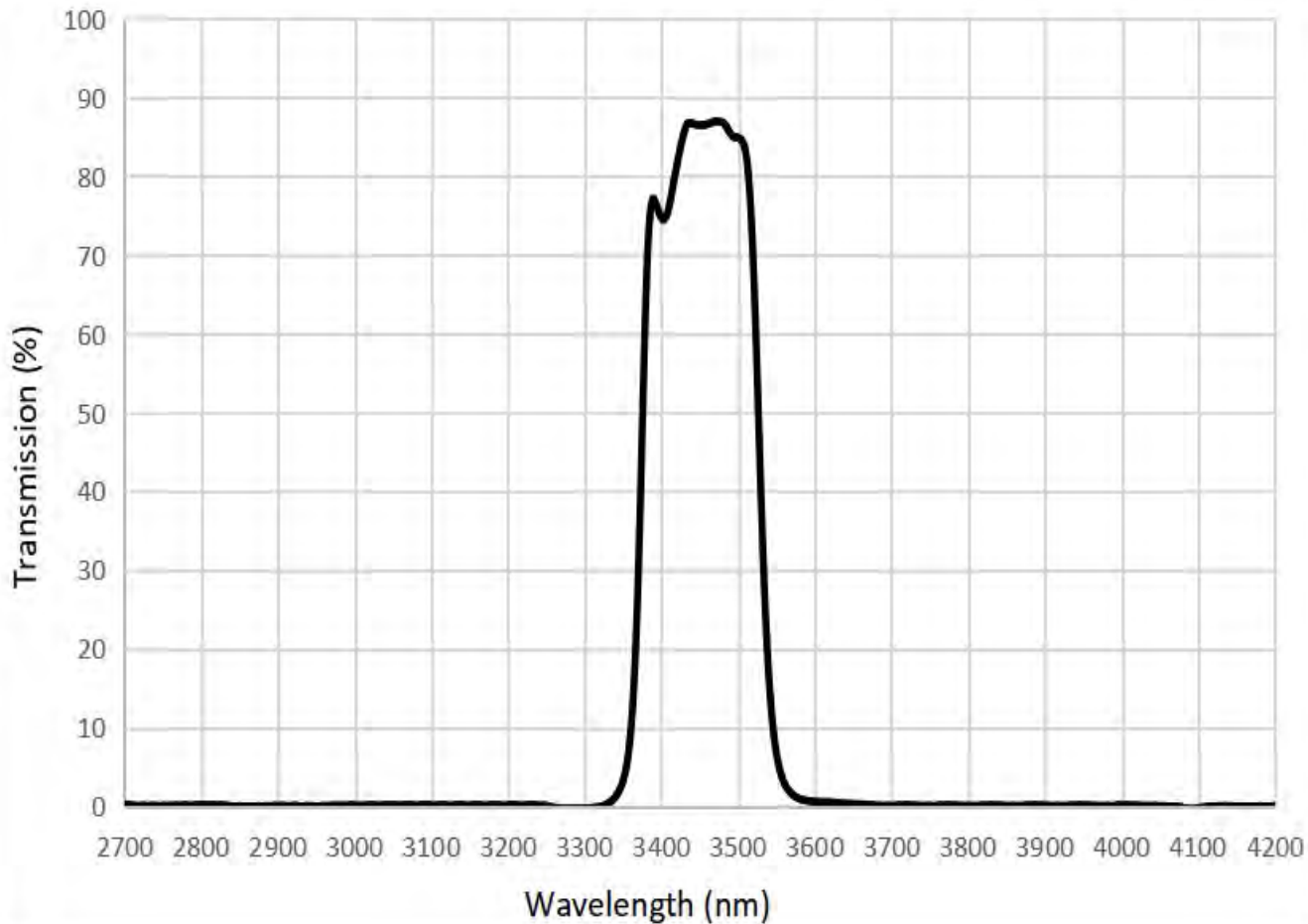
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for
passband): 400-25000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.8$ mm

Cutting service available.

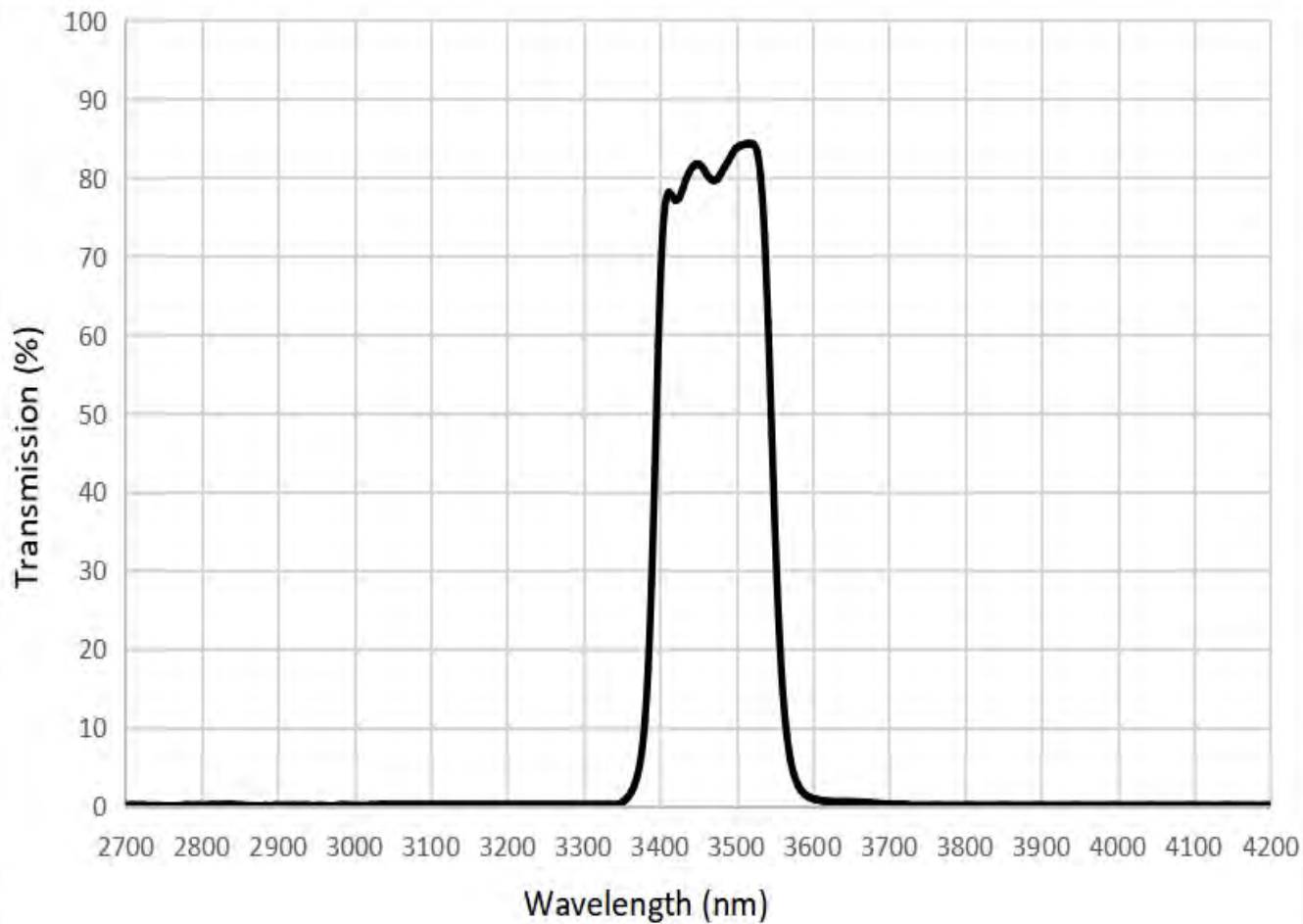


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Name: NBP 3440 160nm
Base material: single-crystal silicon
Center wavelength (CWL): 3440 ± 30 nm
Half wave width (FWHM): 160 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 3460 150nm

Base material: single-crystal silicon

Center wavelength (CWL): 3460 ± 30 nm

Half wave width (FWHM): 150 ± 20 nm

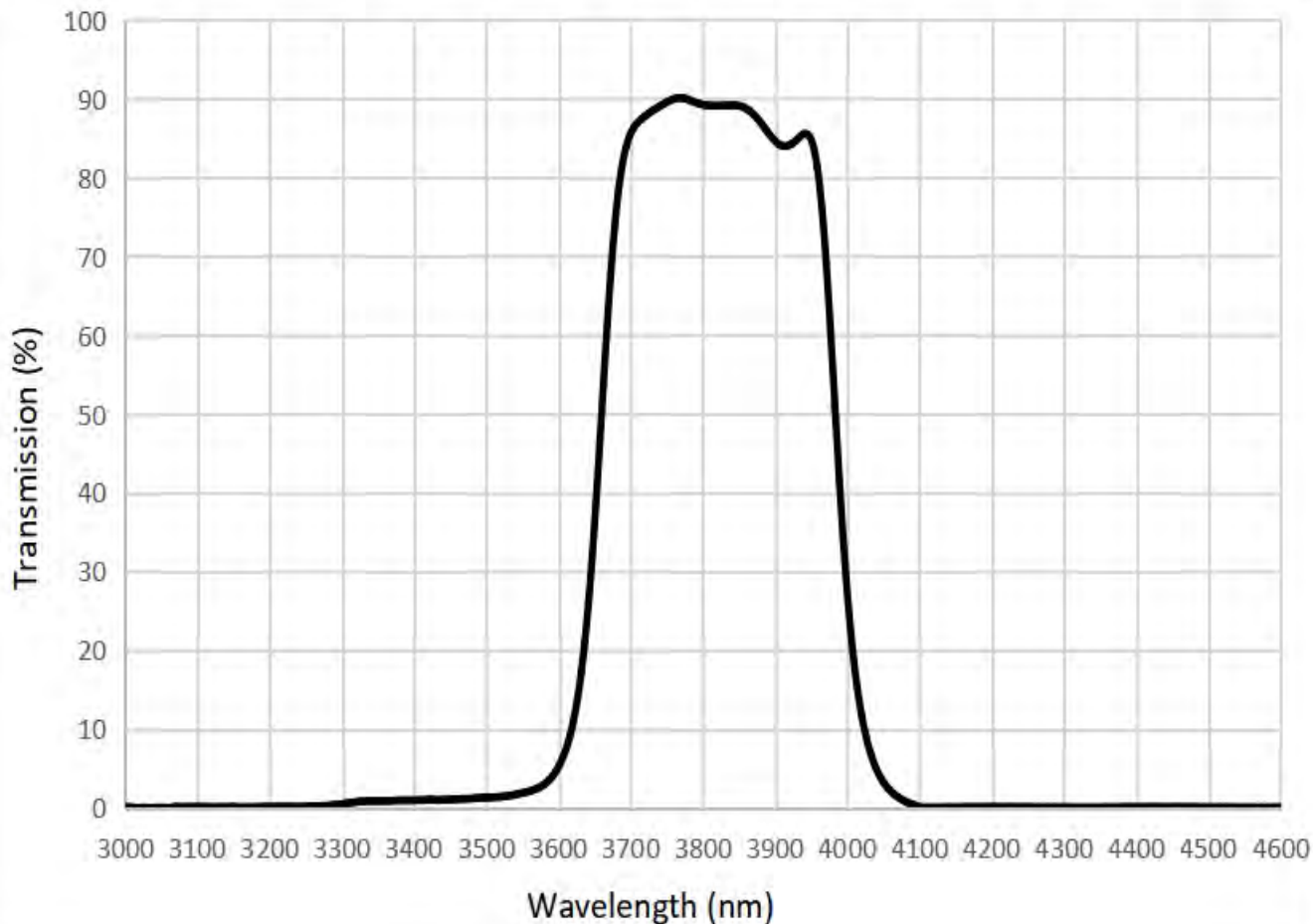
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 3800 300nm

Base material: single-crystal silicon

Center wavelength (CWL): 3800 ± 40 nm

Half wave width (FWHM): 300 ± 30 nm

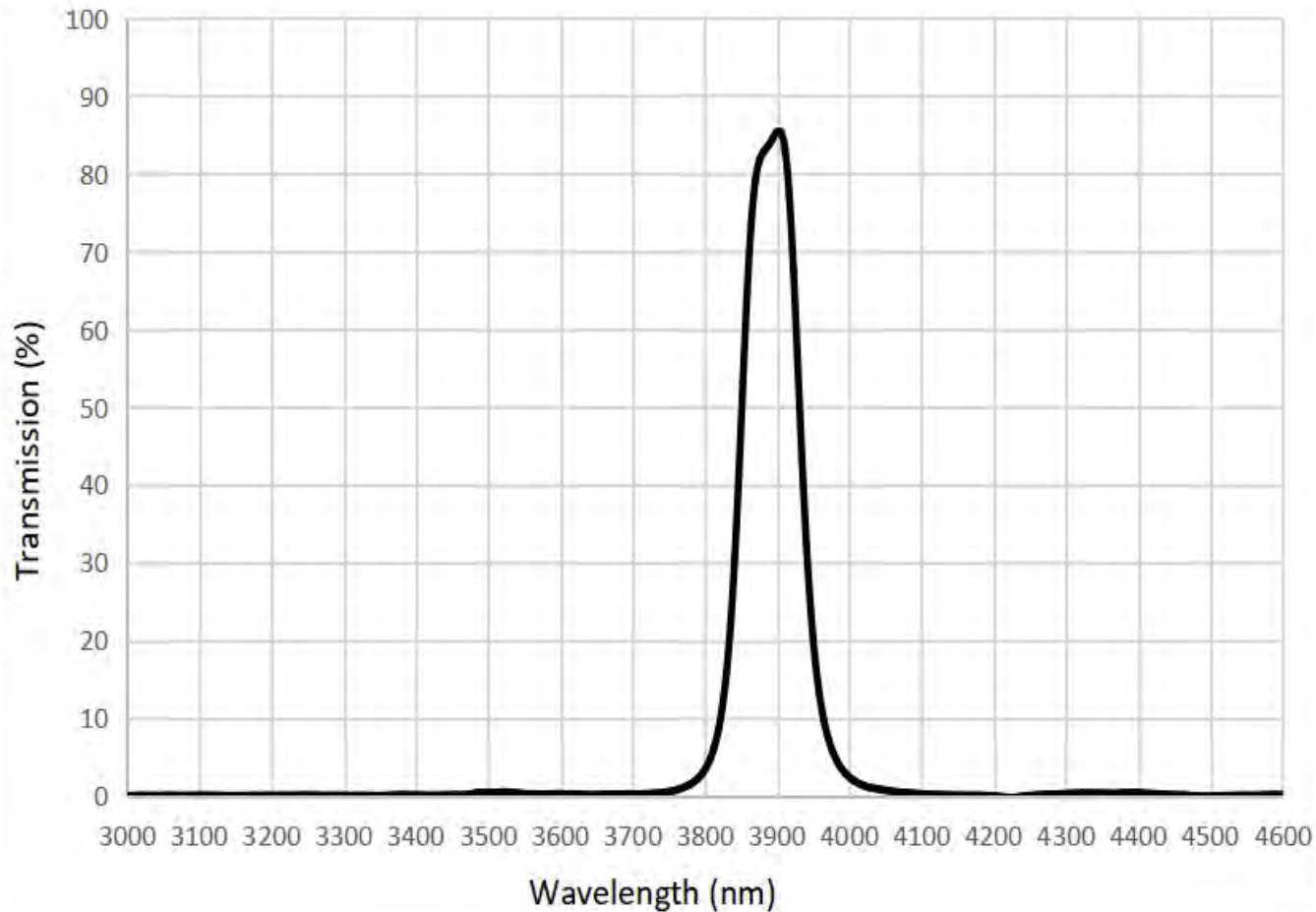
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.

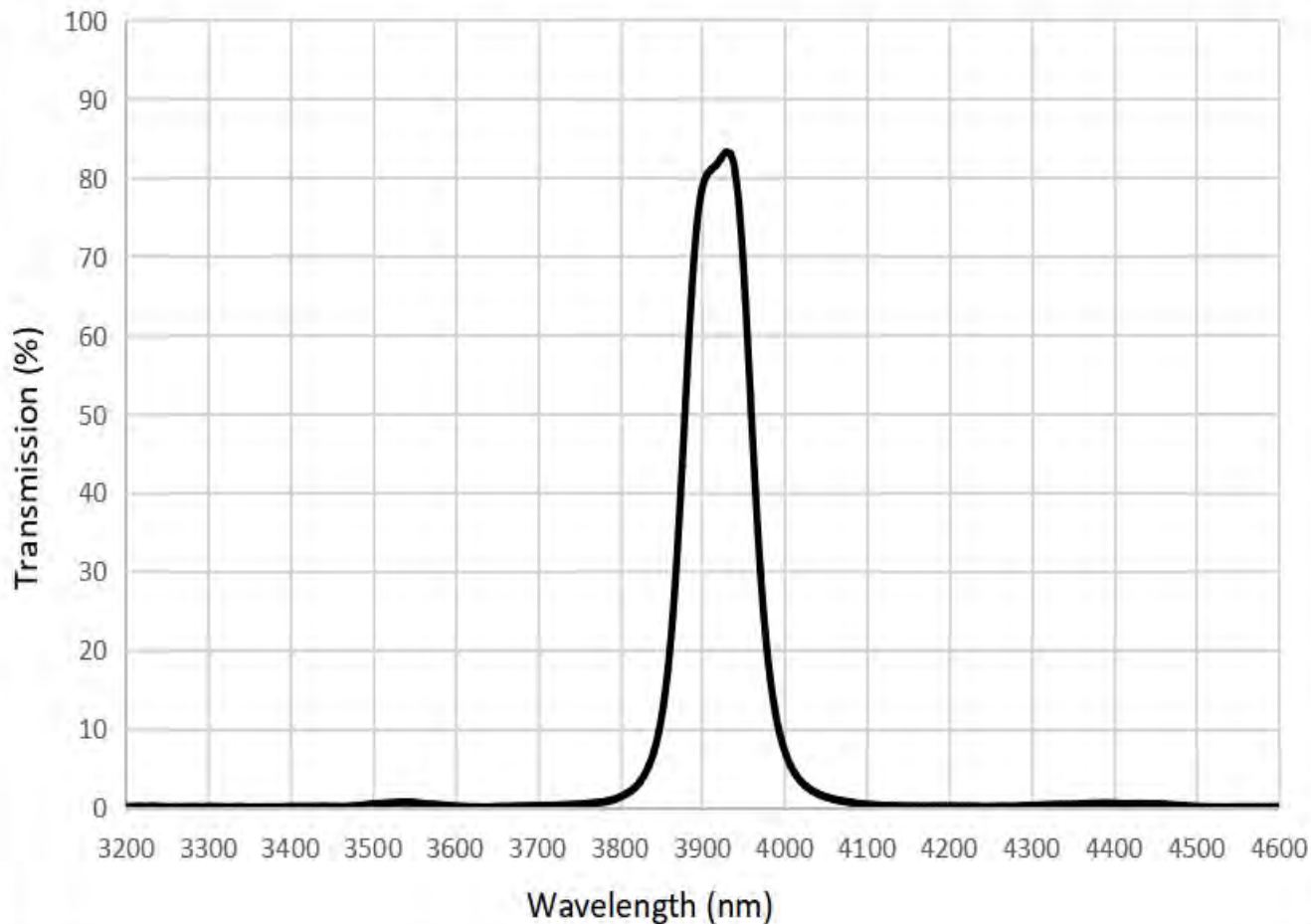


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Name: NBP 3900 90nm
Base material: single-crystal silicon
Center wavelength (CWL): 3900 ± 20 nm
Half wave width (FWHM): 90 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 3920 90nm

Base material: single-crystal silicon

Center wavelength (CWL): 3920 ± 20 nm

Half wave width (FWHM): 90 ± 20 nm

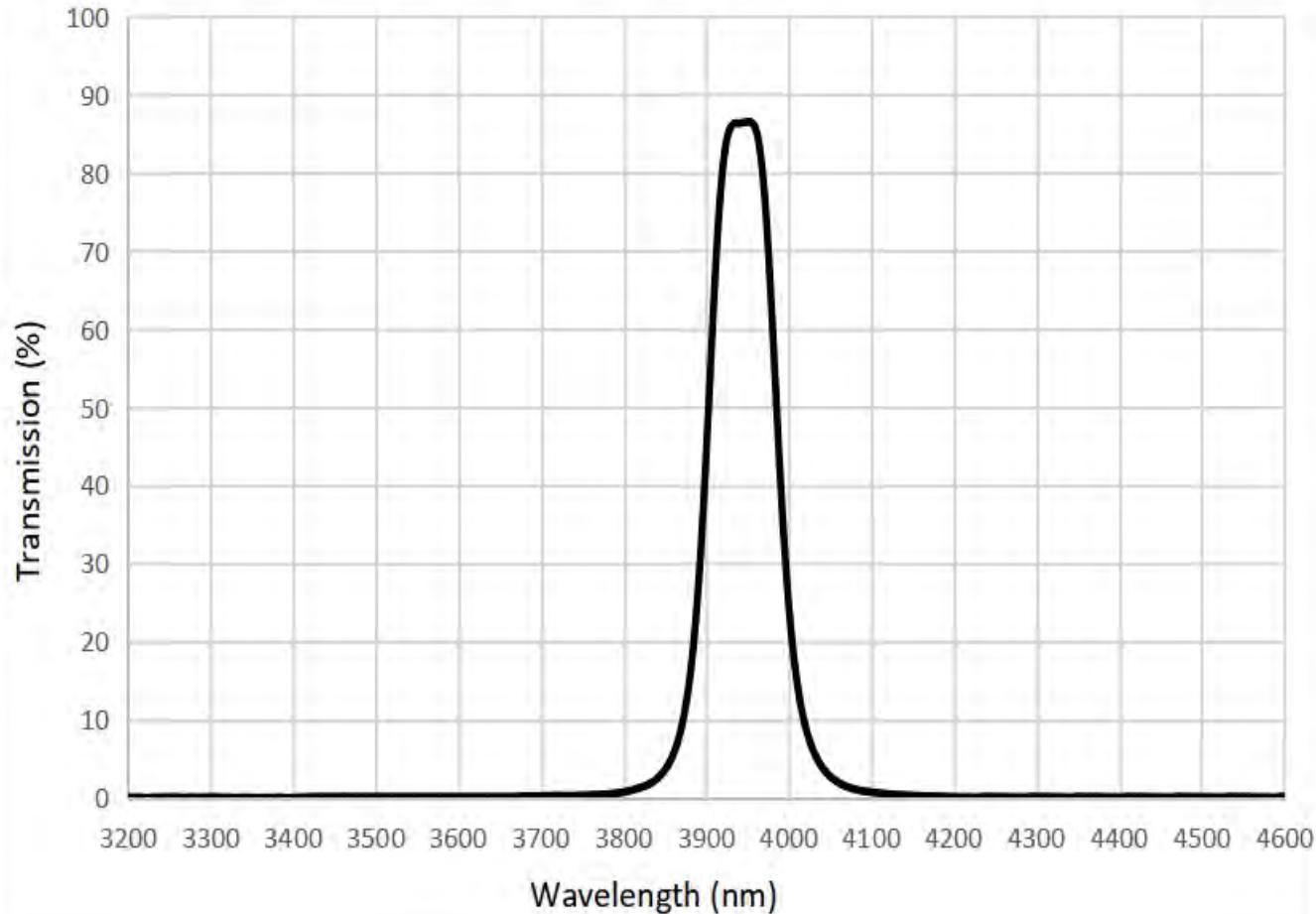
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

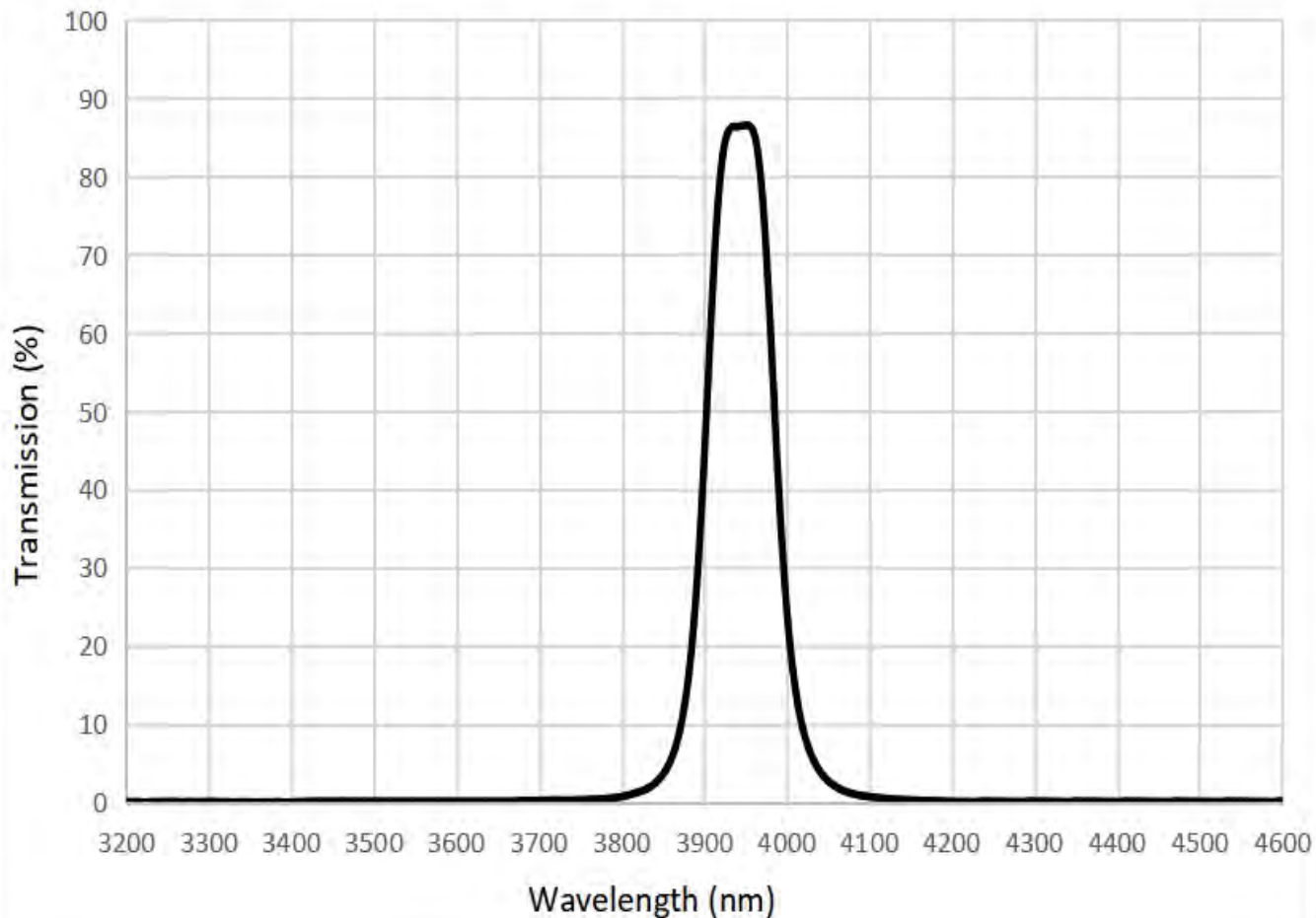
Cutting service available.



Name: NBP 3950 90nm
Base material: single-crystal silicon
Center wavelength (CWL): 3950 ± 20 nm
Half wave width (FWHM): 90 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.

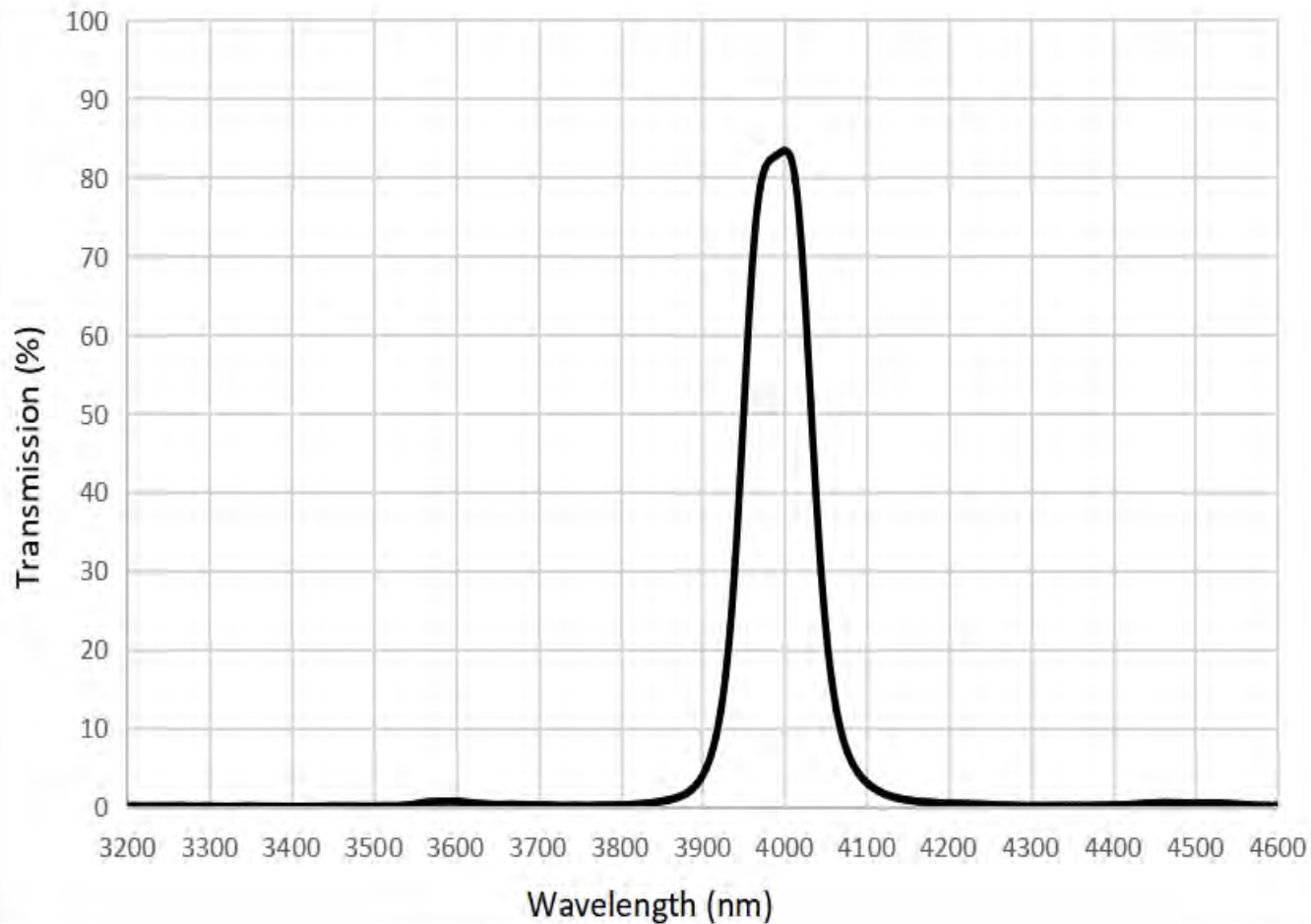


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Name: NBP 3950 90nm
Base material: single-crystal silicon
Center wavelength (CWL): 3950 ± 20 nm
Half wave width (FWHM): 90 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: 3.3*3.3*0.5mm

Cutting service available.



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Name: NBP 3970 90nm

Base material: single-crystal silicon

Center wavelength (CWL): 3970 ± 20 nm

Half wave width (FWHM): 90 ± 20 nm

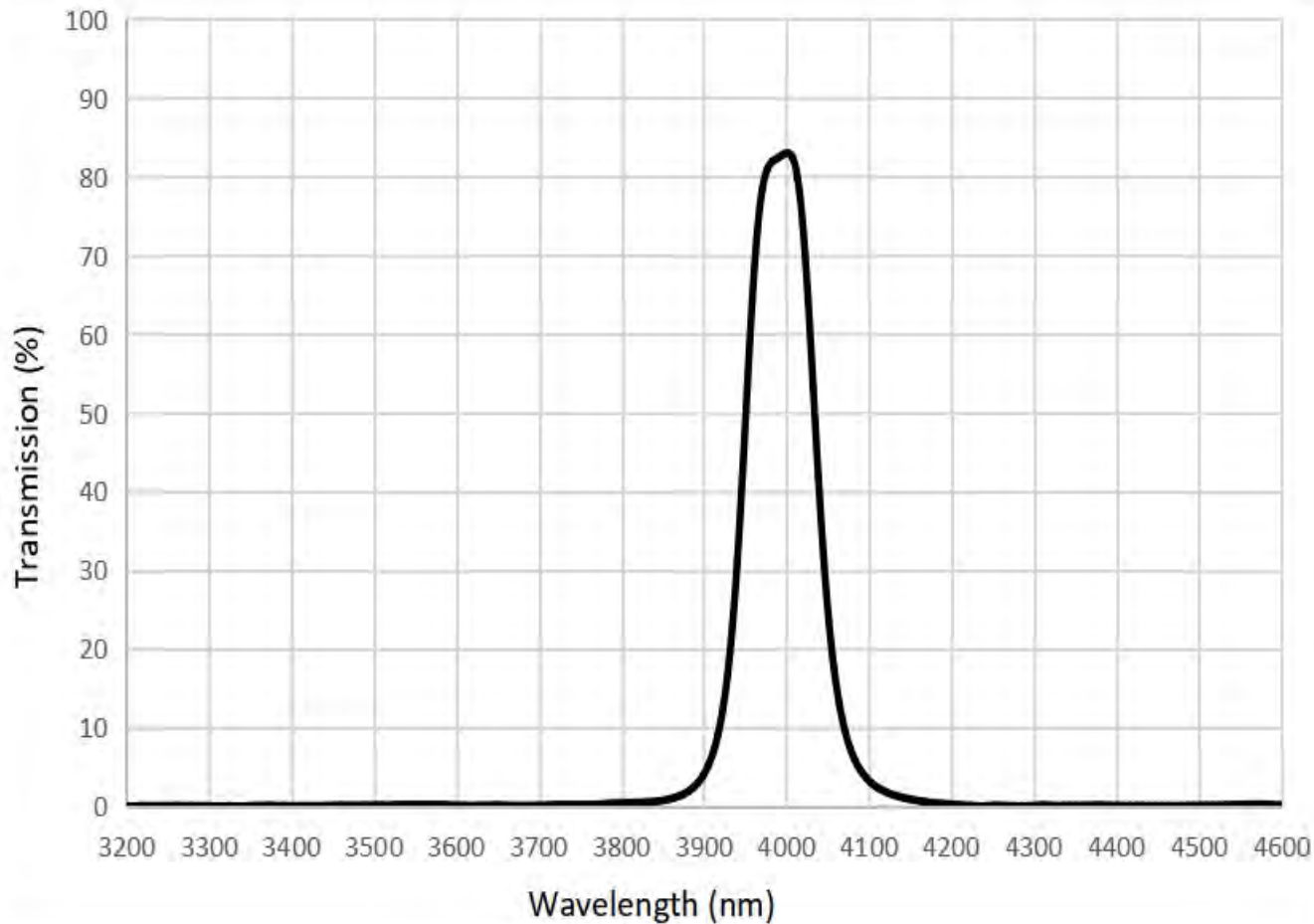
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.

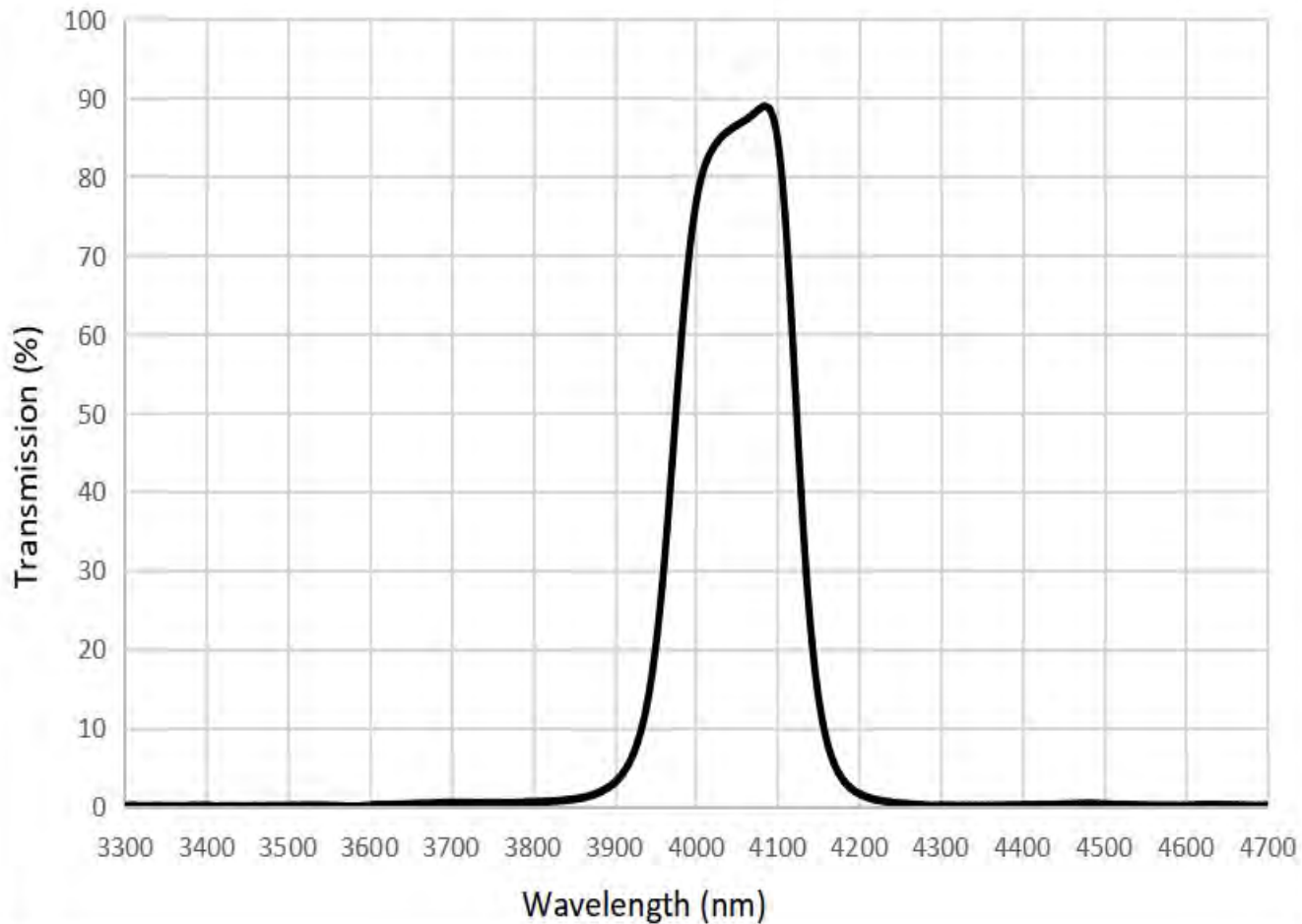


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Name: NBP 4000 90nm
Base material: single-crystal silicon
Center wavelength (CWL): 4000 ± 20 nm
Half wave width (FWHM): 90 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4050 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4050 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

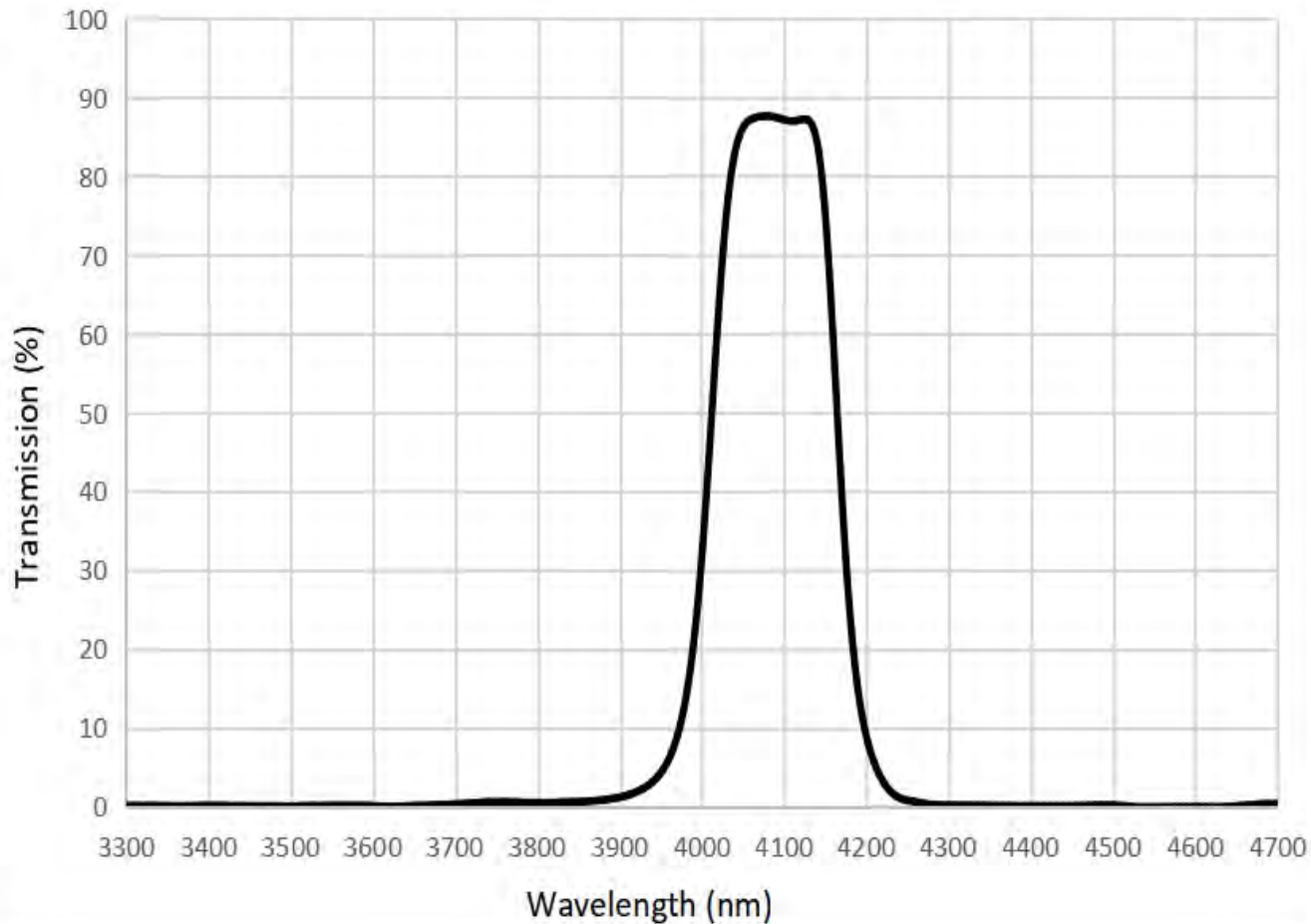
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4100 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4100 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

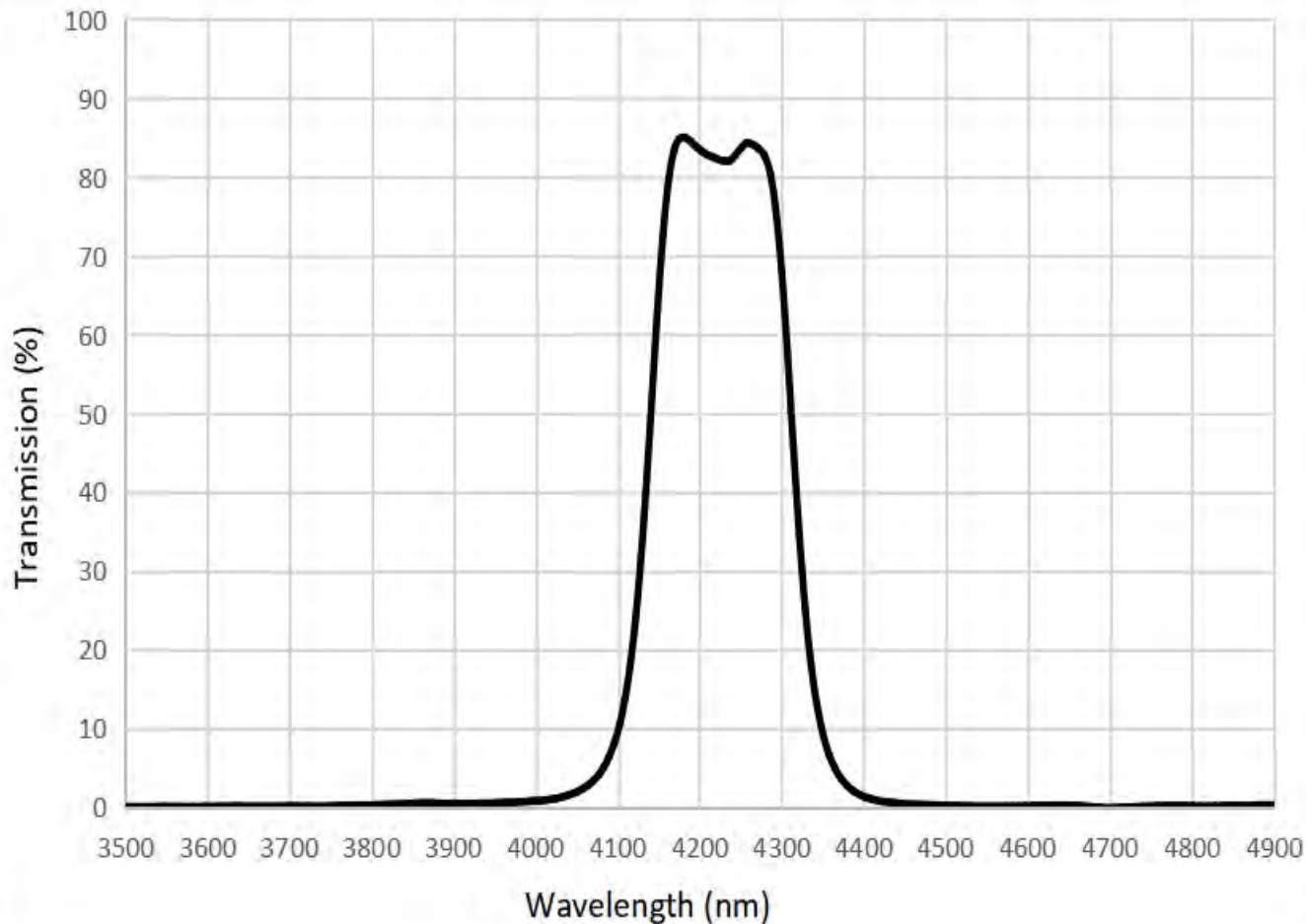
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4200 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4200 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

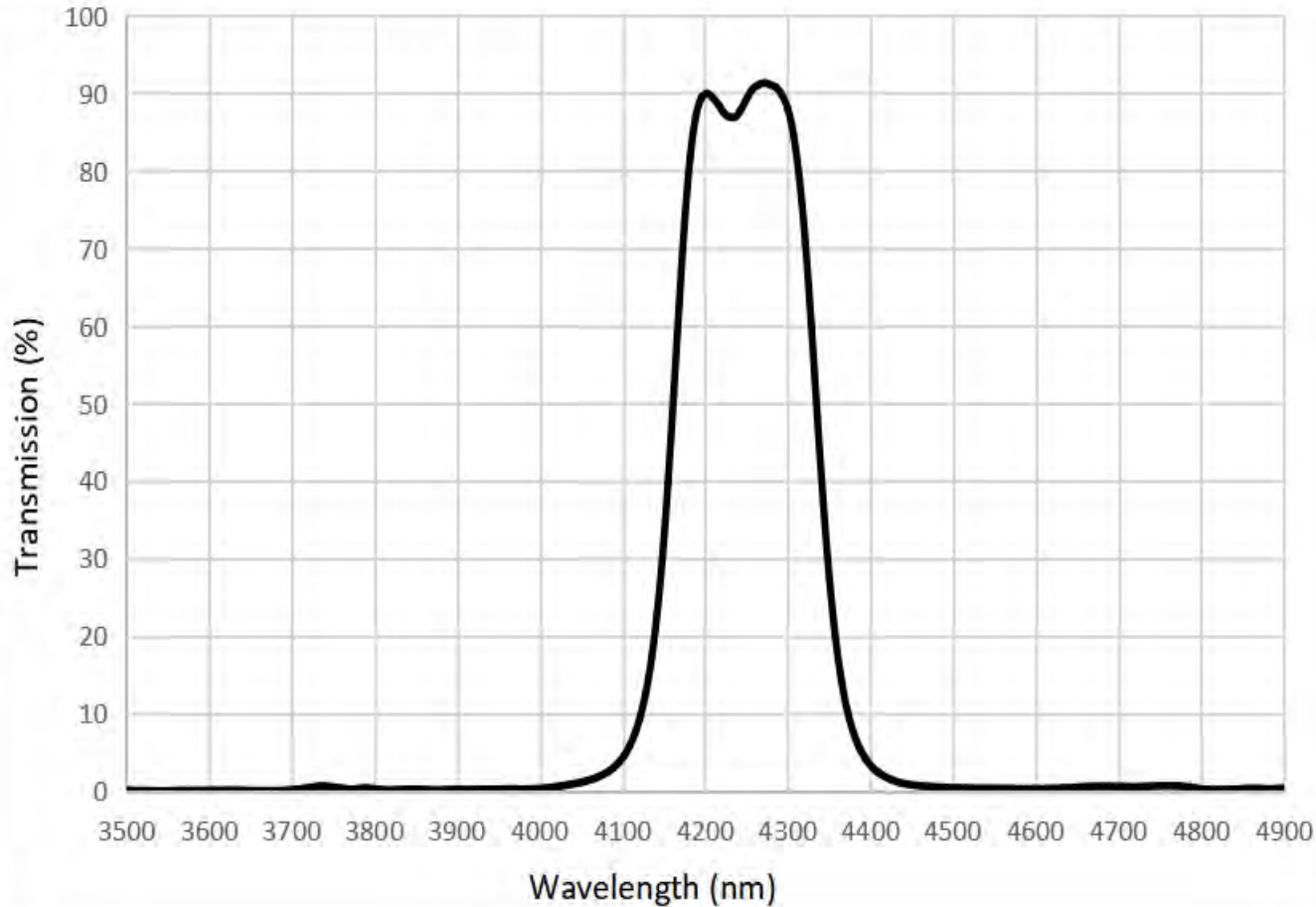
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4230 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 4230 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

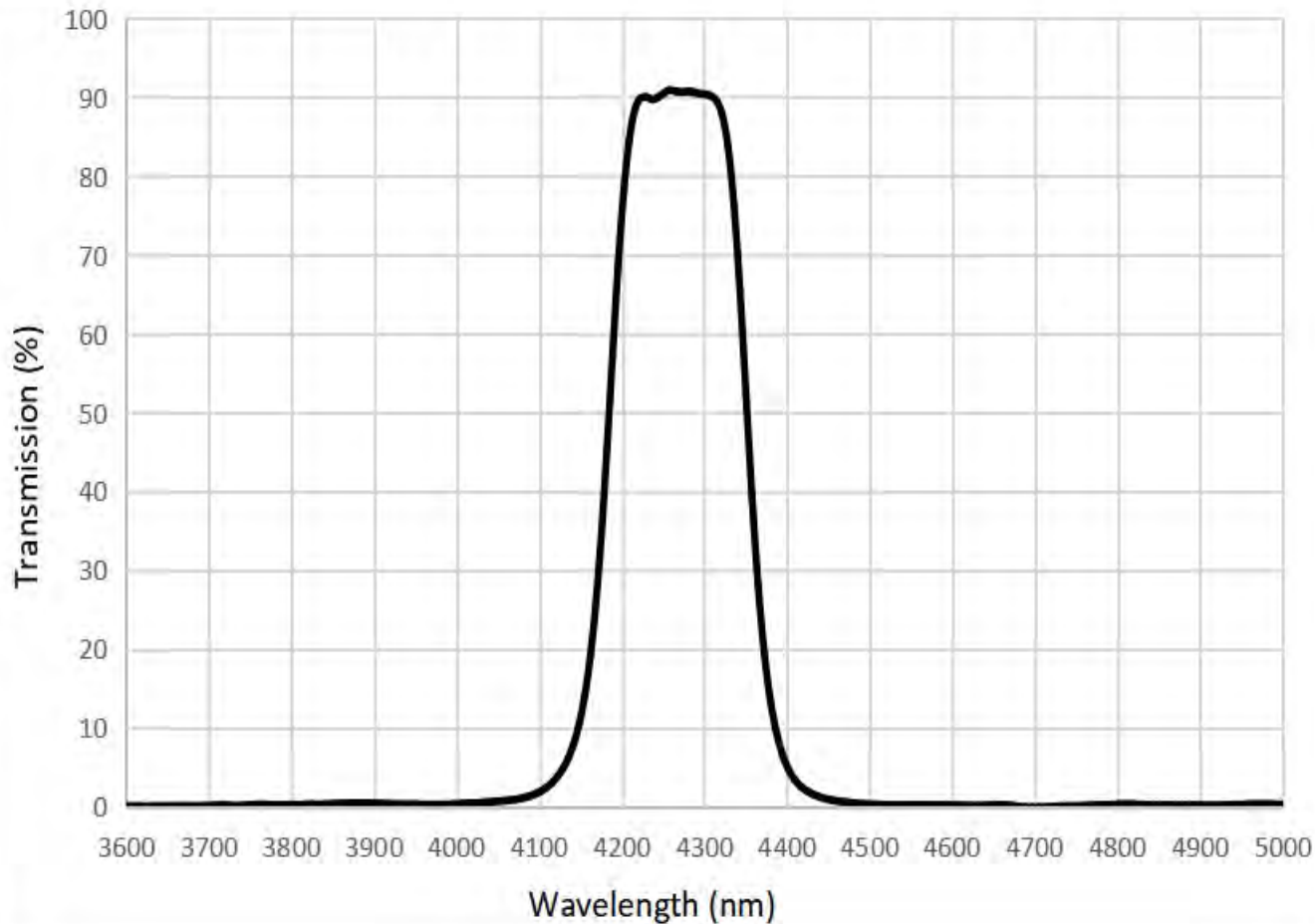
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4260 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4260 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

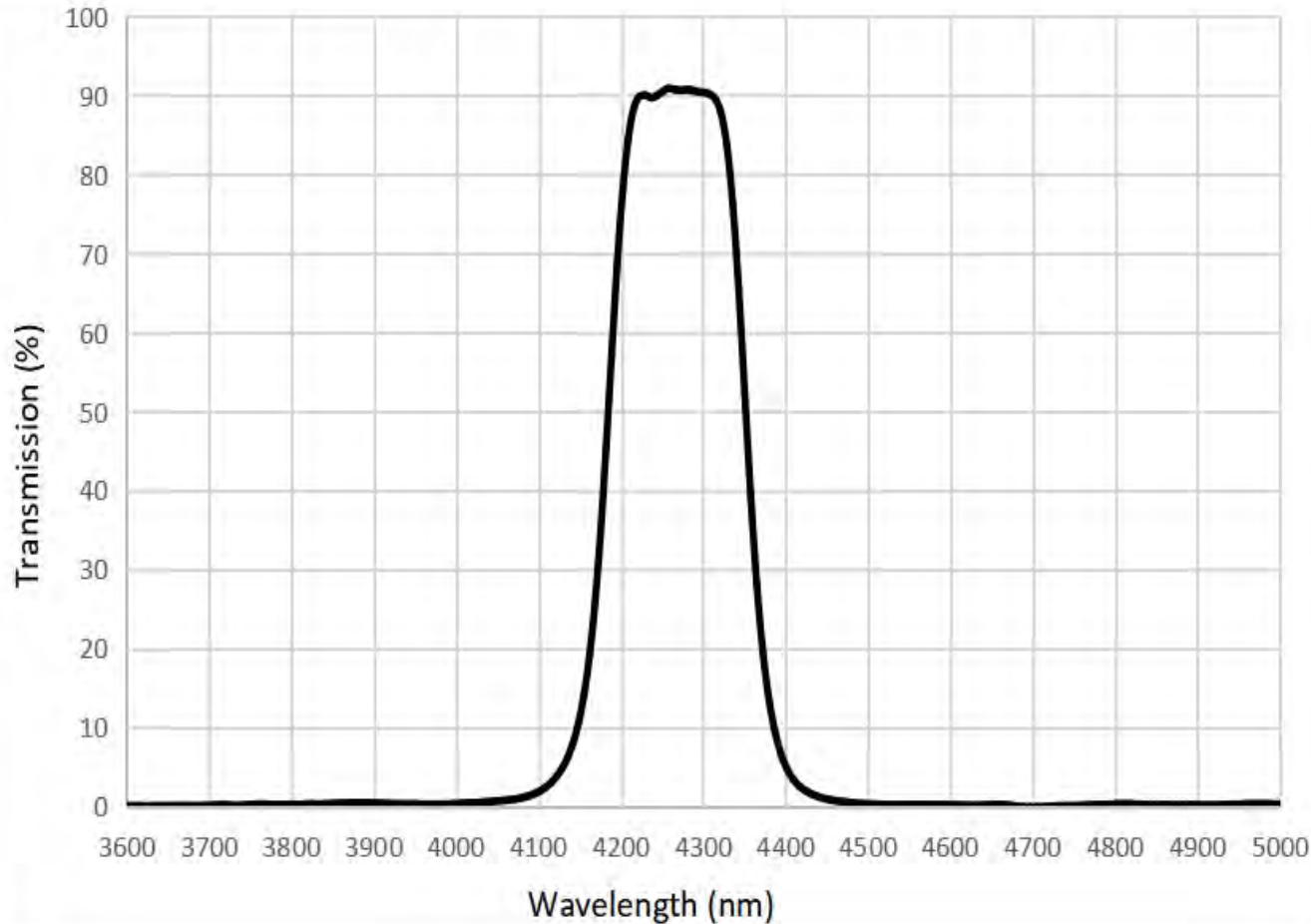
Peak Transmittance (T_p): $> 80\%$

cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4260 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4260 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

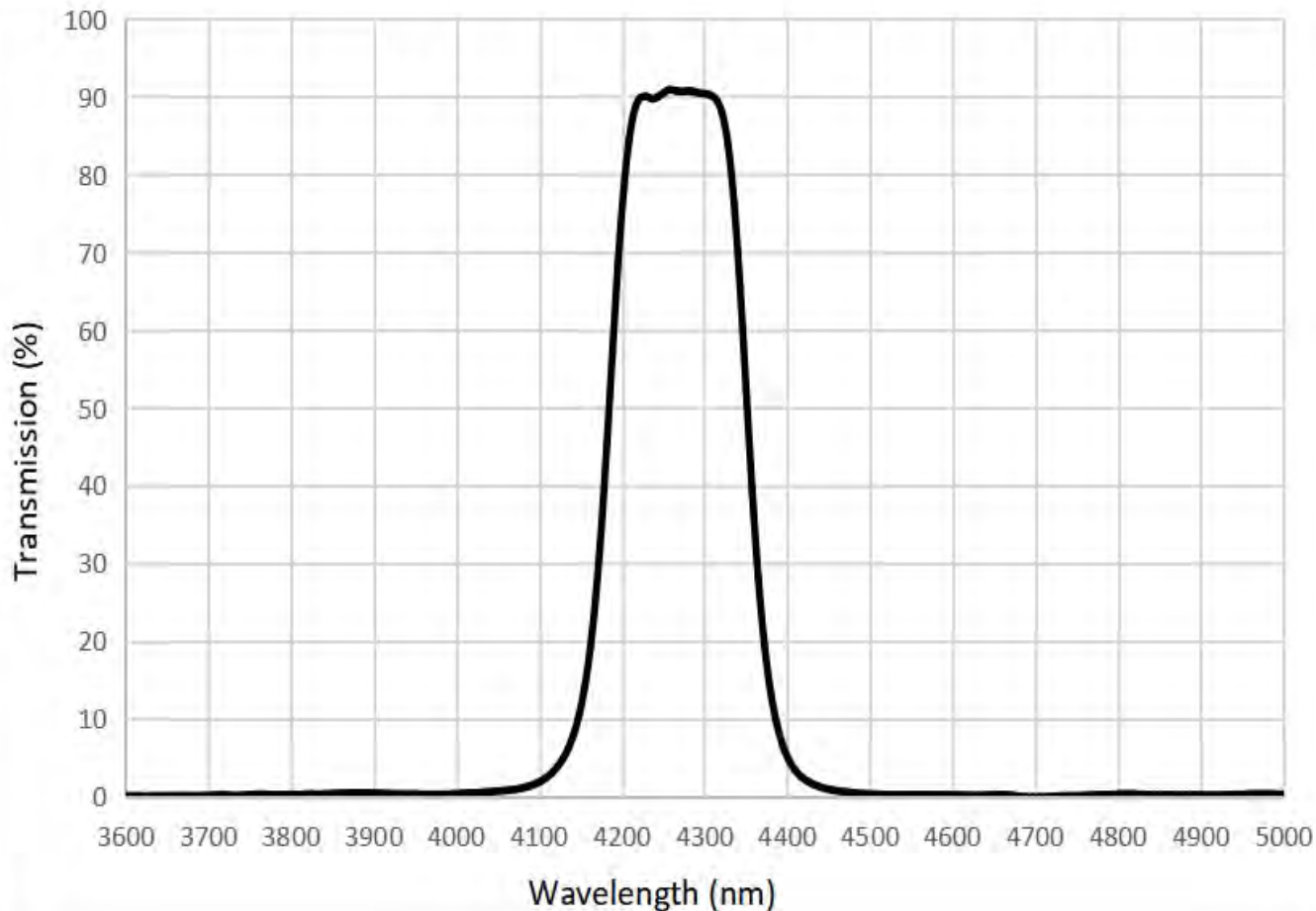
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: 2.9*2.9*0.5mm

Cutting service available.

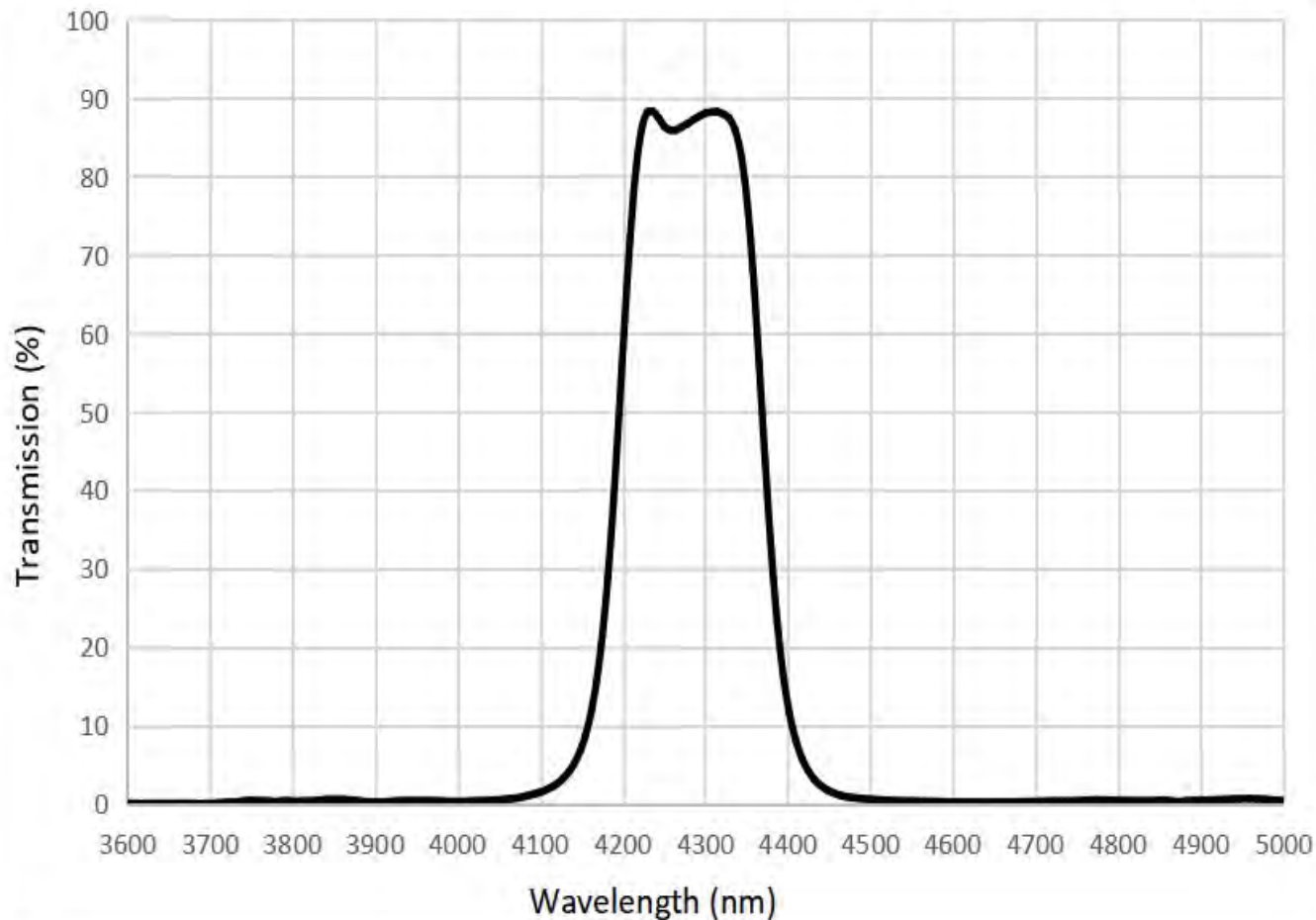


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Name: NBP 4260 180nm
Base material: single-crystal silicon
Center wavelength (CWL): $4260 \pm 30\text{nm}$
Half wave width (FWHM): $180 \pm 20\text{nm}$
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $3.3 \times 3.3 \times 0.5\text{mm}$

Cutting service available.



Name: NBP 4280 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4280 ± 20 nm

Half wave width (FWHM): 180 ± 20 nm

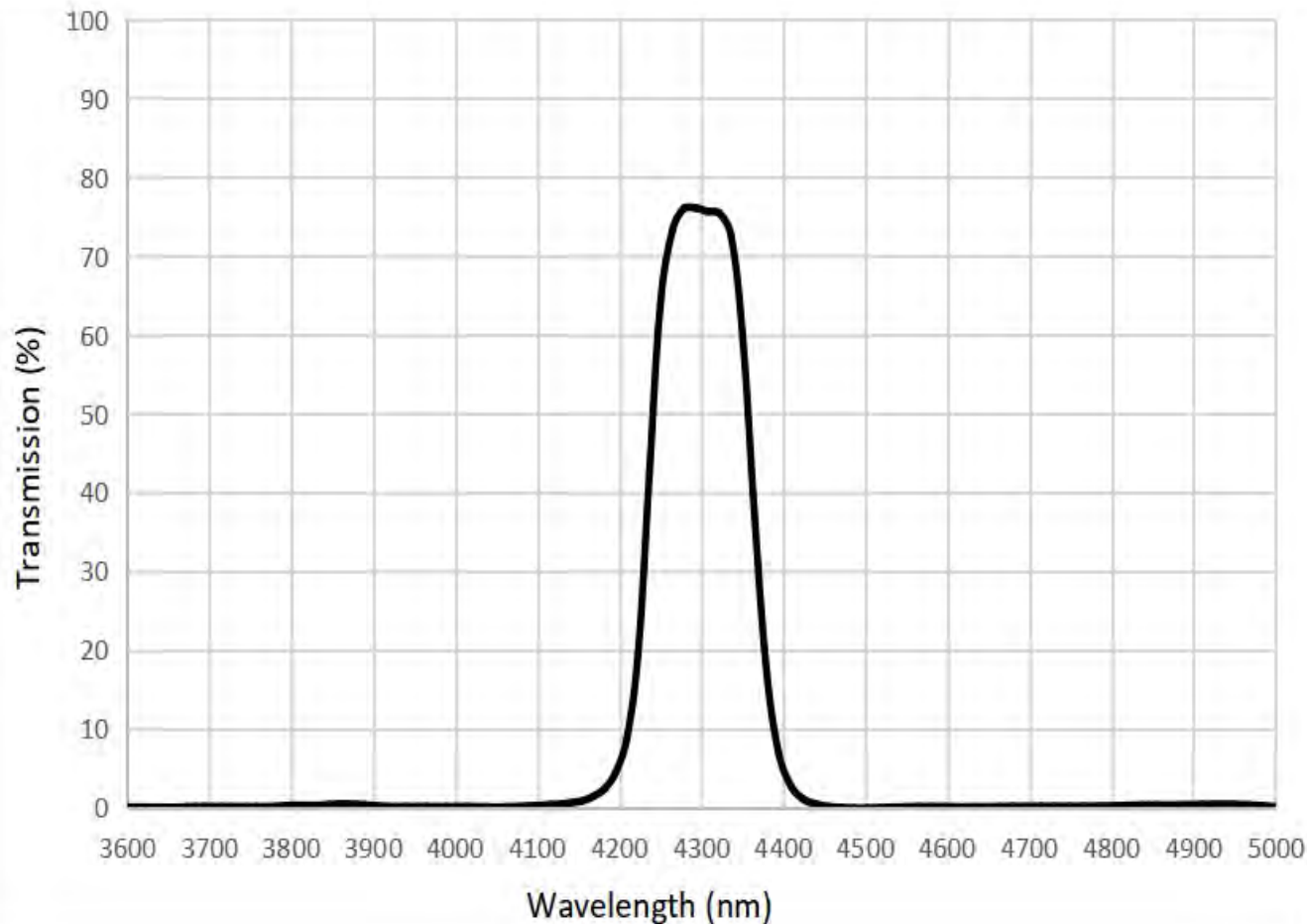
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4300 130nm

Base material: single-crystal silicon

Center wavelength (CWL): $4300 \pm 30\text{nm}$

Half wave width (FWHM): $130 \pm 20\text{nm}$

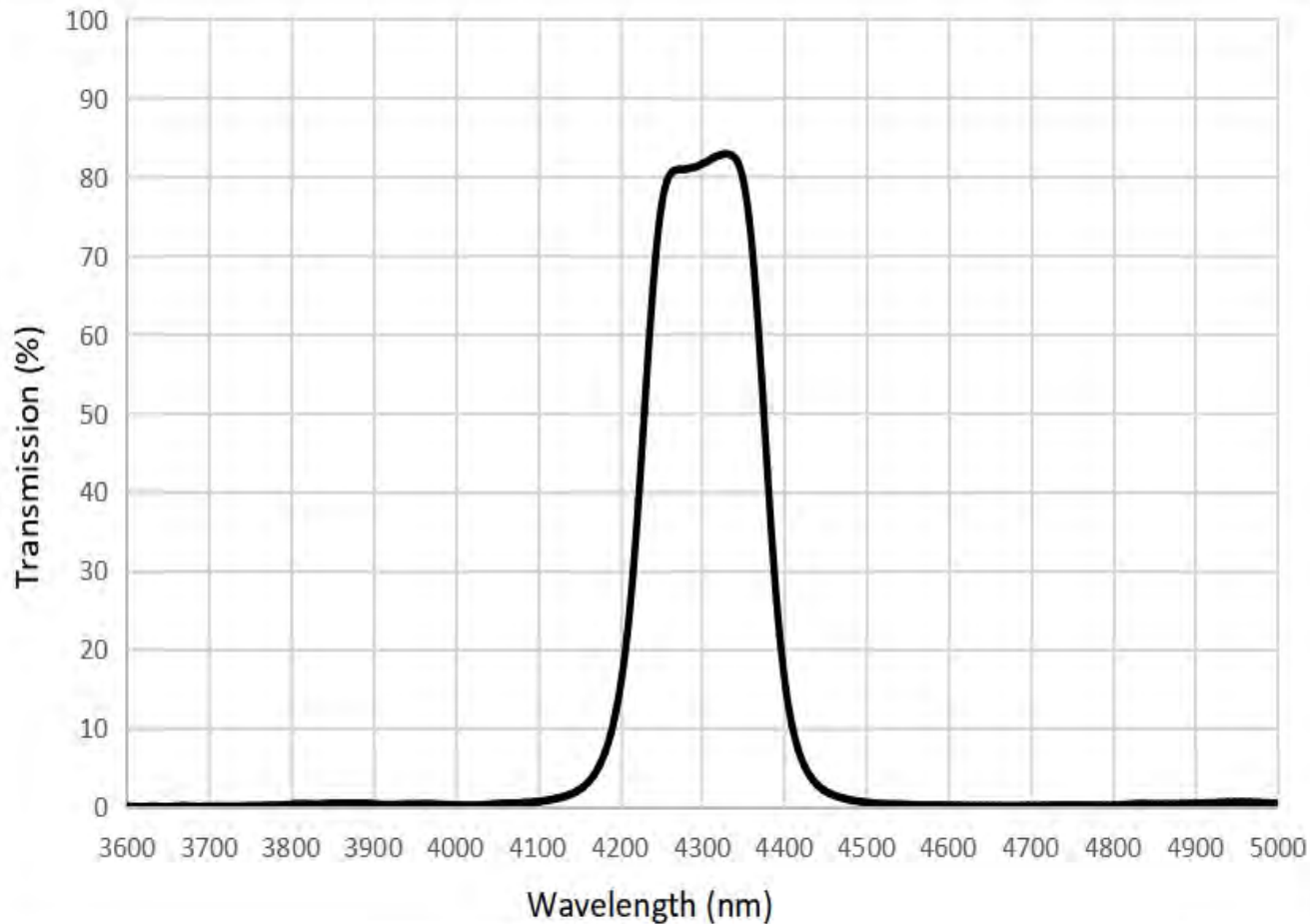
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25^*0.5\text{mm}$

Cutting service available.



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Name: NBP 4300 160nm

Base material: single-crystal silicon

Center wavelength (CWL): $4300 \pm 30\text{nm}$

Half wave width (FWHM): $160 \pm 20\text{nm}$

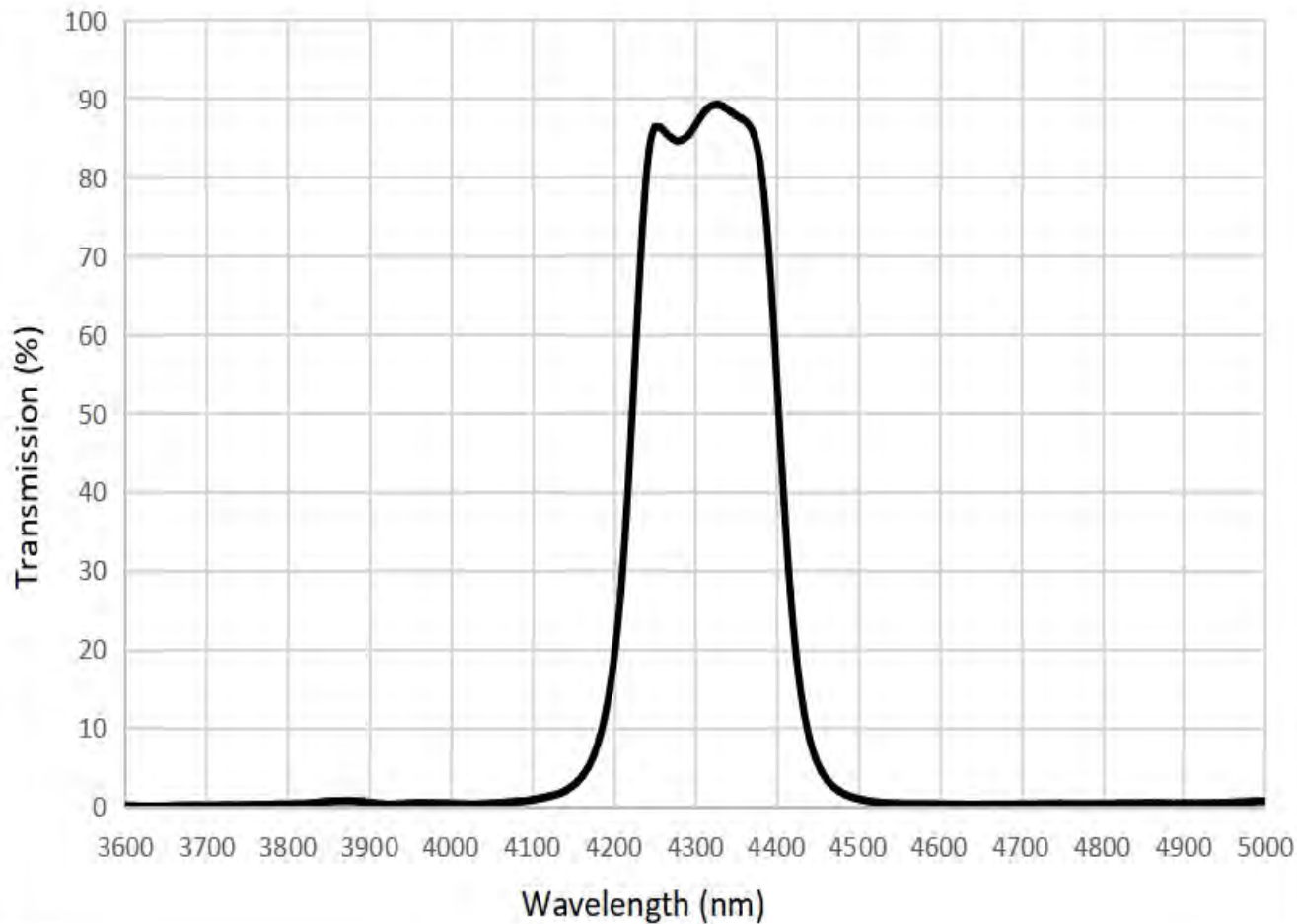
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for
Passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5\text{mm}$

Cutting service available.



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Name: NBP 4300 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4300 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

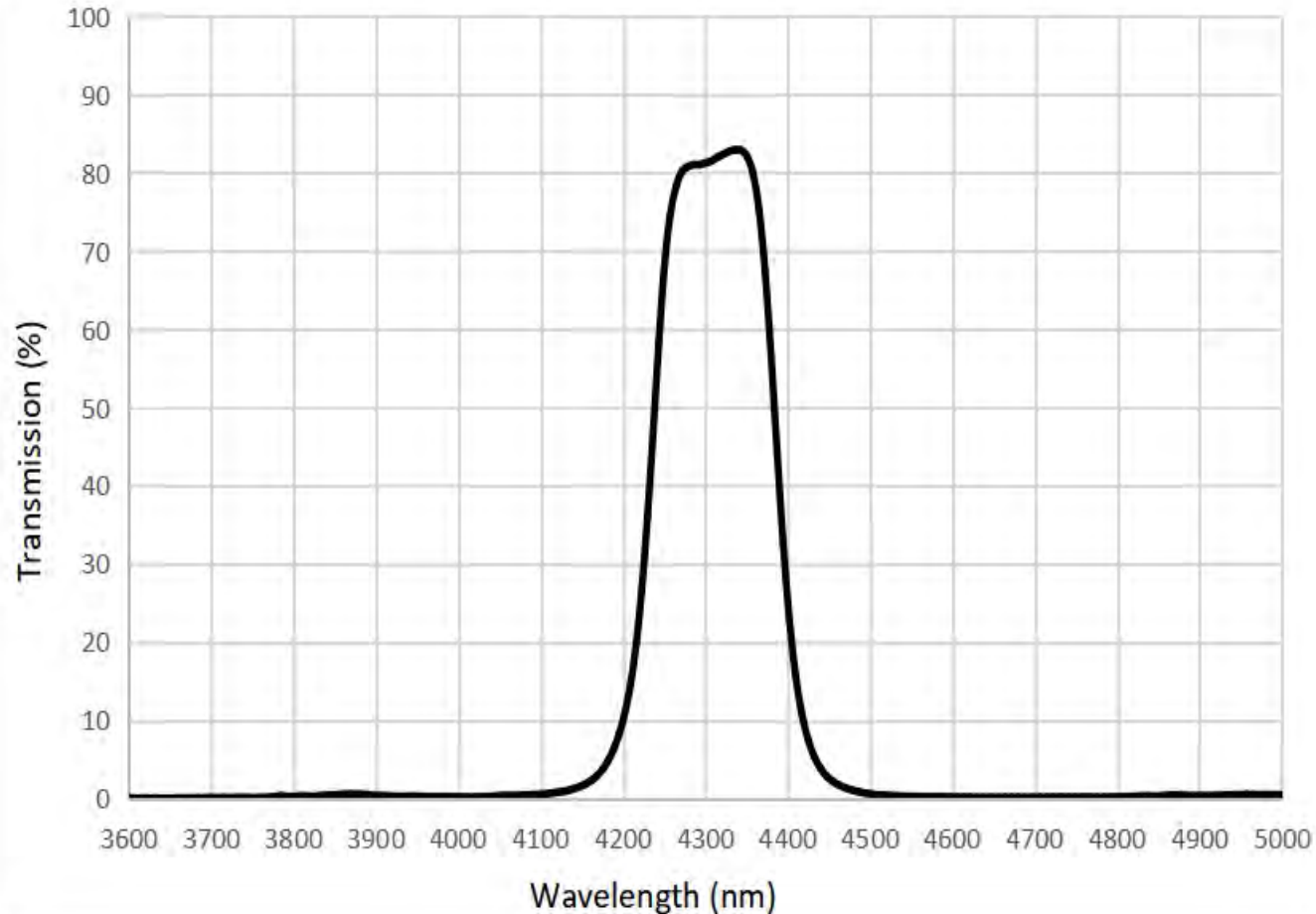
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for
passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4320 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 4320 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

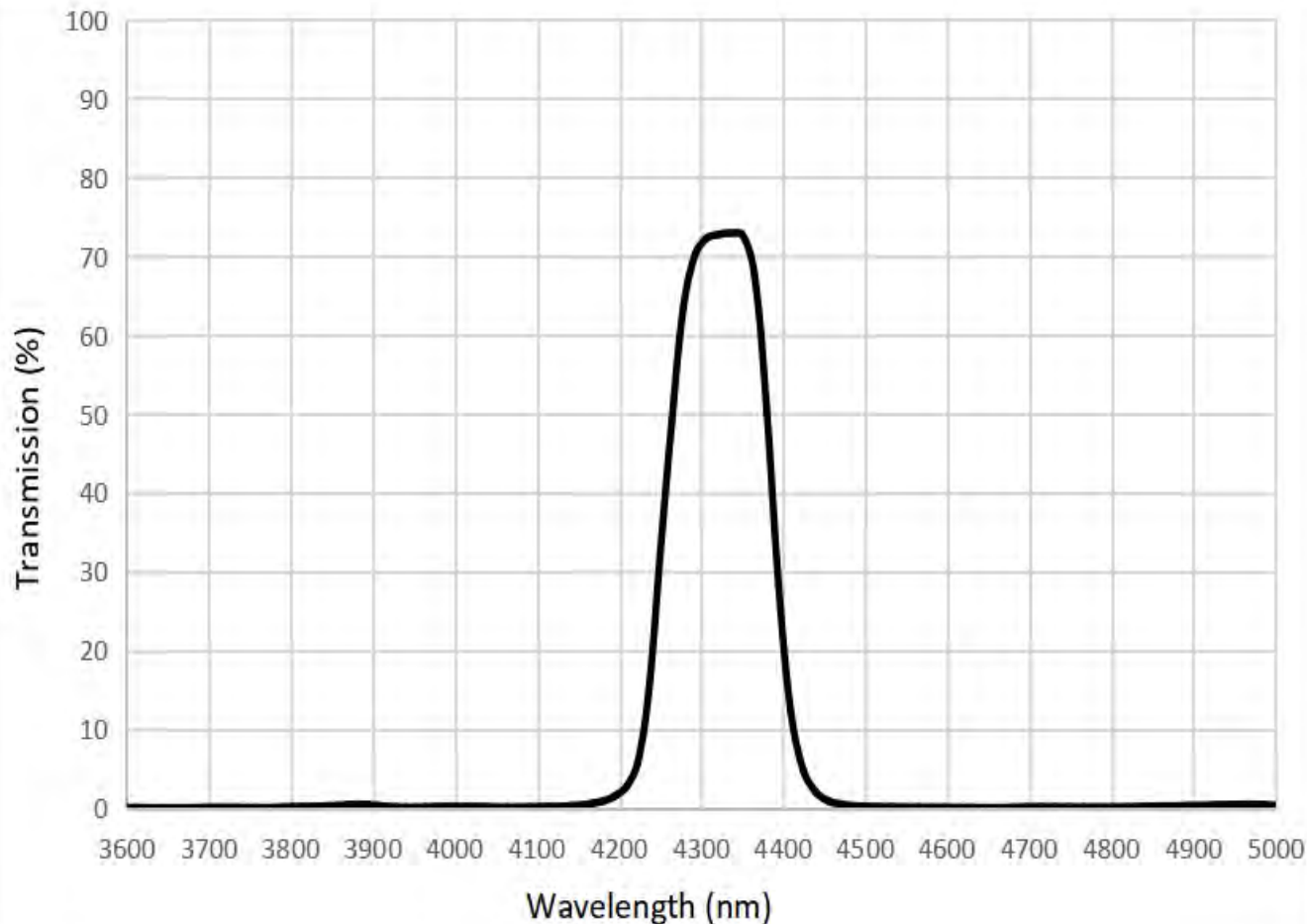
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4330 130nm

Base material: single-crystal silicon

Center wavelength (CWL): 4330 ± 30 nm

Half wave width (FWHM): 130 ± 20 nm

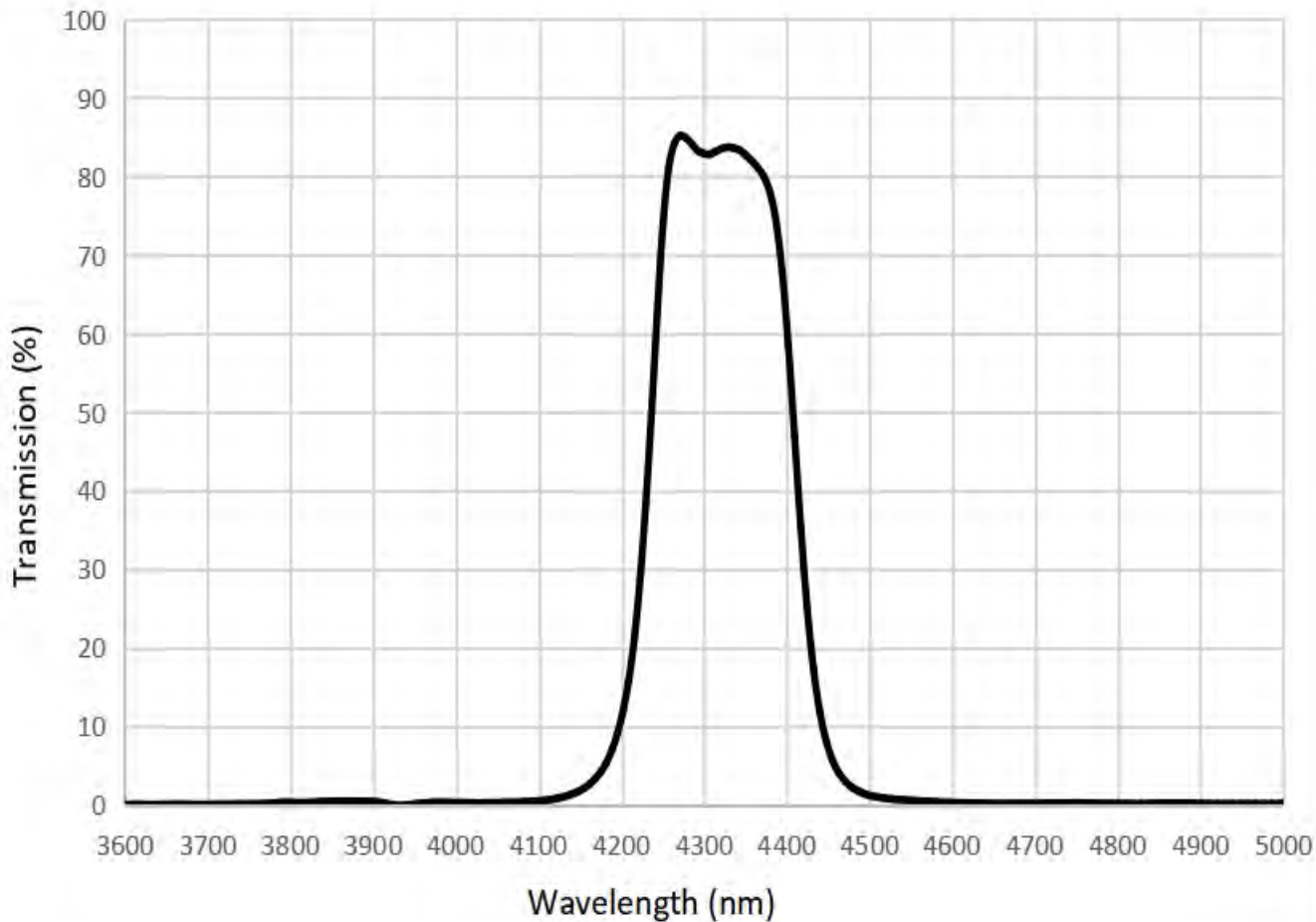
Peak Transmittance (T_p): $> 70\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4330 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4330 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

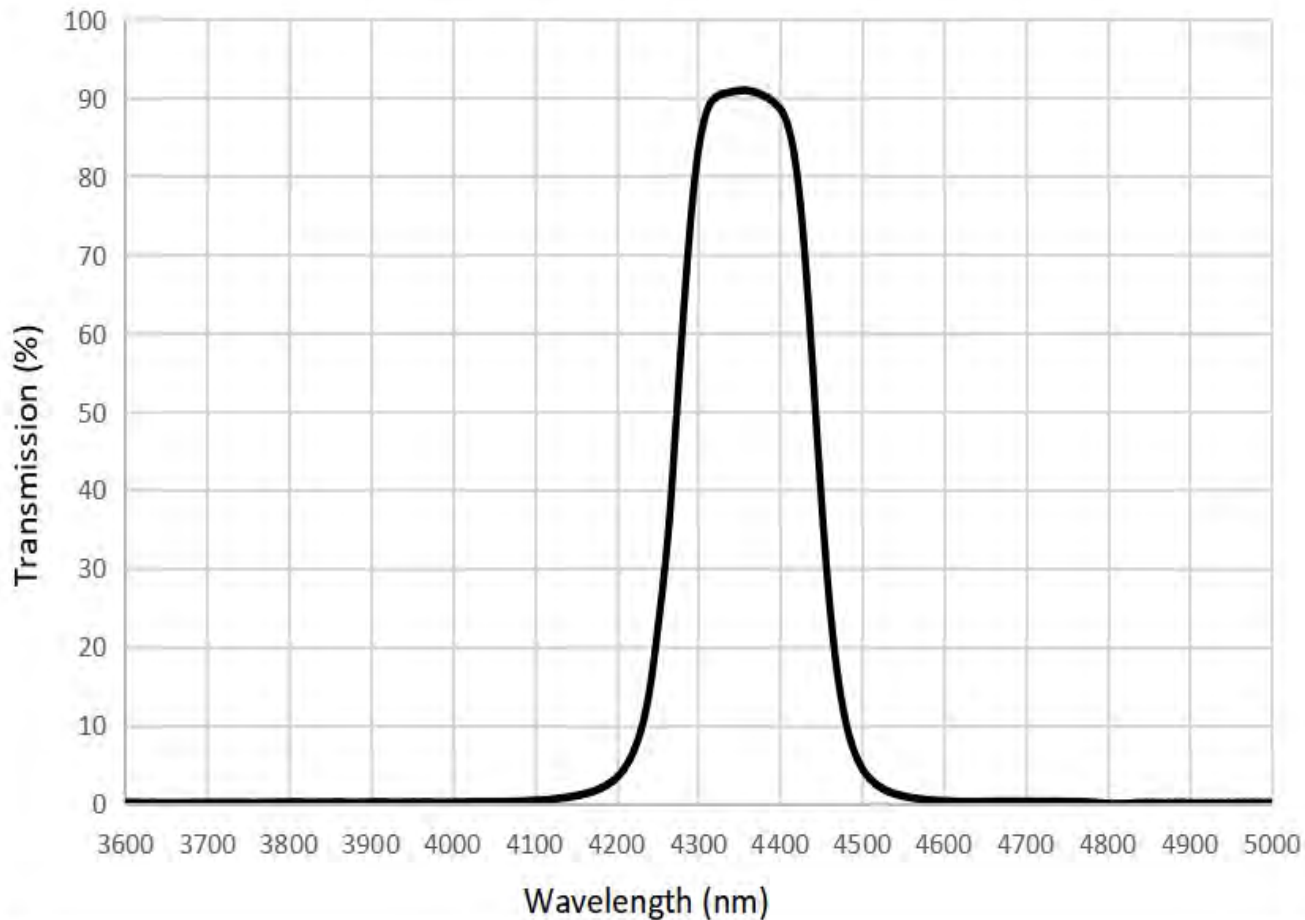
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 * 0.5$ mm

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Name: NBP 4360 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4360 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

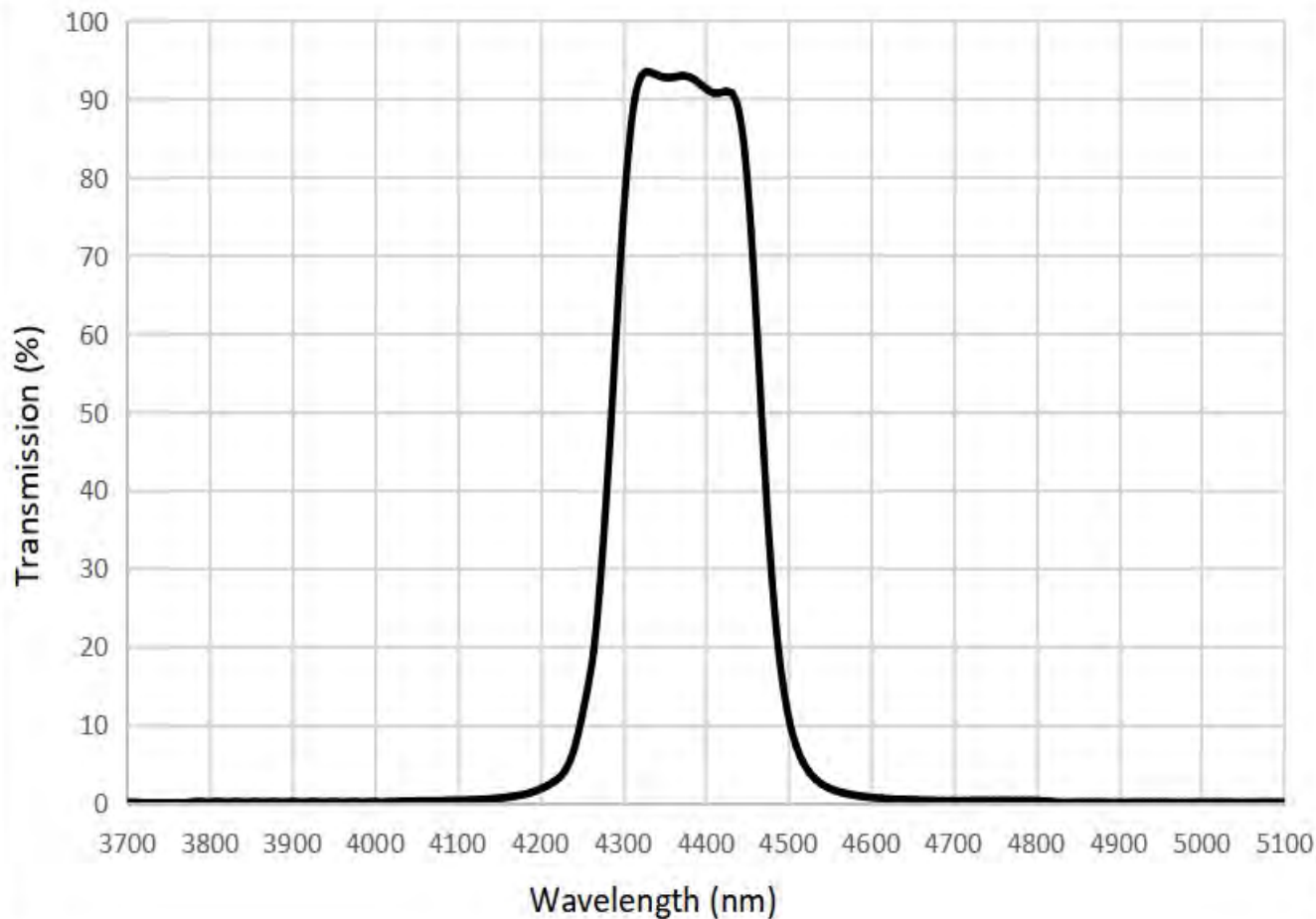
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.

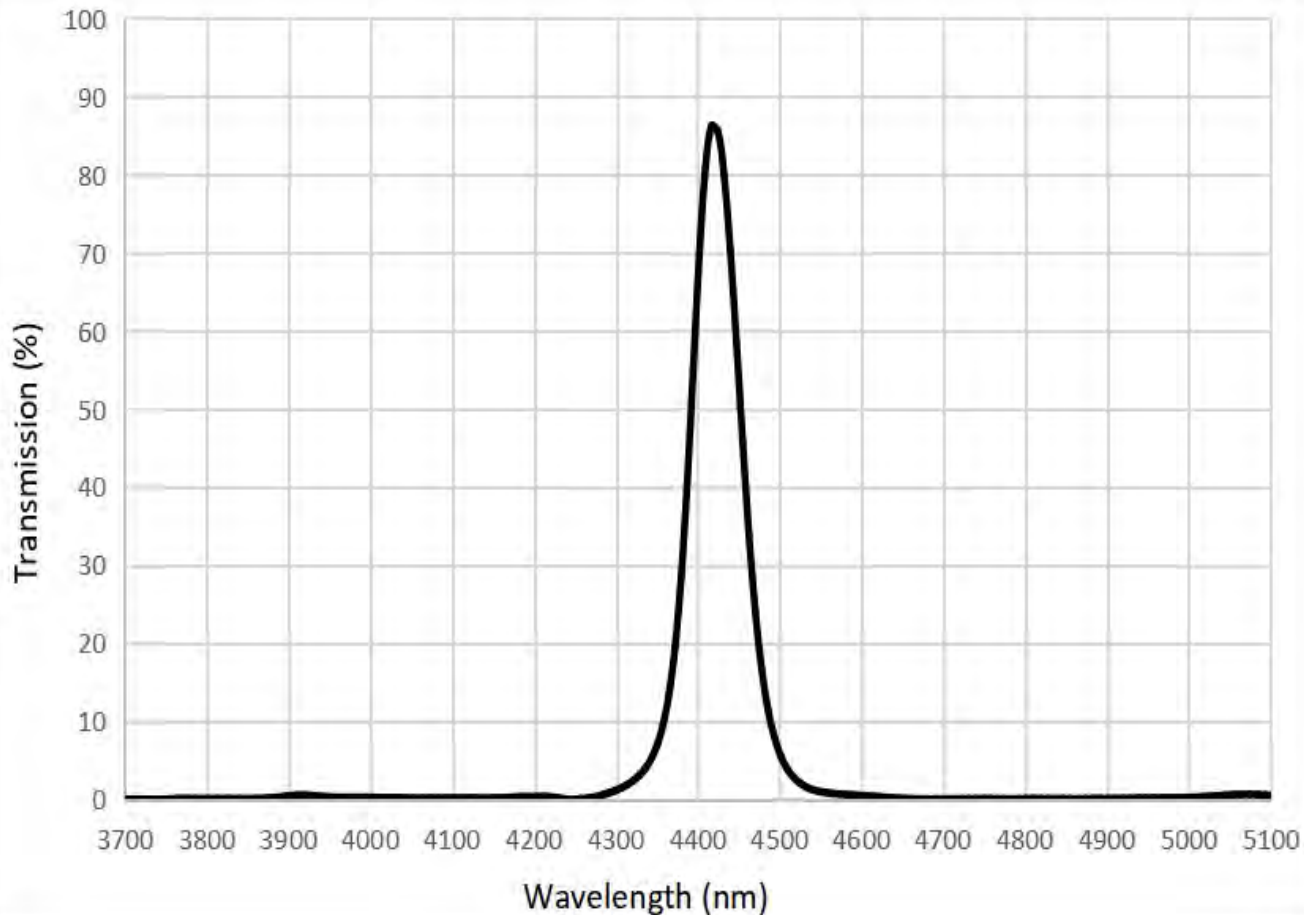


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Name: NBP 4380 180nm
Base material: single-crystal silicon
Center wavelength (CWL): 4380 ± 30 nm
Half wave width (FWHM): 180 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4420 60nm

Base material: single-crystal silicon

Center wavelength (CWL): 4420 ± 10 nm

Half wave width (FWHM): 60 ± 20 nm

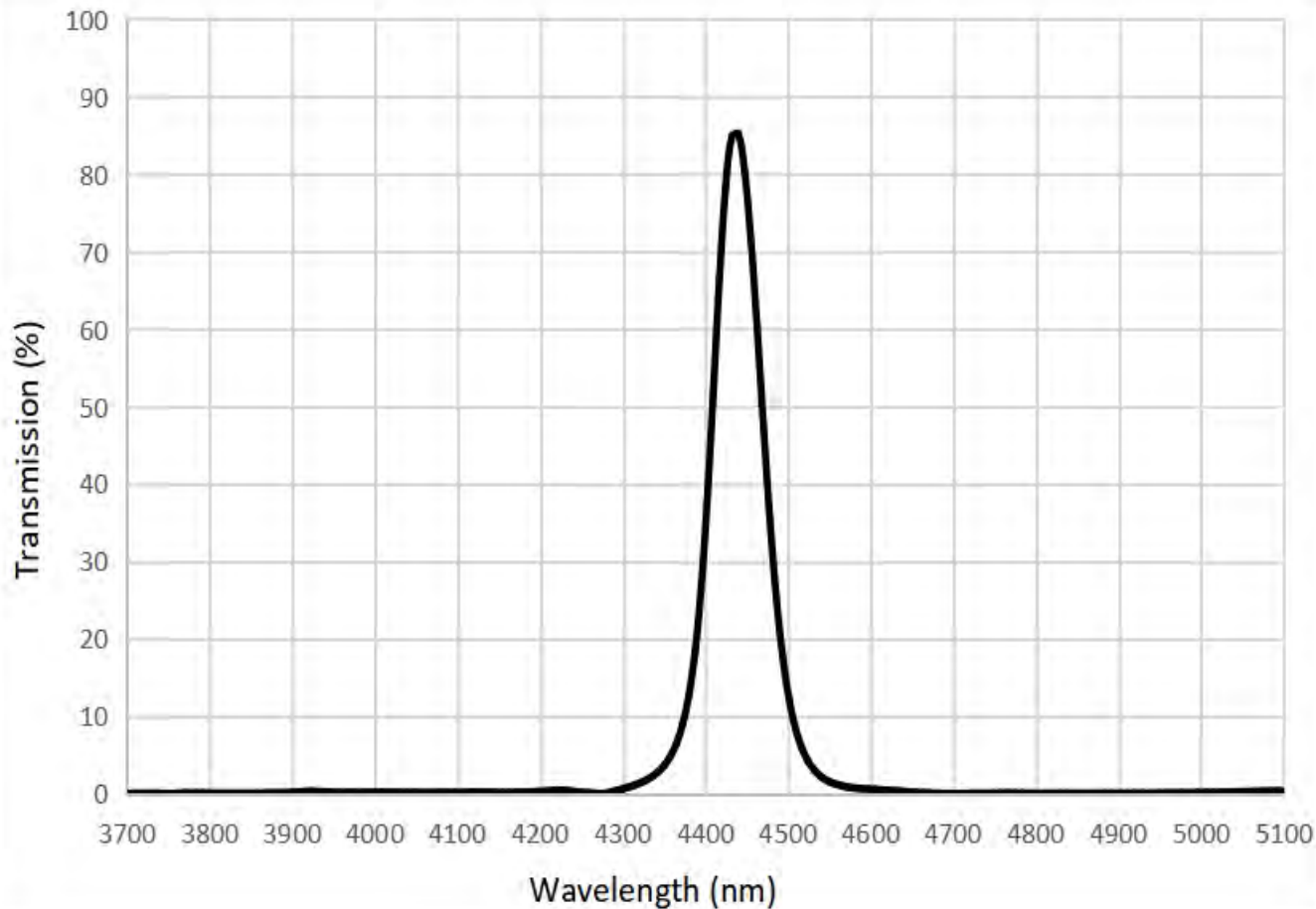
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.



Name: NBP 4430 60nm

Base material: single-crystal silicon

Center wavelength (CWL): 4430 ± 10 nm

Half wave width (FWHM): 60 ± 20 nm

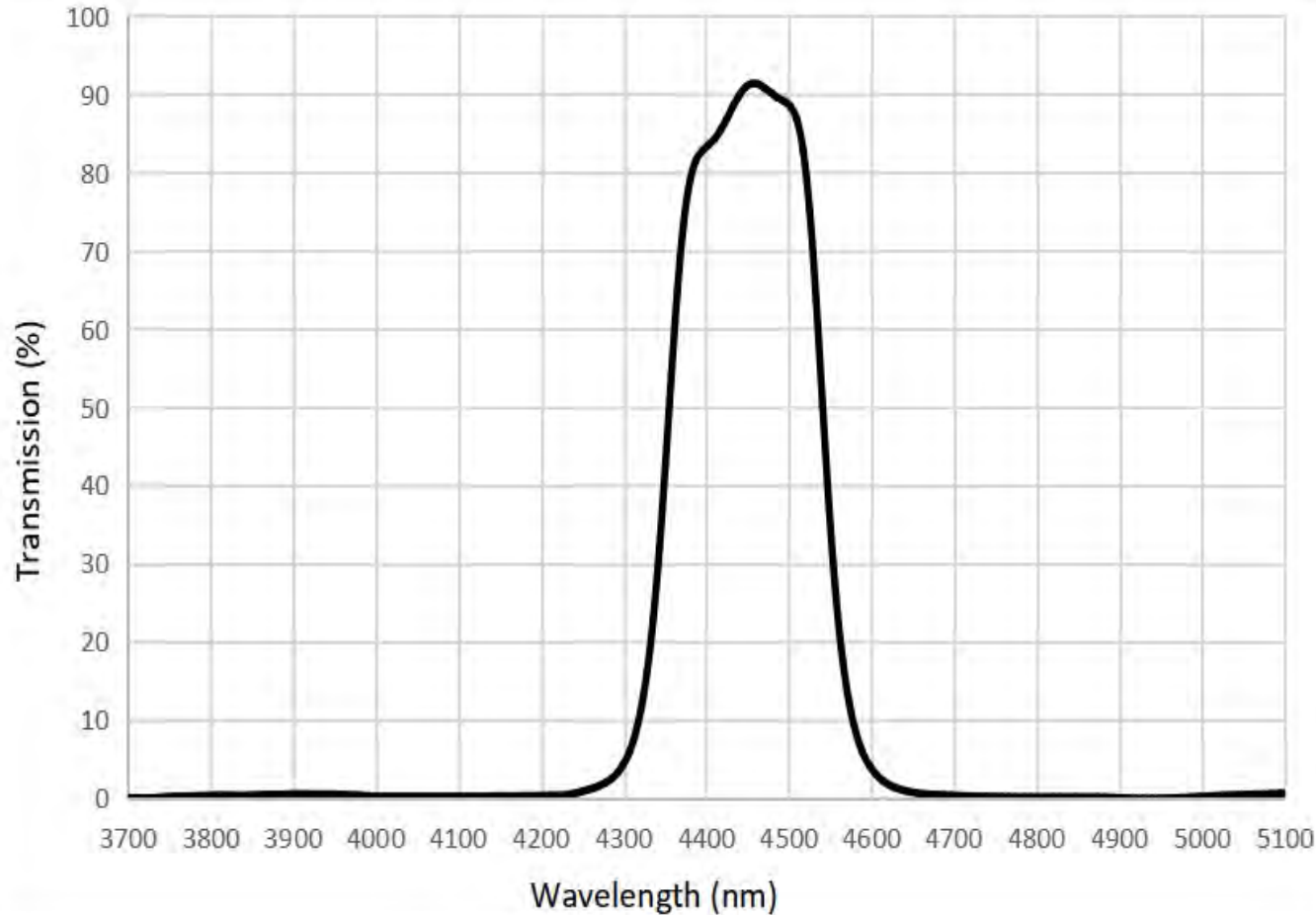
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 * 0.5$ mm

Cutting service available.



Name: NBP 4450 200nm

Base material: single-crystal silicon

Center wavelength (CWL): 4450 ± 30 nm

Half wave width (FWHM): 200 ± 20 nm

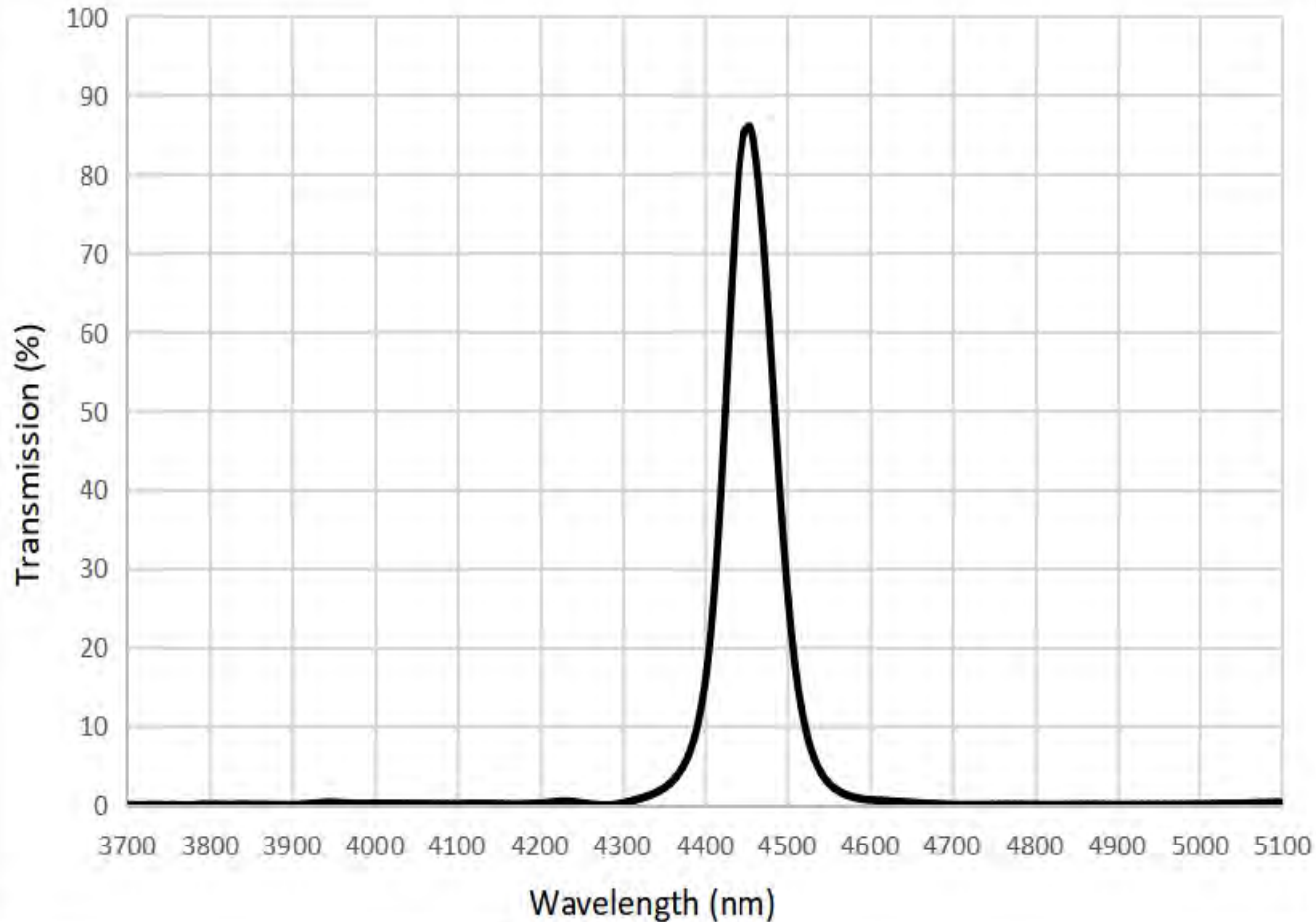
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

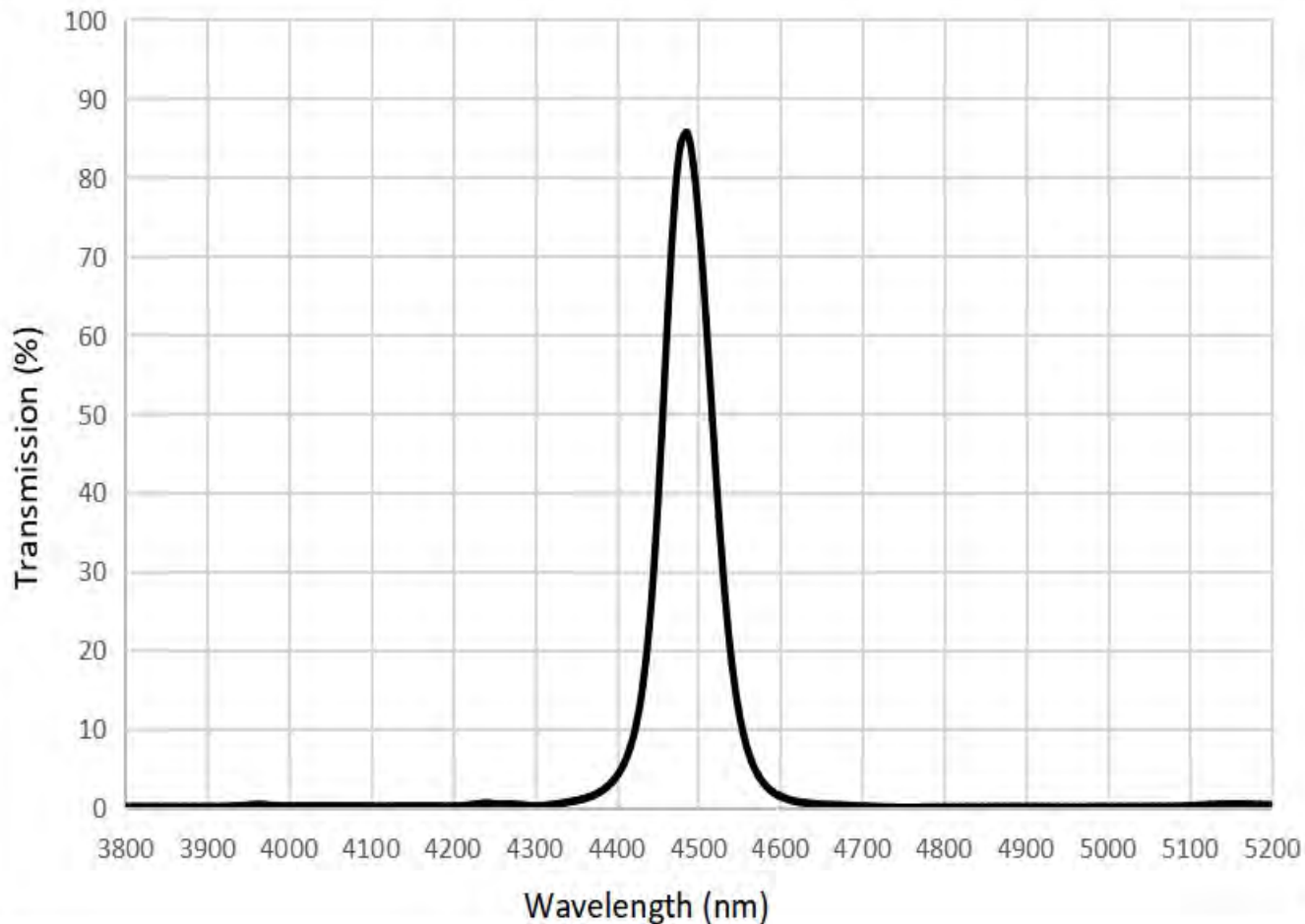
Cutting service available.



Name: NBP 4450 60nm
Base material: single-crystal silicon
Center wavelength (CWL): 4450 ± 10 nm
Half wave width (FWHM): 60 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.



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Name: NBP 4480 60nm

Base material: single-crystal silicon

Center wavelength (CWL): 4480 ± 10 nm

Half wave width (FWHM): 60 ± 20 nm

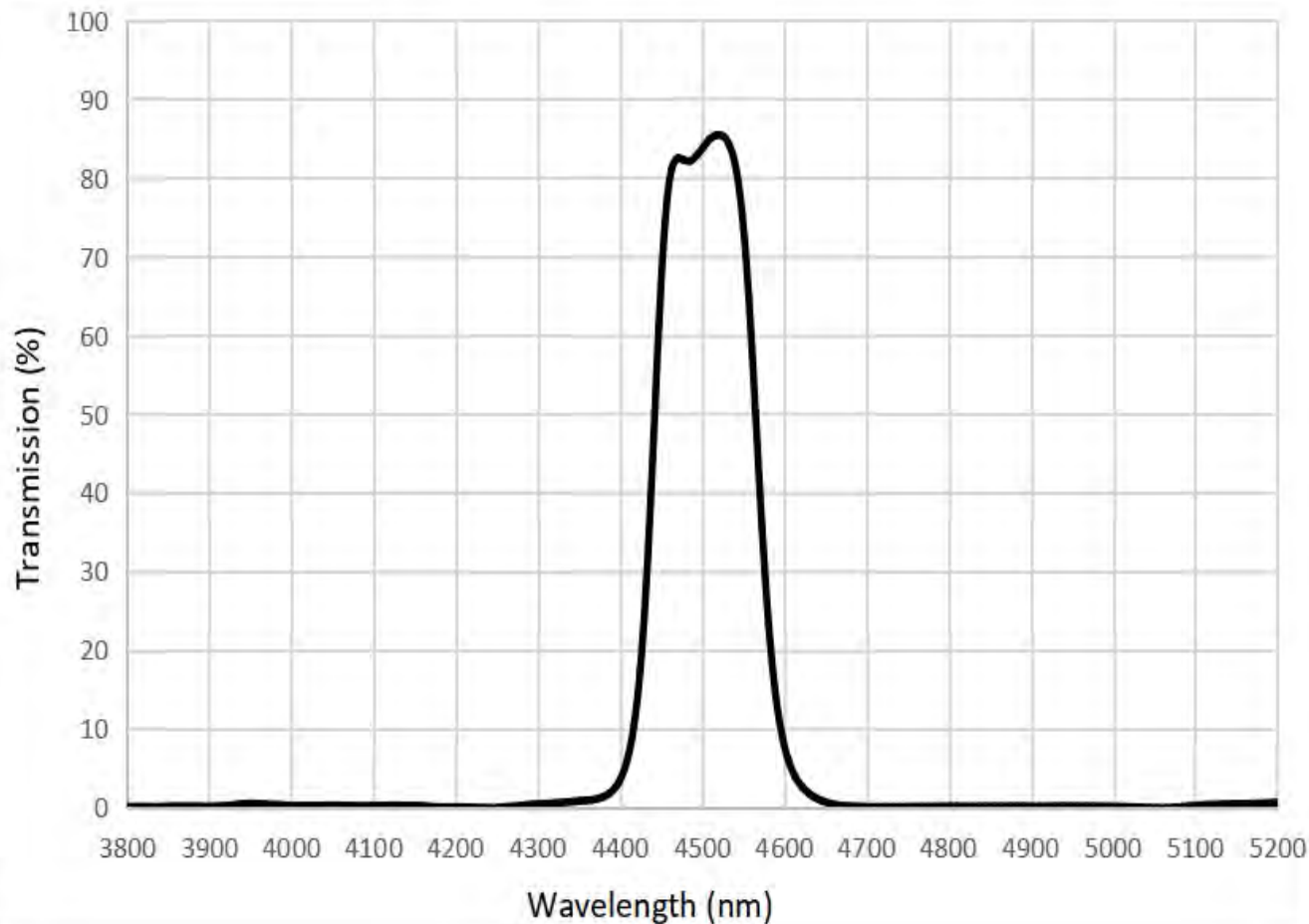
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.



Name: NBP 4500 140nm

Base material: single-crystal silicon

Center wavelength (CWL): 4500 ± 30 nm

Half wave width (FWHM): 140 ± 20 nm

Peak Transmittance (T_p): $> 80\%$

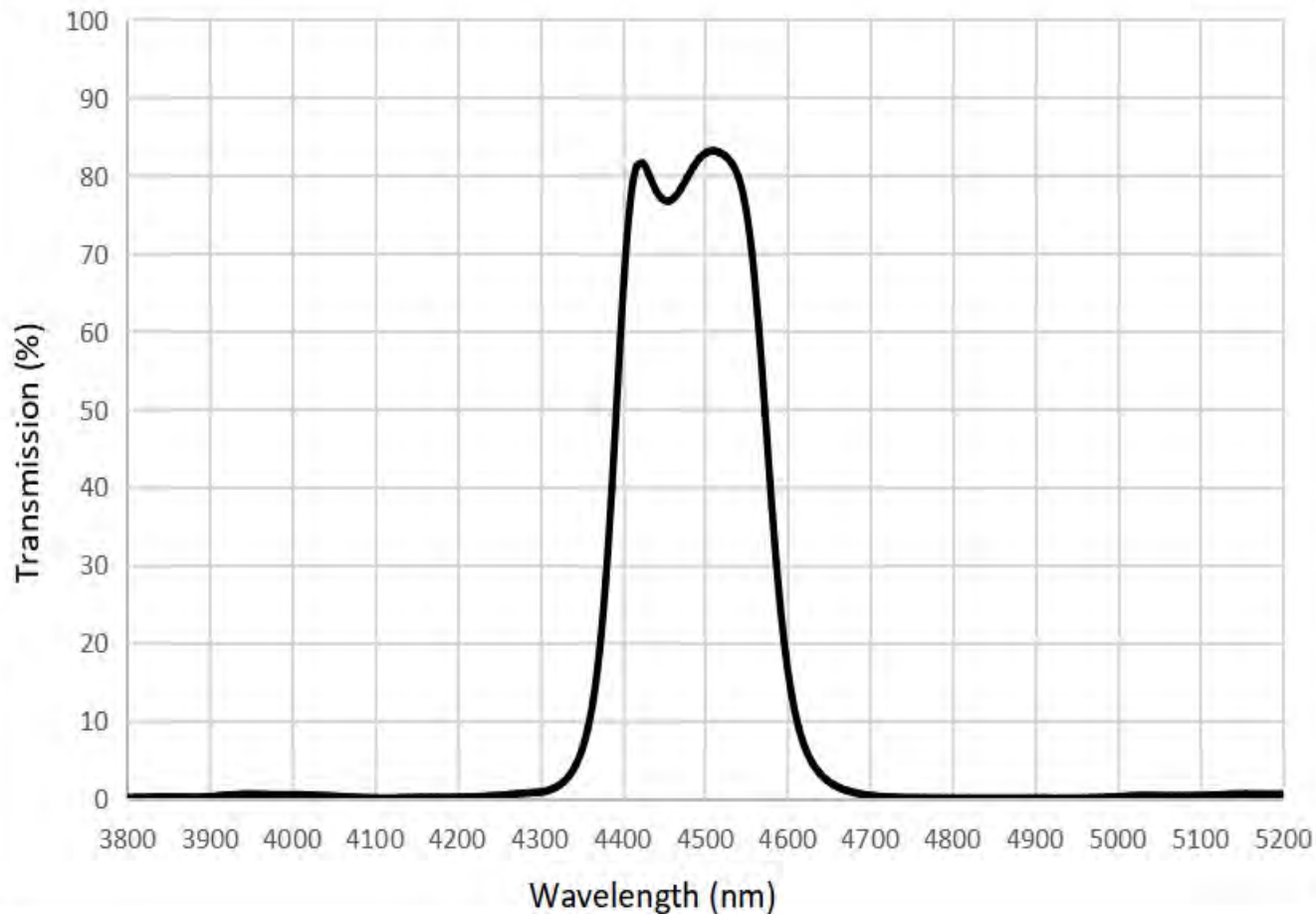
Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.

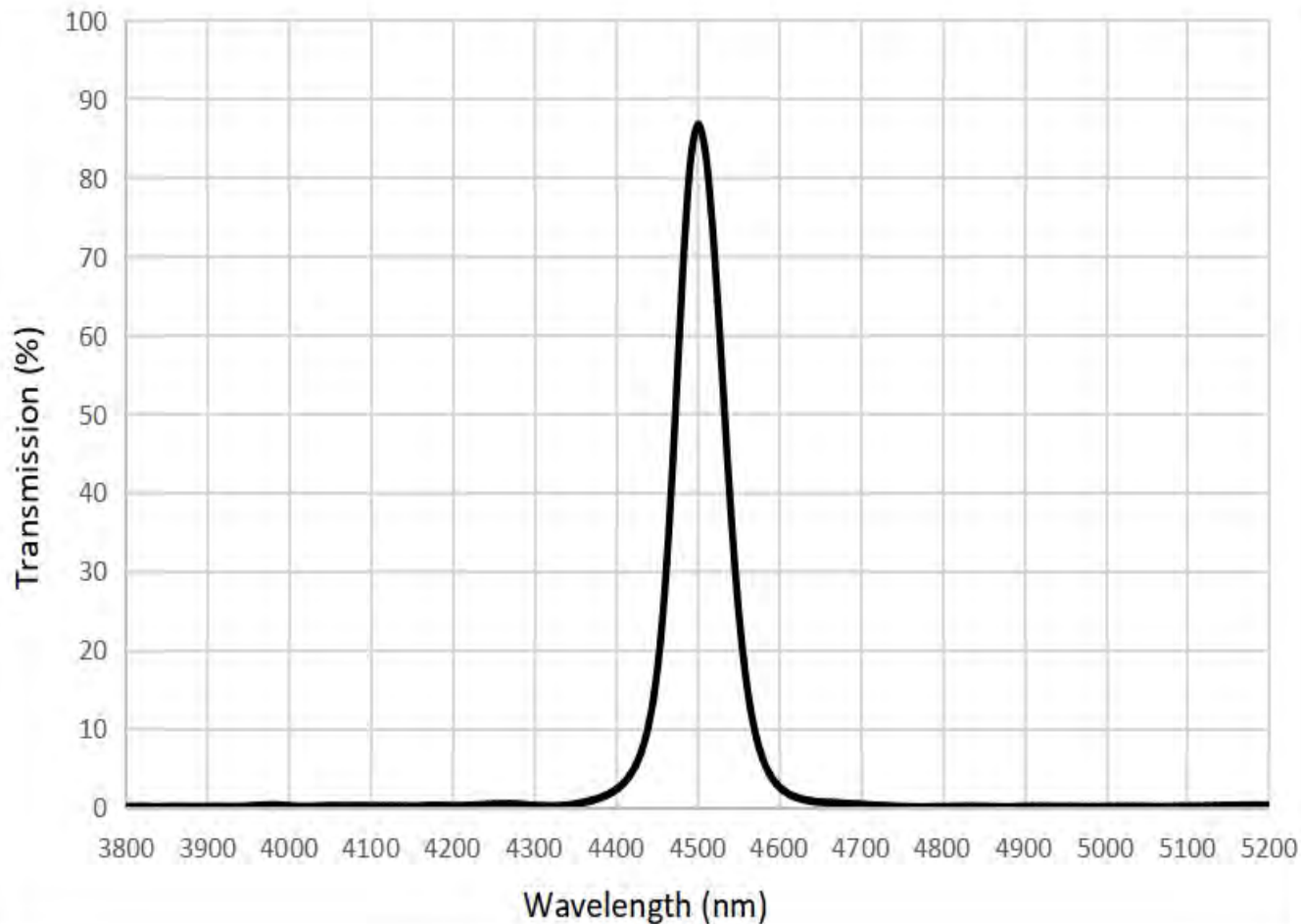
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Base material: single-crystal silicon
Center wavelength (CWL): 4500 ± 30 nm
Half wave width (FWHM): 200 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4500 60nm

Base material: single-crystal silicon

Center wavelength (CWL): 4500 ± 10 nm

Half wave width (FWHM): 60 ± 20 nm

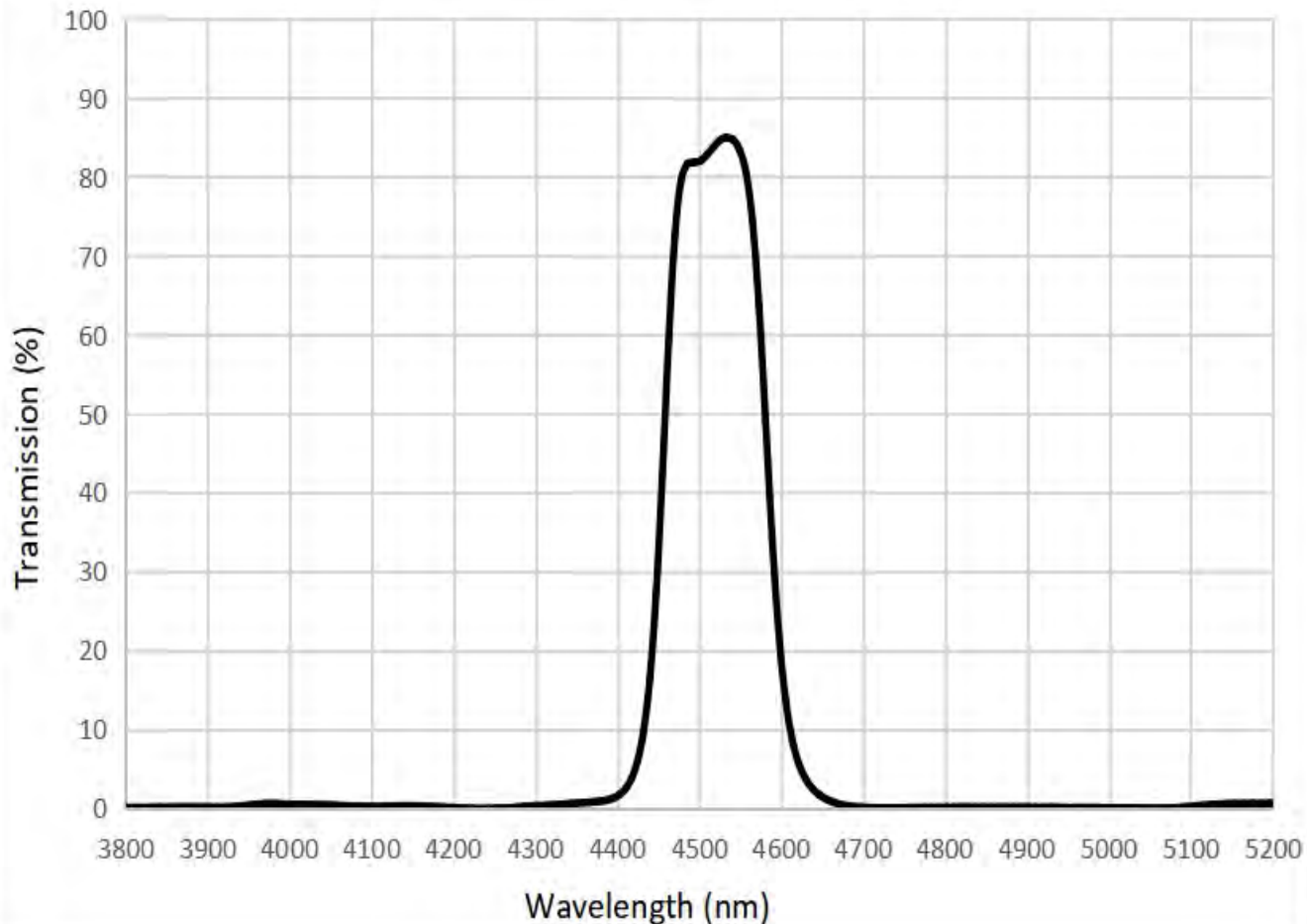
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

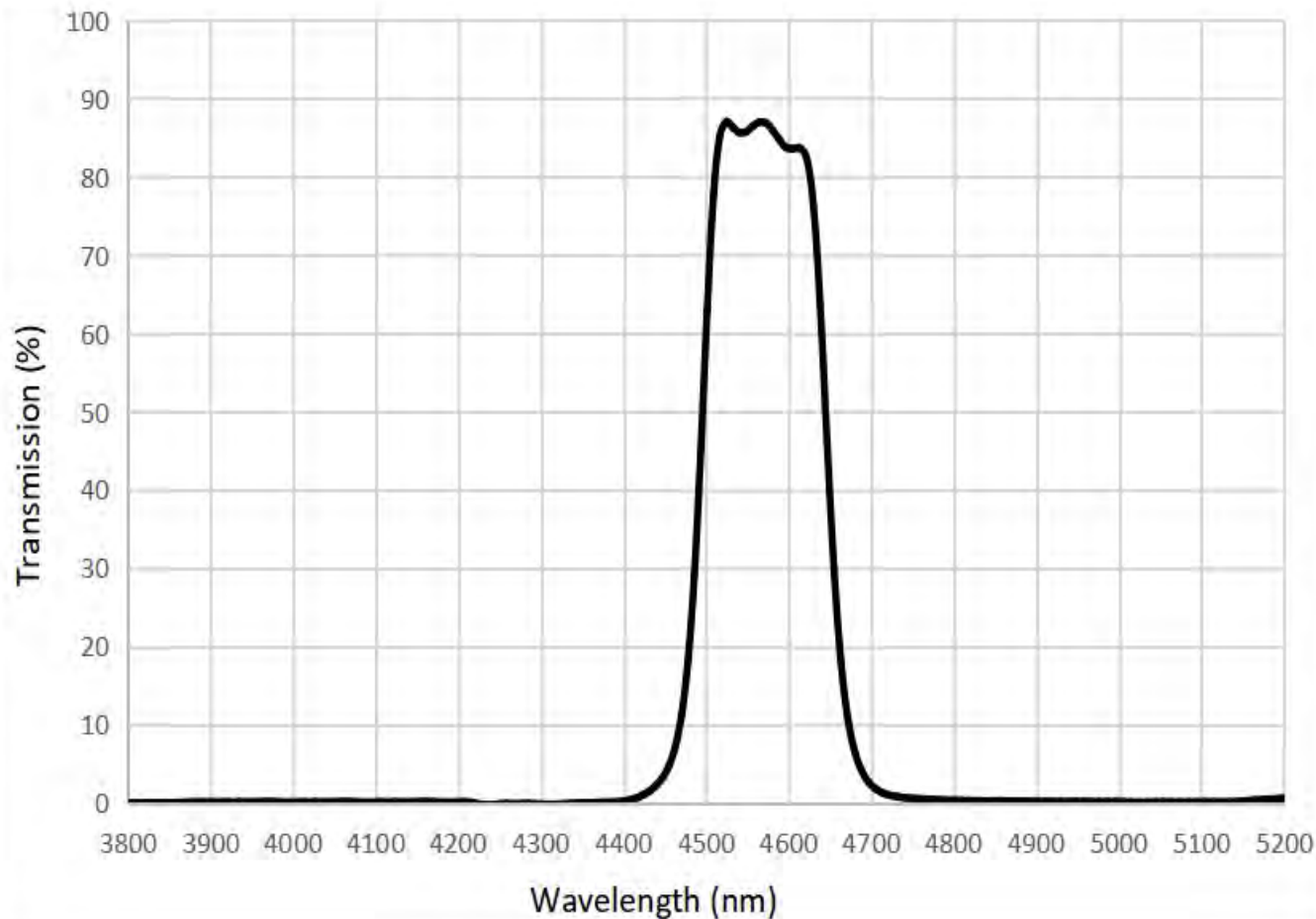
Cutting service available.



Name: NBP 4520 140nm
Base material: single-crystal silicon
Center wavelength (CWL): 4520 ± 30 nm
Half wave width (FWHM): 140 ± 20 nm
Peak Transmittance (T_p): $> 80\%$
Cutoff range (Except for passband): 400-11000nm
Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4560 150nm

Base material: single-crystal silicon

Center wavelength (CWL): 4560 ± 30 nm

Half wave width (FWHM): 150 ± 20 nm

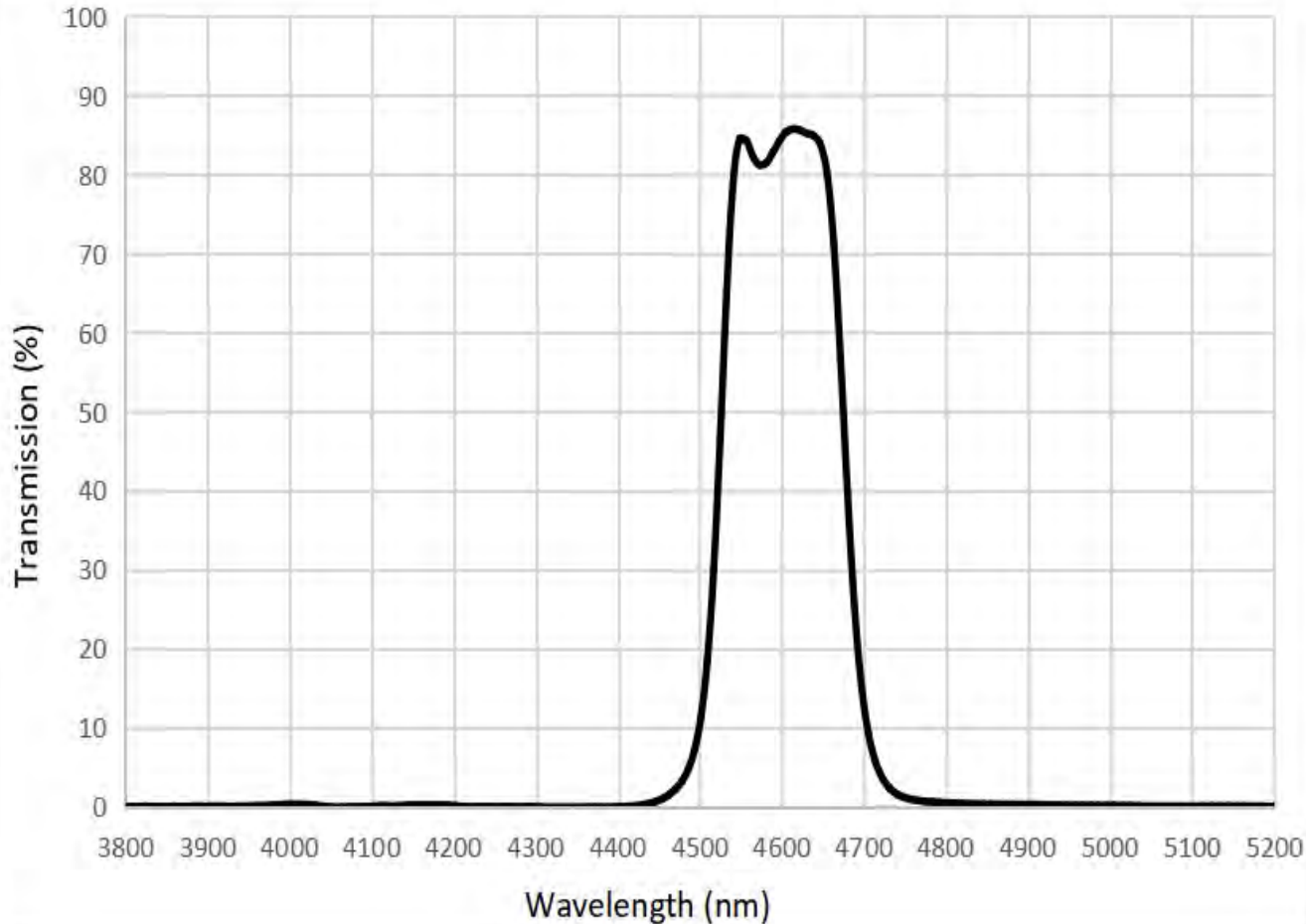
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4600 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 4600±30nm

Half wave width (FWHM): 160±20nm

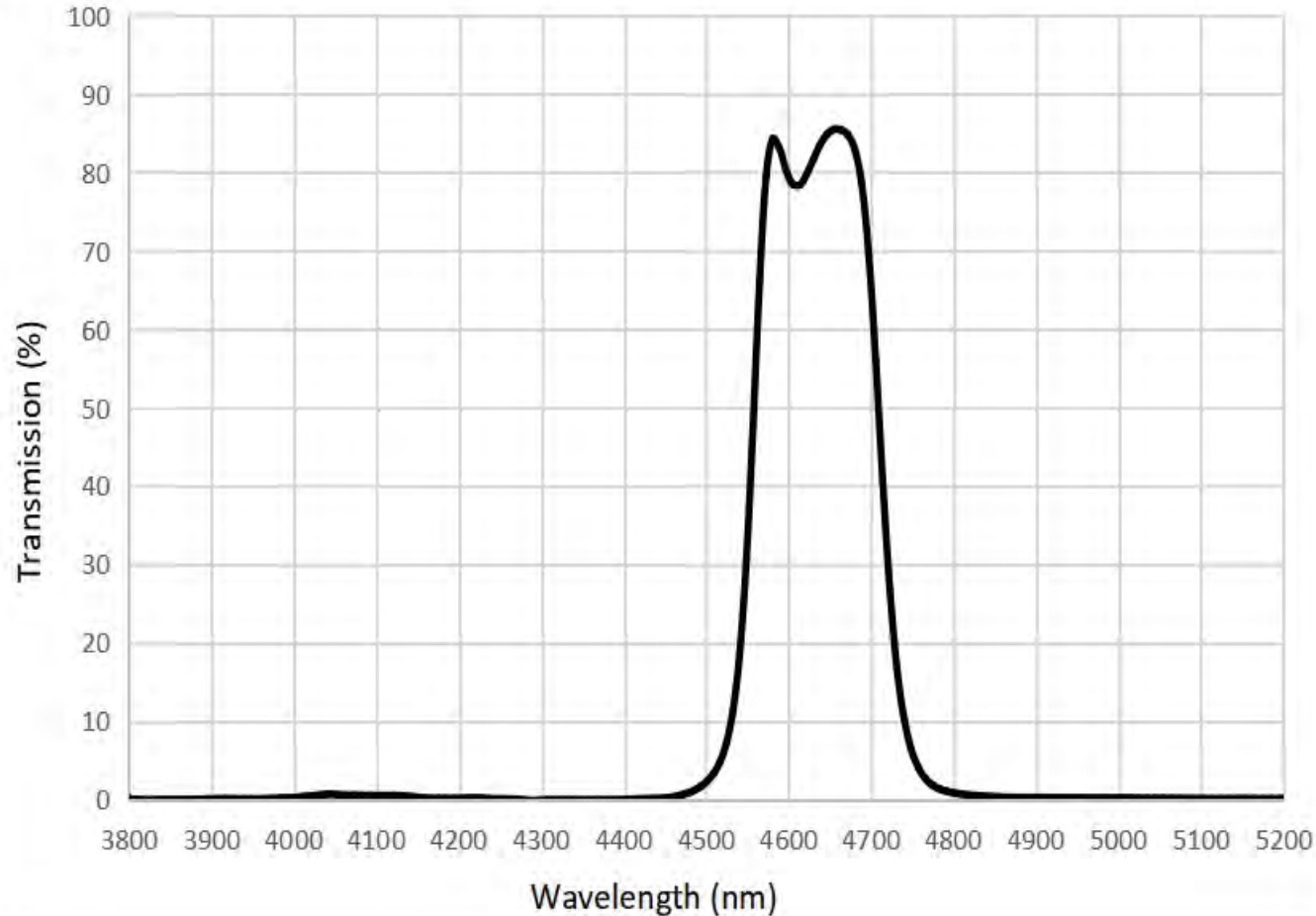
Peak Transmittance (Tp): >80%

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



Name: NBP 4640 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 4640 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

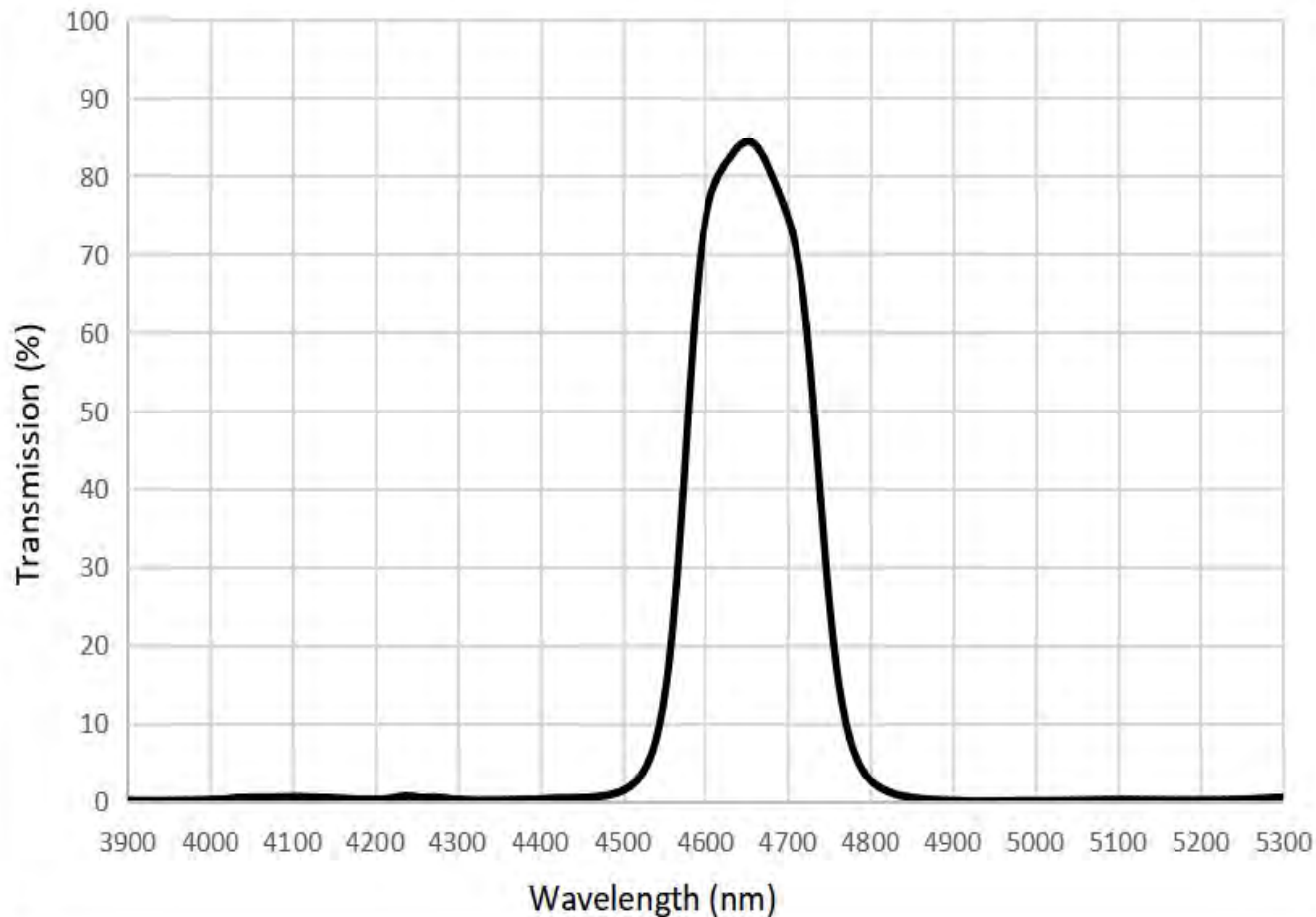
Peak Transmittance (Tp): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 4650 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 4650 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

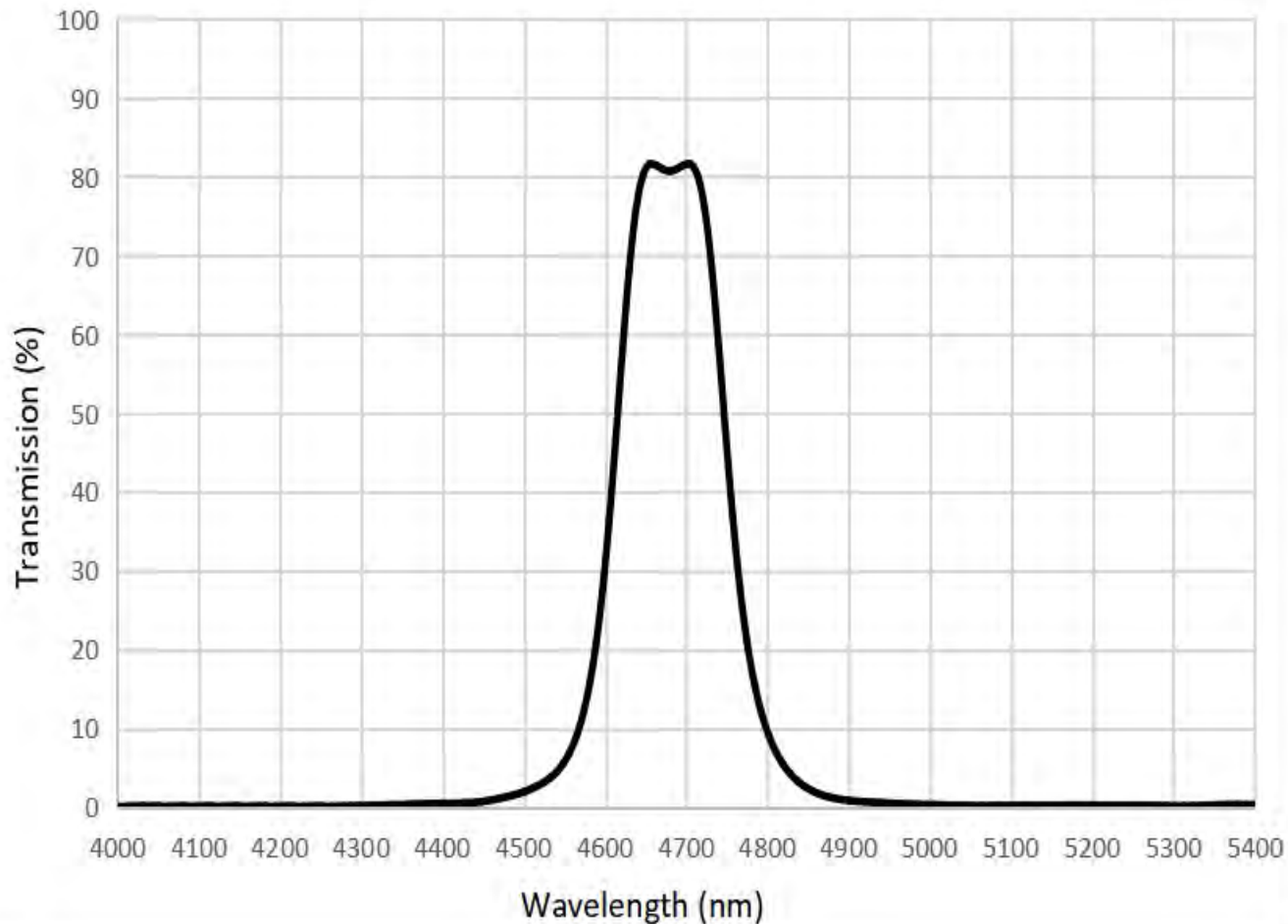
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4680 150nm

Base material: sapphire

Center wavelength (CWL): 4680 ± 30 nm

Half wave width (FWHM): 150 ± 20 nm

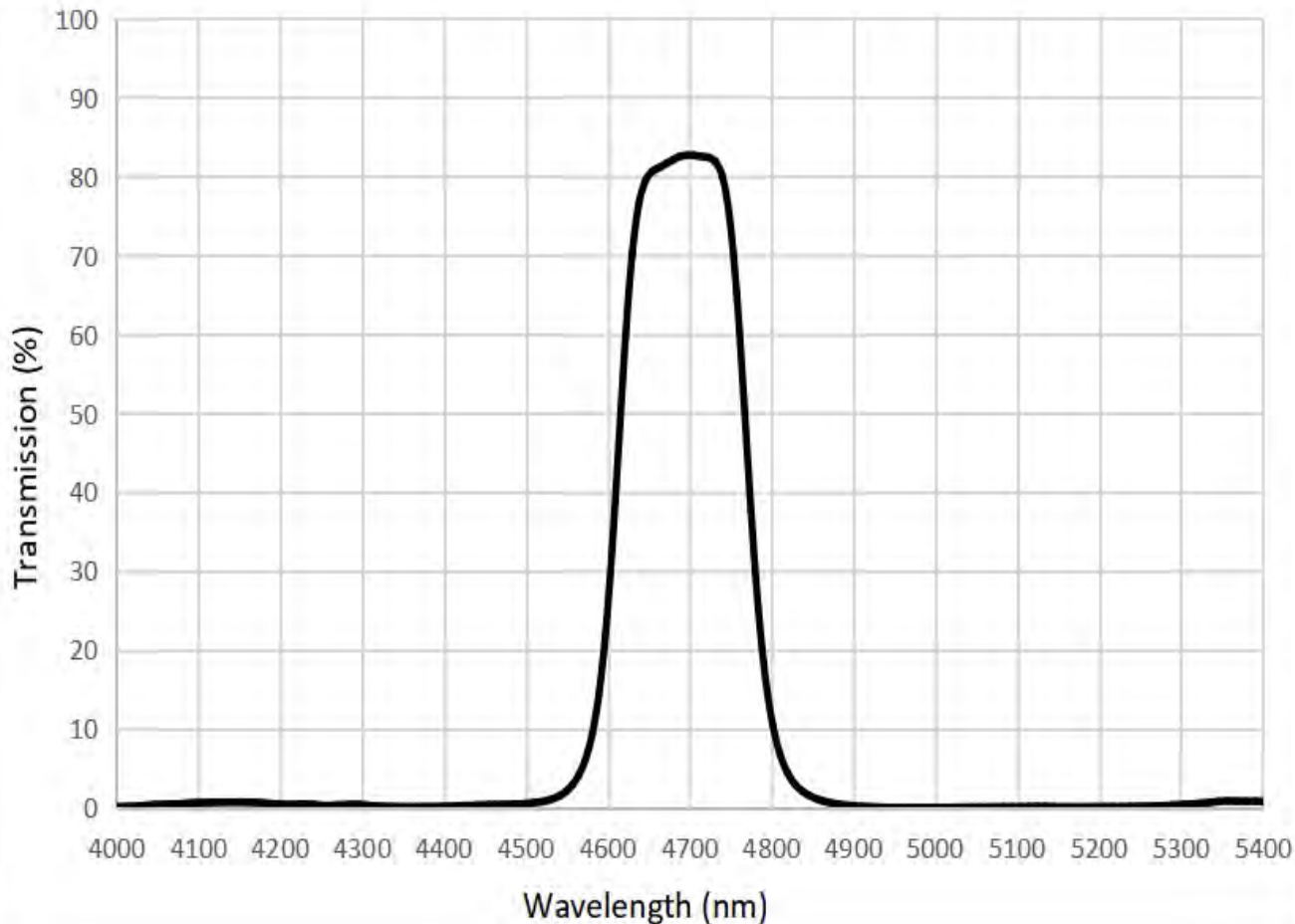
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for
passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.8$ mm

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Name: NBP 4690 160nm

Base material: single-crystal silicon

Center wavelength (CWL): 4690 ± 30 nm

Half wave width (FWHM): 160 ± 20 nm

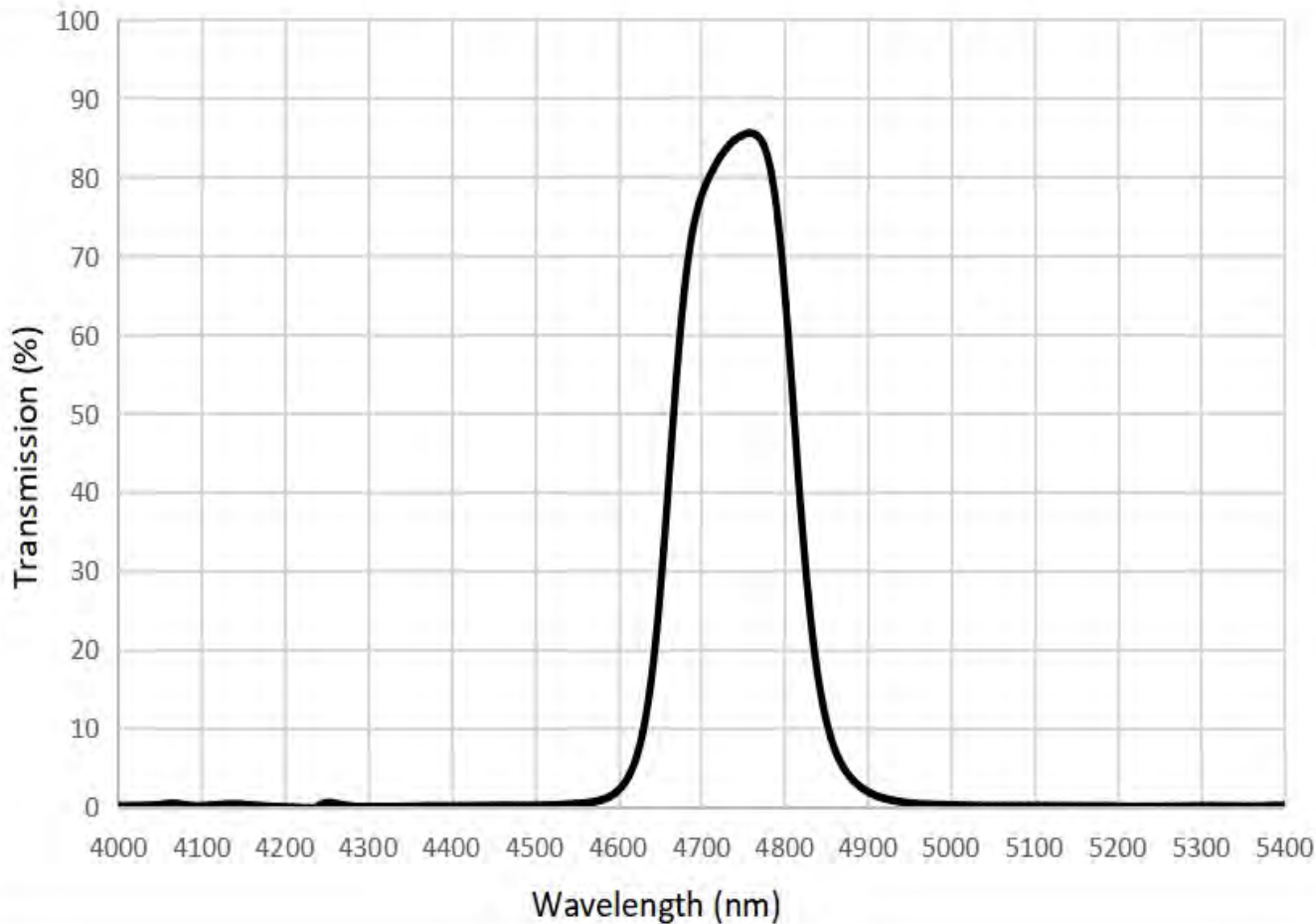
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

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Name: NBP 4750 180nm

Base material: single-crystal silicon

Center wavelength (CWL): 4750 ± 30 nm

Half wave width (FWHM): 180 ± 20 nm

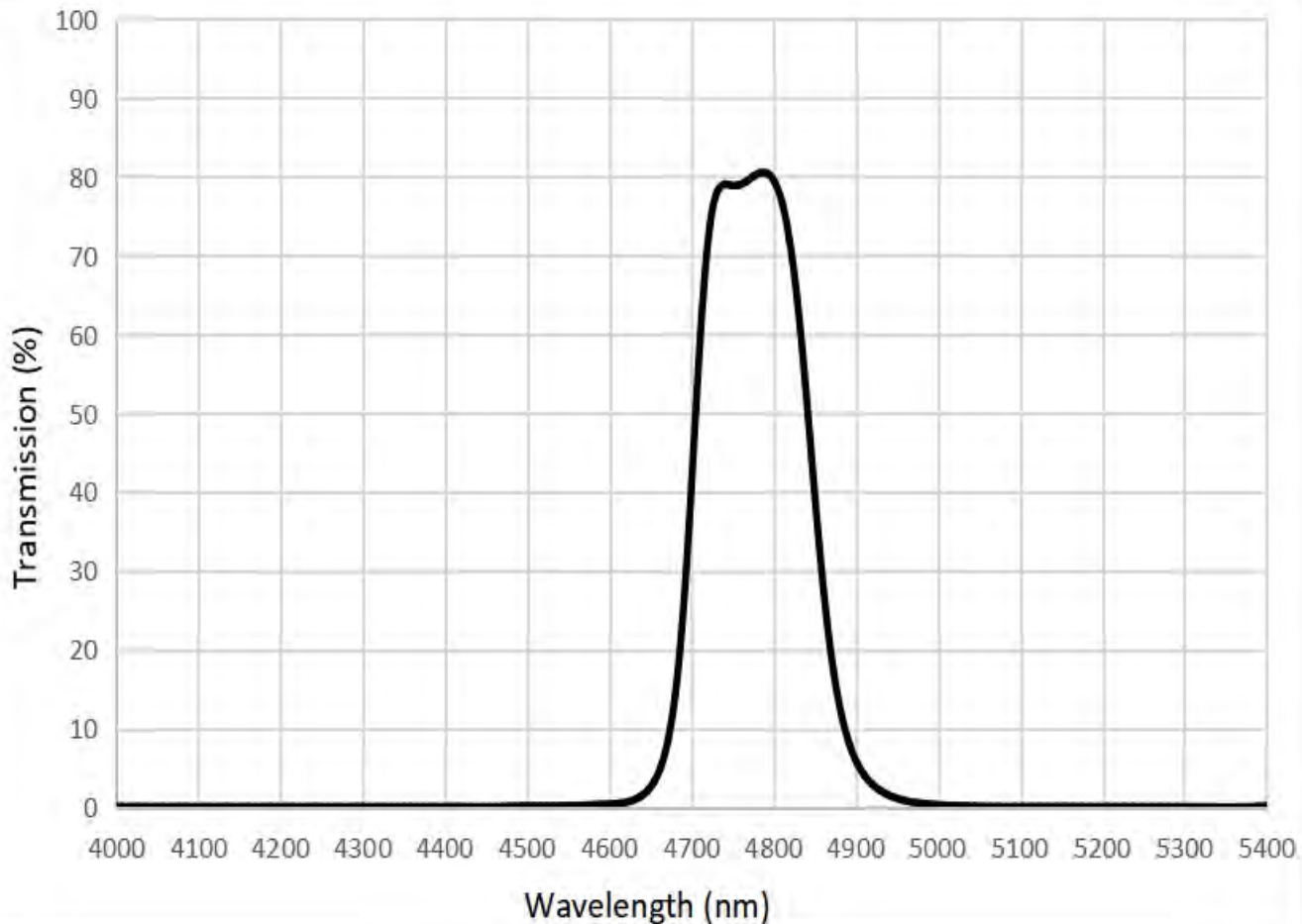
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 4770 150nm

Base material: single-crystal silicon

Center wavelength (CWL): 4770 ± 30 nm

Half wave width (FWHM): 150 ± 20 nm

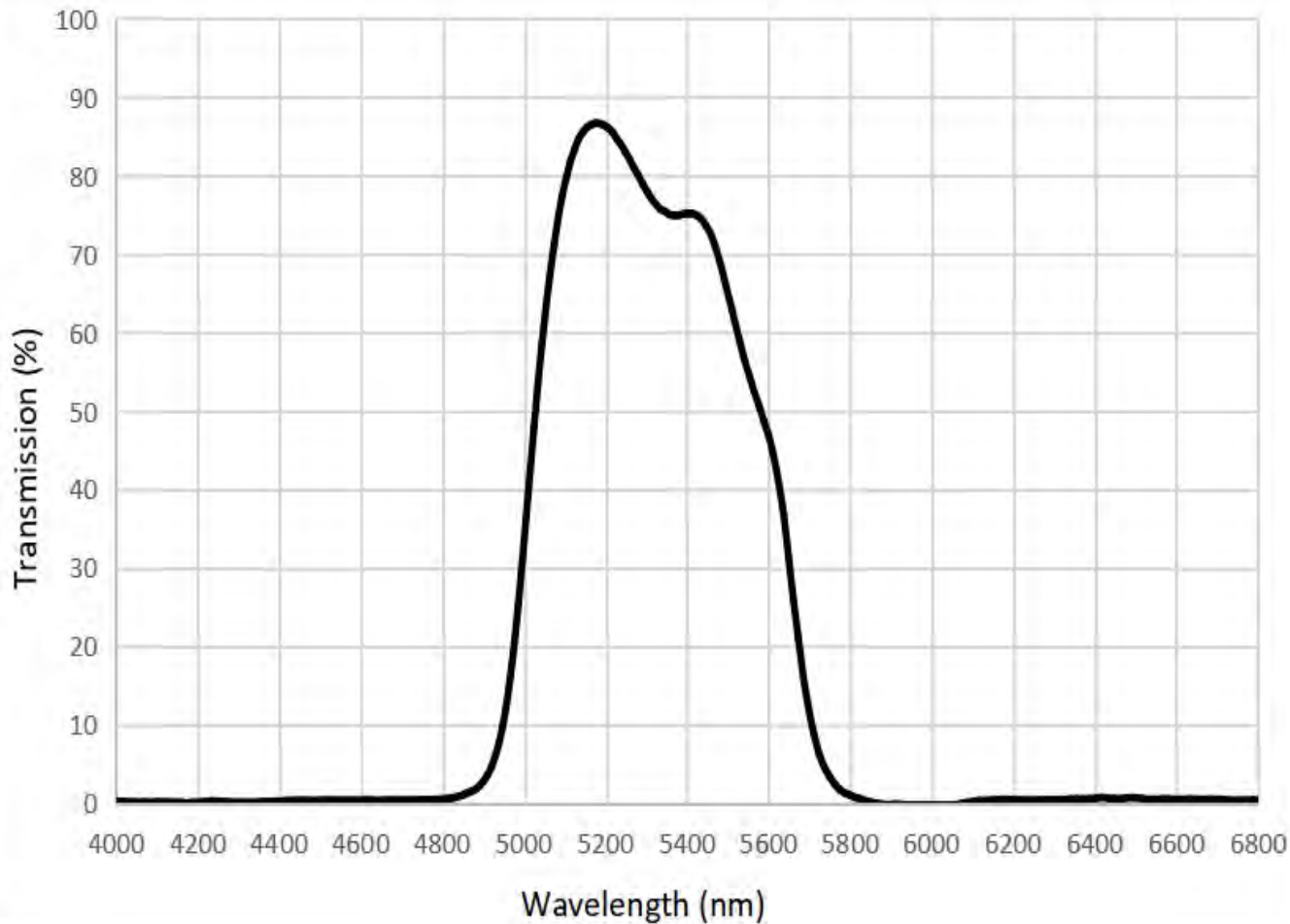
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 5300 600nm

Base material: single-crystal silicon

Center wavelength (CWL): 5300 ± 40 nm

Half wave width (FWHM): 600 ± 30 nm

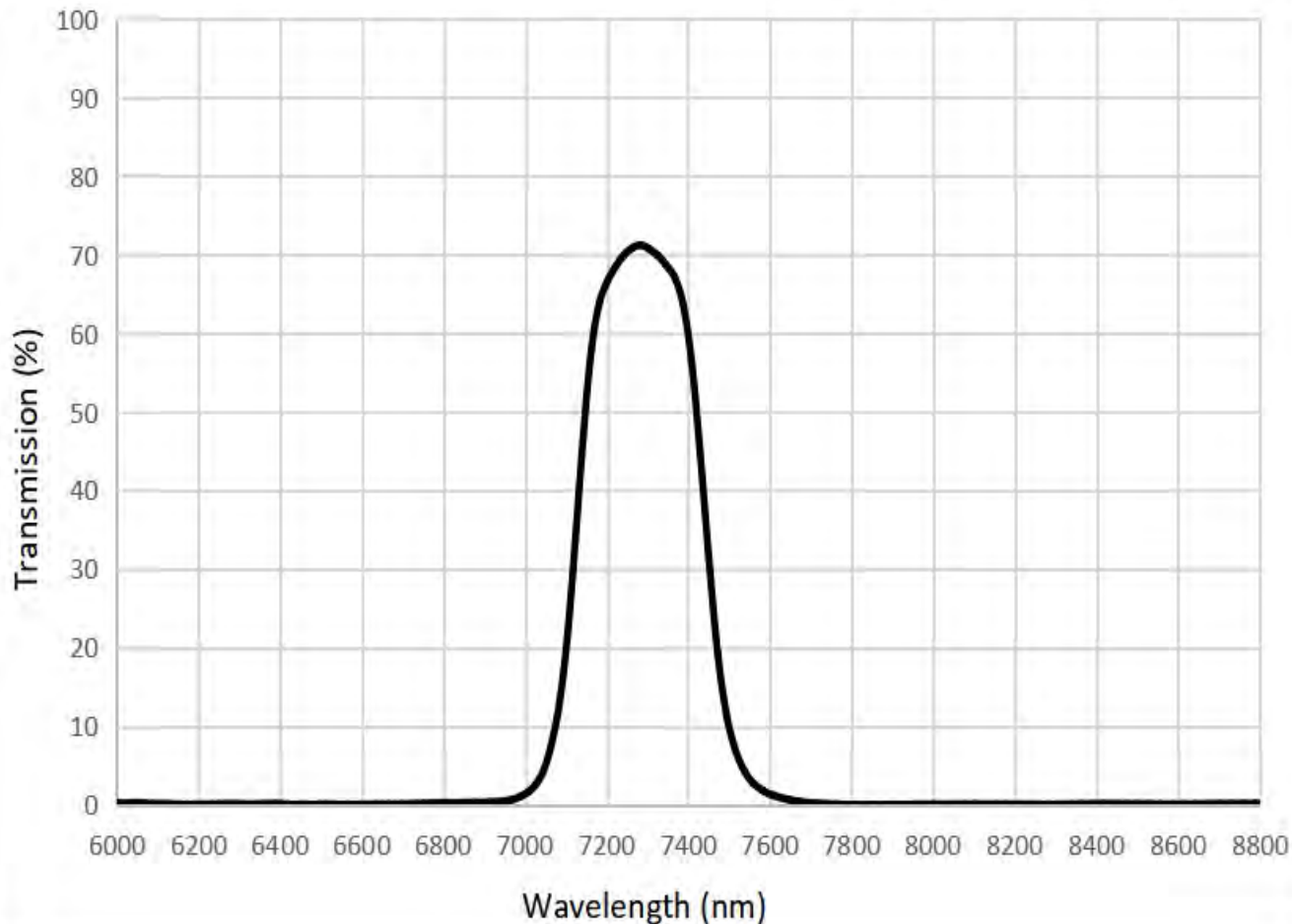
Peak Transmittance (T_p): $> 80\%$

Cutoff range (Except for passband): 400-11000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.



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Name: NBP 7300 300nm

Base material: single-crystal silicon

Center wavelength (CWL): 7300±40nm

Half wave width (FWHM): 300±30nm

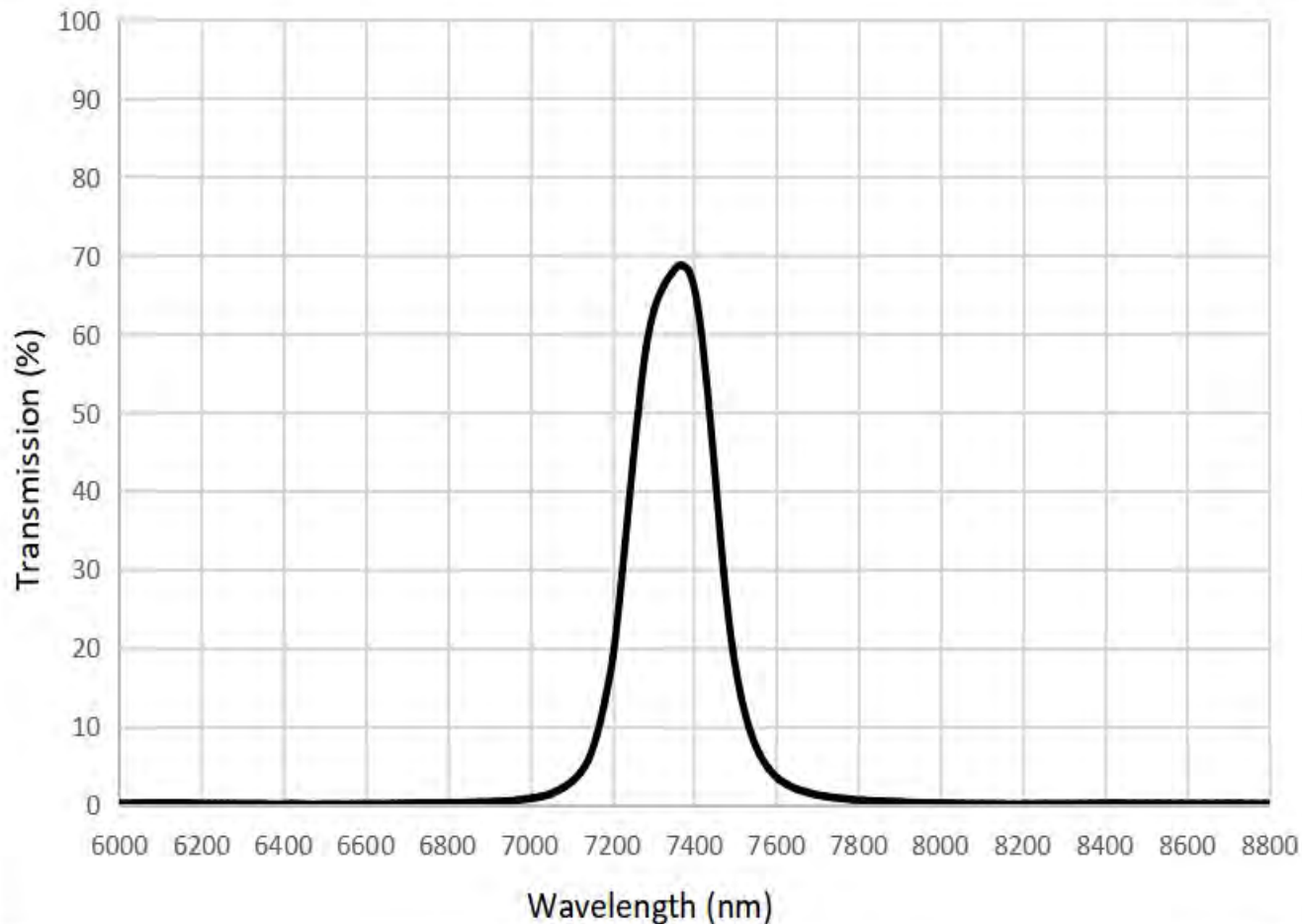
Peak Transmittance (Tp): >70%

Cutoff range (Except for passband): 400-12000nm

Cut-off depth: ≤1%

Base material size: Φ25*0.5mm

Cutting service available.

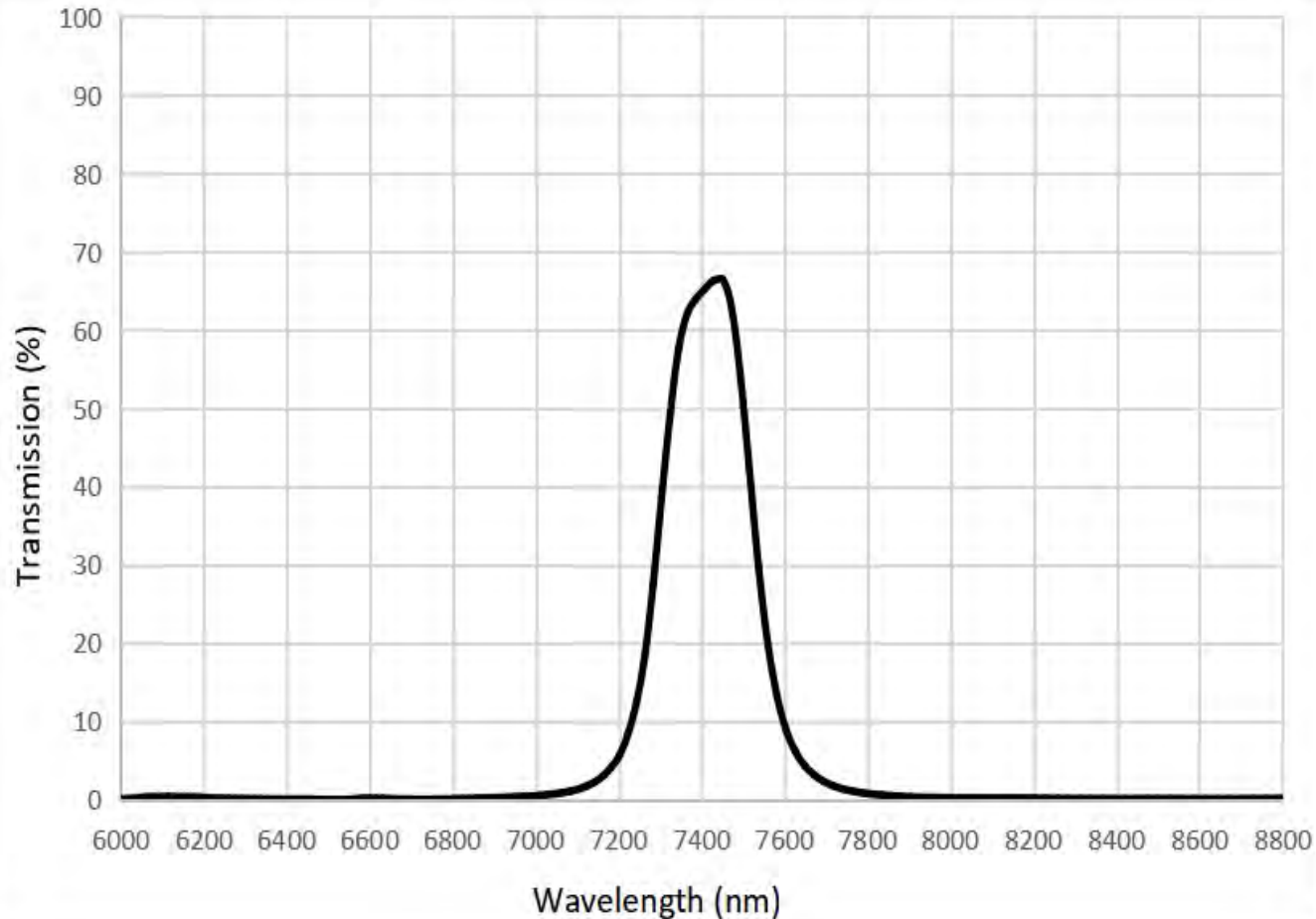


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Name: NBP 7350 200nm
Base material: single-crystal silicon
Center wavelength (CWL): 7350 \pm 30nm
Half wave width (FWHM): 200 \pm 30nm
Peak Transmittance (Tp): > 65%
Cutoff range (Except for passband): 400-12000nm
Cut-off depth: \leq 1%

Base material size: Φ 100*0.5mm

Cutting service available.



Name: NBP 7410 200nm

Base material: single-crystal silicon

Center wavelength (CWL): 7410 ± 30 nm

Half wave width (FWHM): 200 ± 30 nm

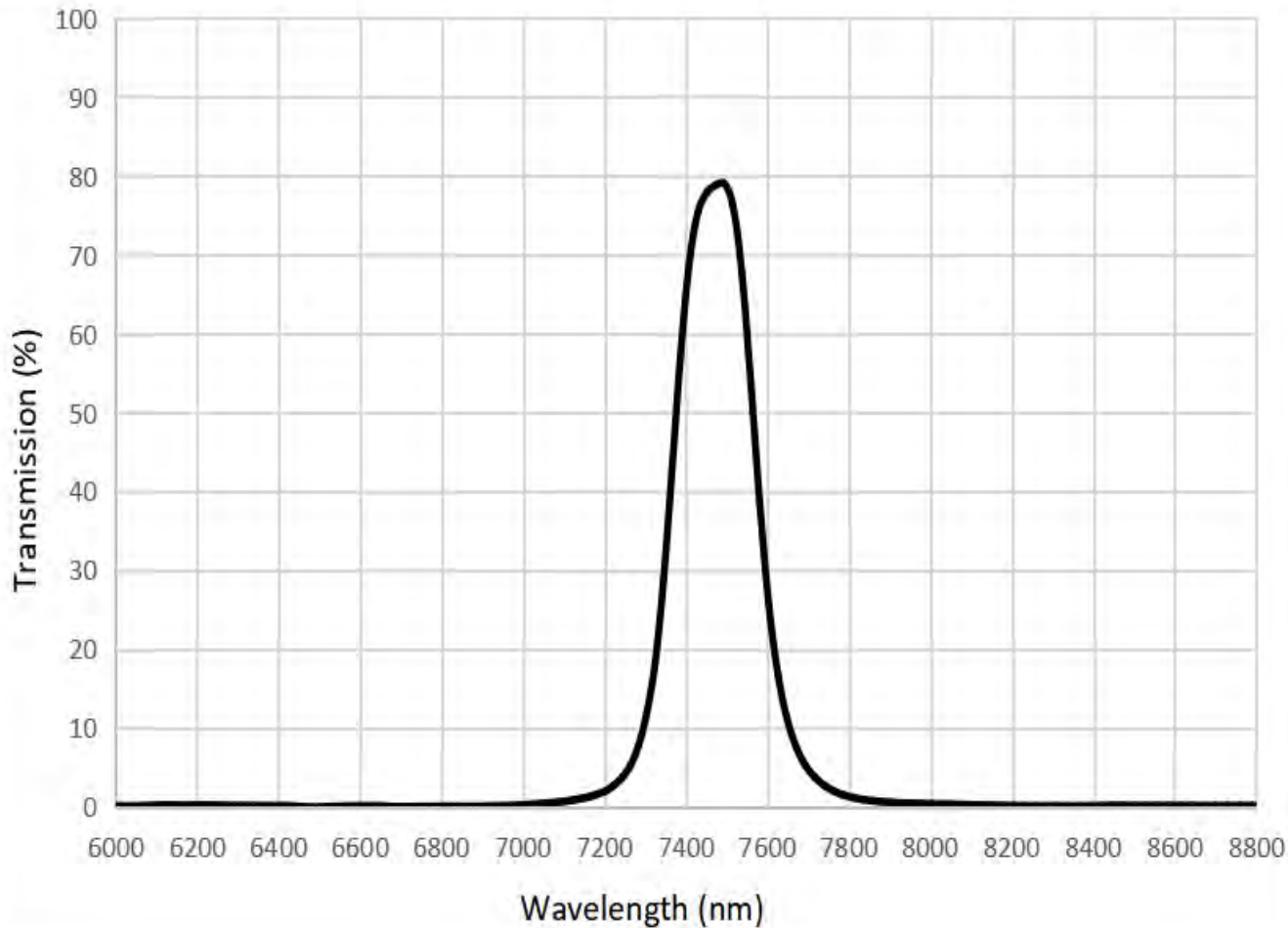
Peak Transmittance (T_p): $> 65\%$

Cutoff range (Except for passband): 400-12000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 7470 200nm

Base material: single-crystal silicon

Center wavelength (CWL): 7470 ± 30 nm

Half wave width (FWHM): 200 ± 30 nm

Peak Transmittance (T_p): $> 75\%$

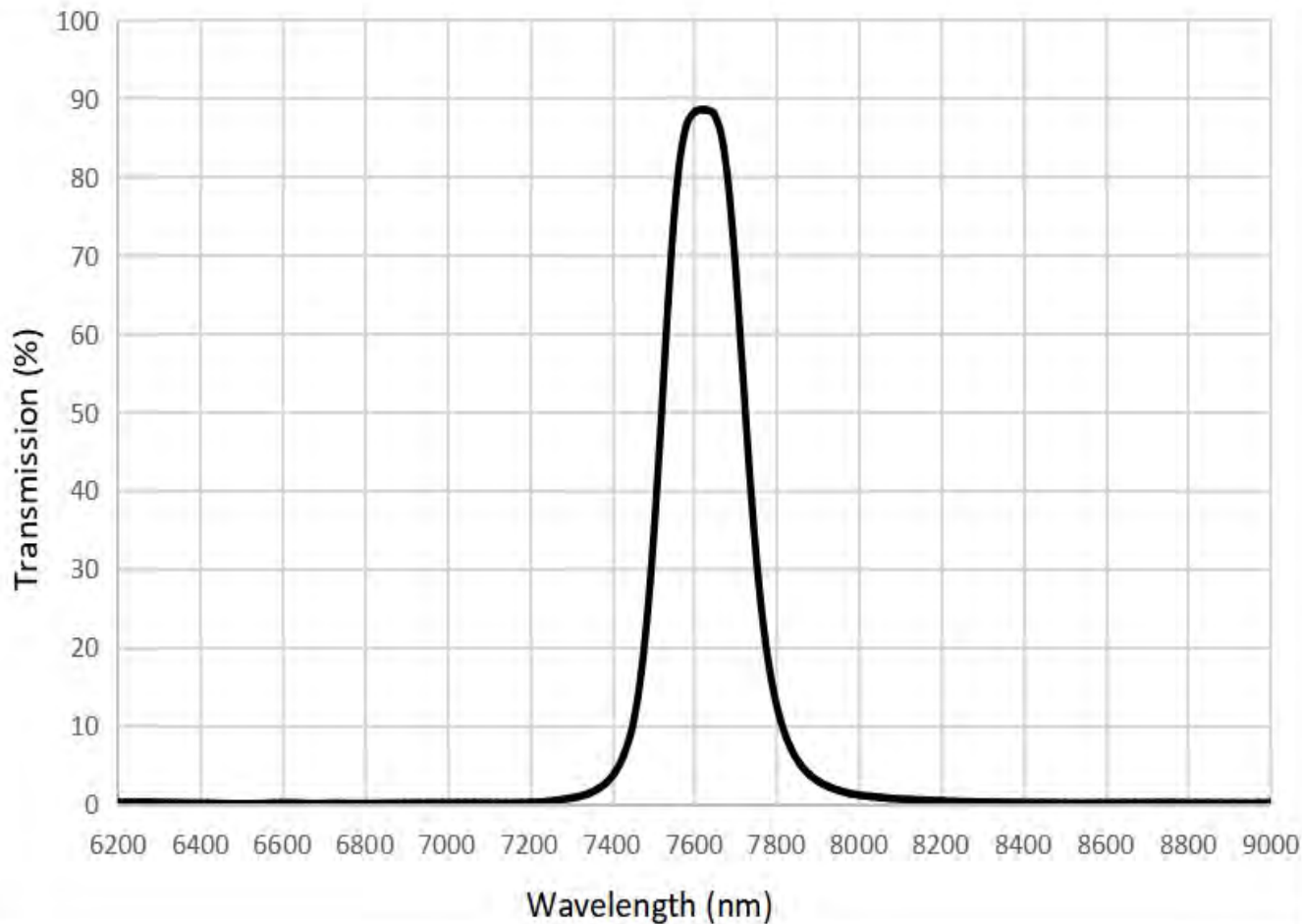
Cutoff range (Except for passband): 400-12000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 * 0.5$ mm

Cutting service available.

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Name: NBP 7625 200nm

Base material: single-crystal silicon

Center wavelength (CWL): 7625 ± 30 nm

Half wave width (FWHM): 200 ± 30 nm

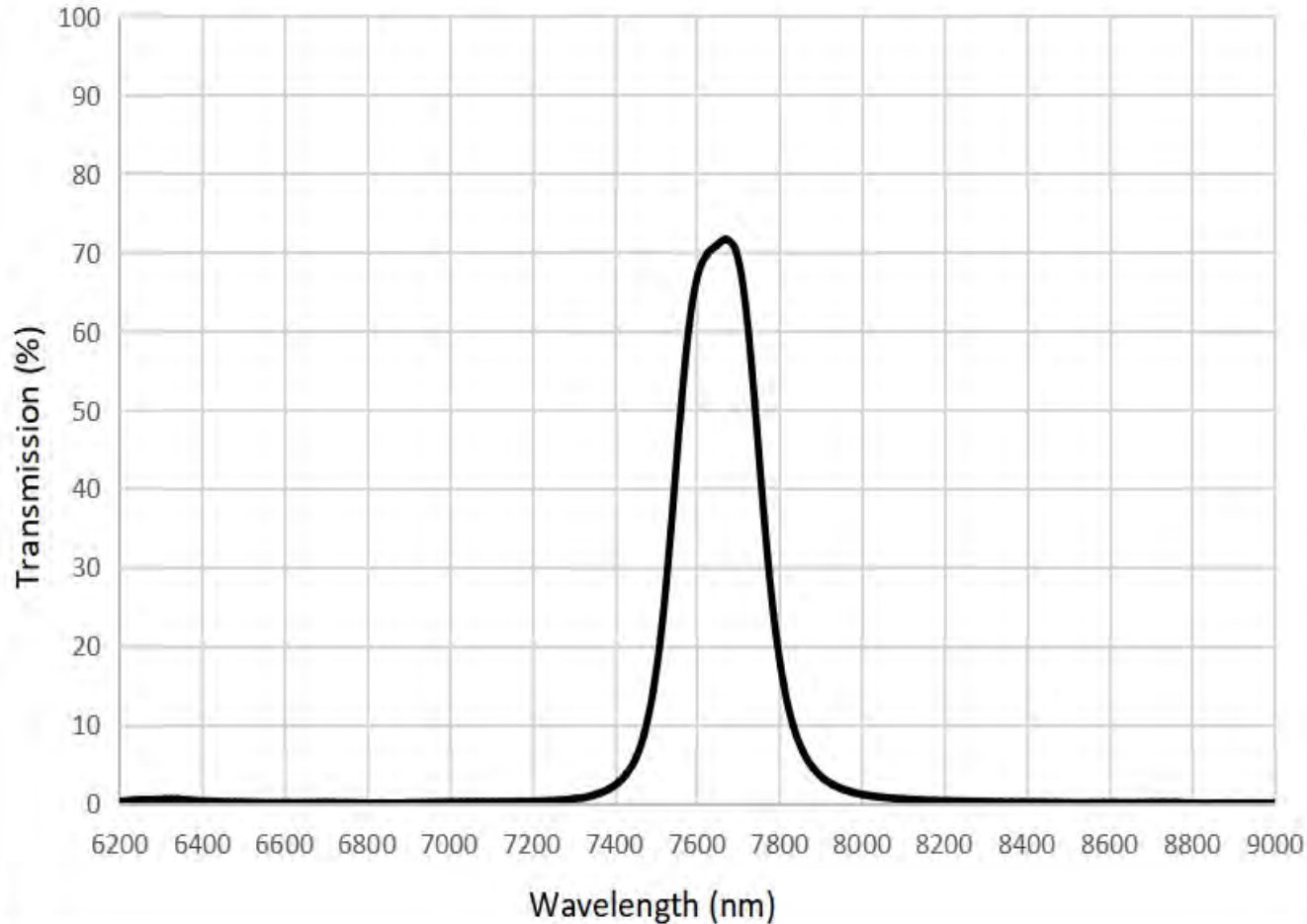
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-12000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 7650 200nm

Base material: single-crystal silicon

Center wavelength (CWL): 7650 ±30nm

Half wave width (FWHM): 200±30nm

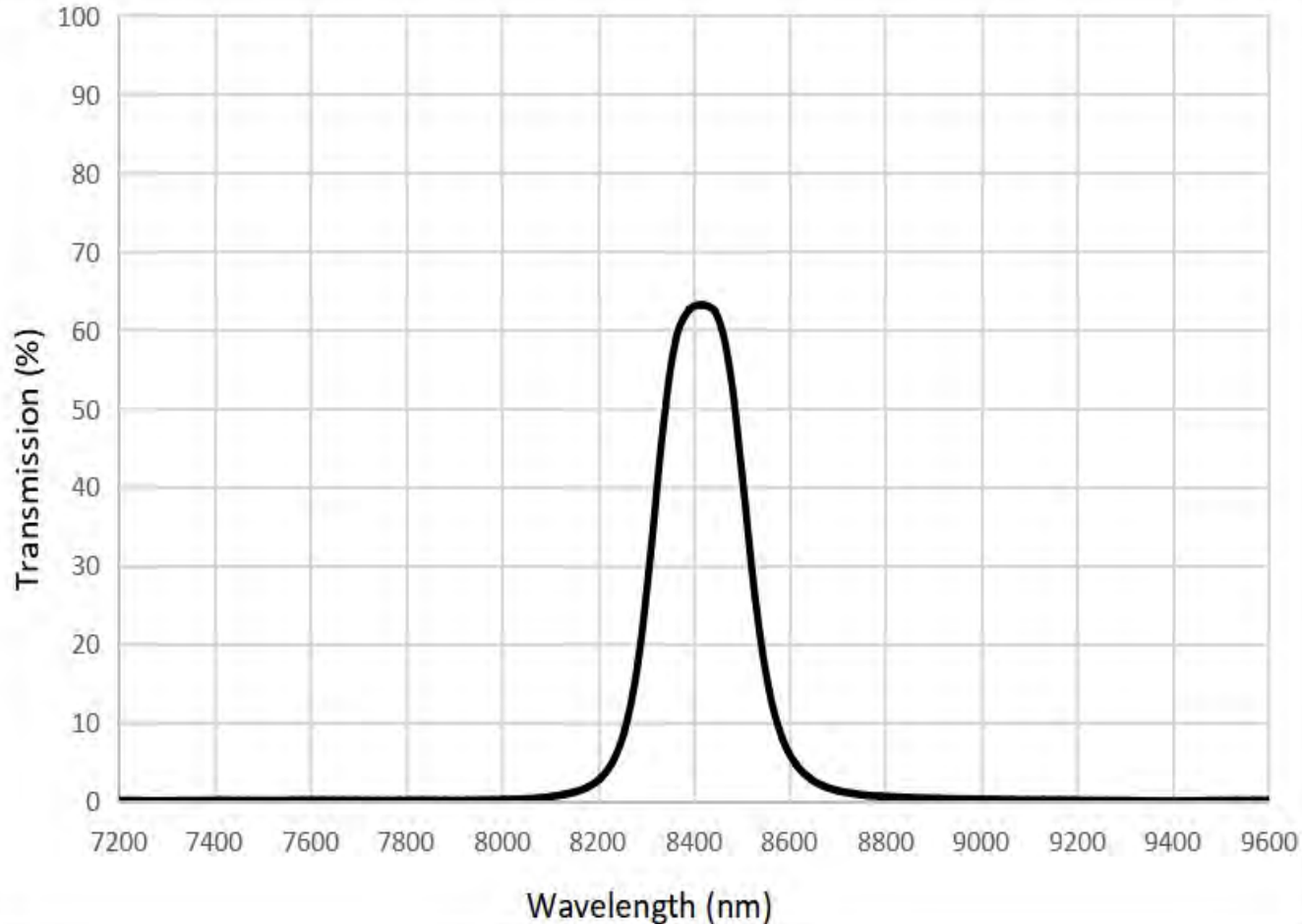
Peak Transmittance (Tp): >70%

Cutoff range (Except for passband): 400-12000nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



Name: NBP 8420 200nm

Base material: single-crystal silicon

Center wavelength (CWL): 8420 ± 40 nm

Half wave width (FWHM): 200 ± 30 nm

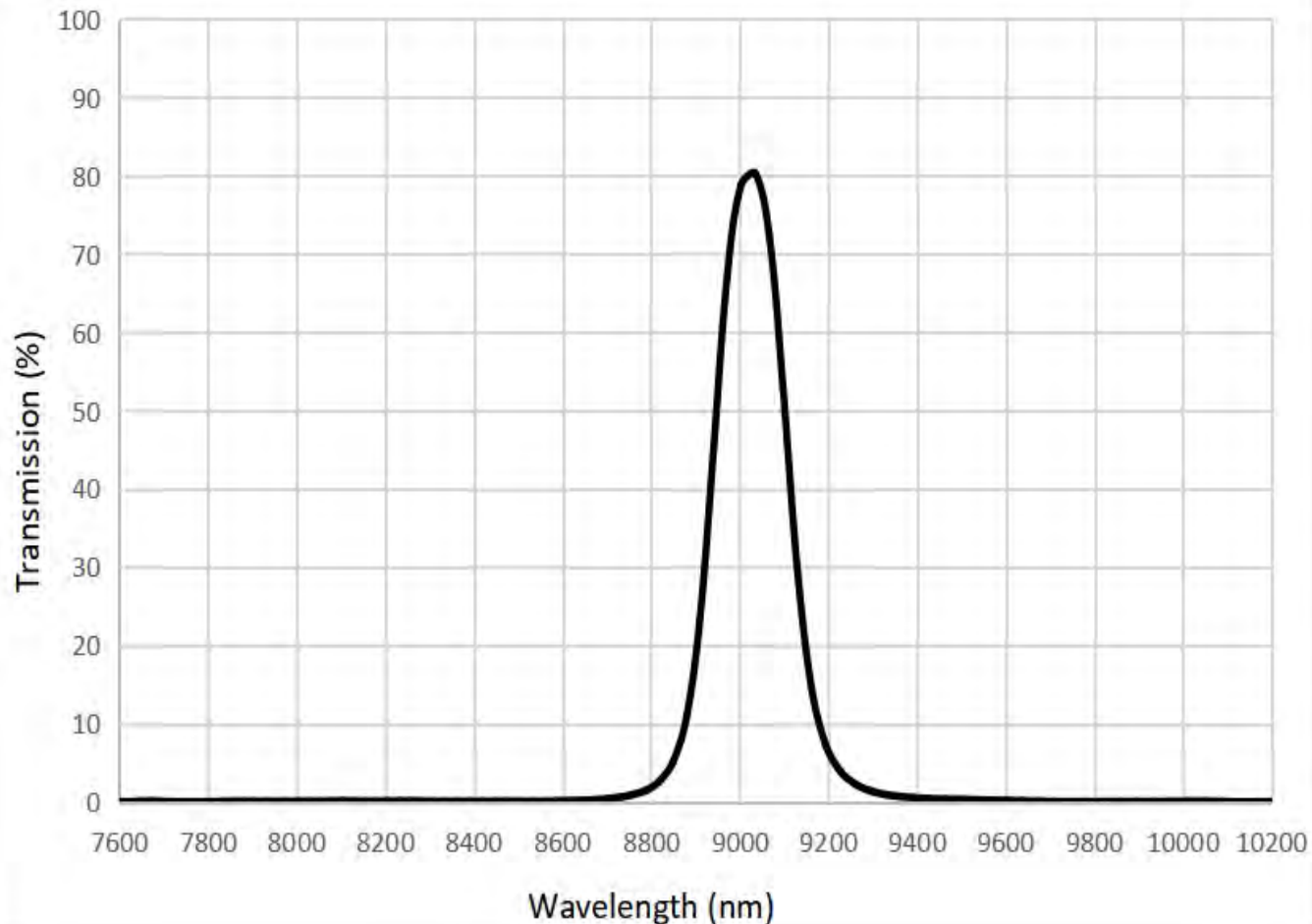
Peak Transmittance (T_p): $> 60\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 9020 180nm

Base material: Zone melting silicon

Center wavelength (CWL): 9020 ± 30 nm

Half wave width (FWHM): 180 ± 30 nm

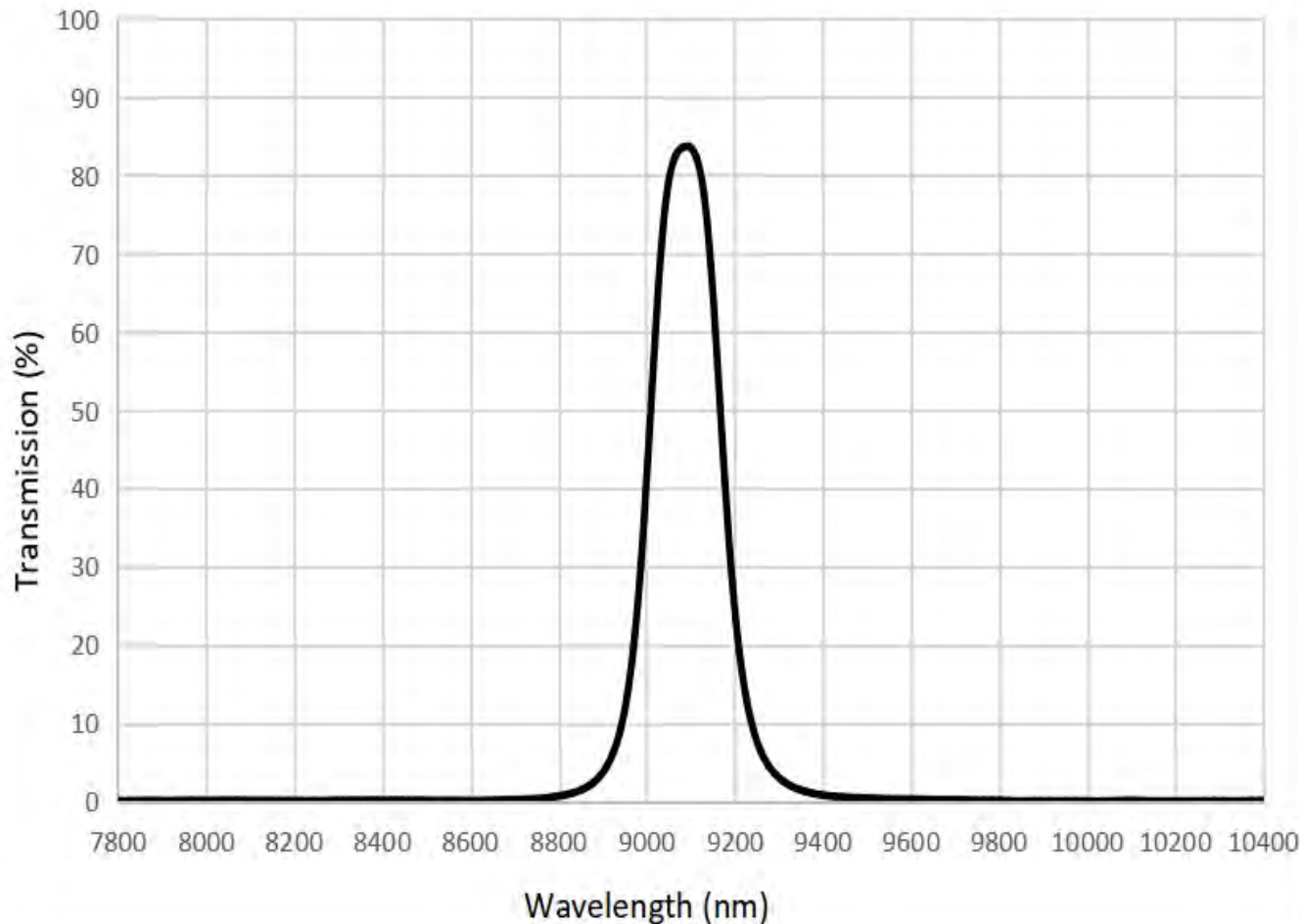
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 9080 180nm

Base material: Zone melting silicon

Center wavelength (CWL): 9080 ± 30 nm

Half wave width (FWHM): 180 ± 30 nm

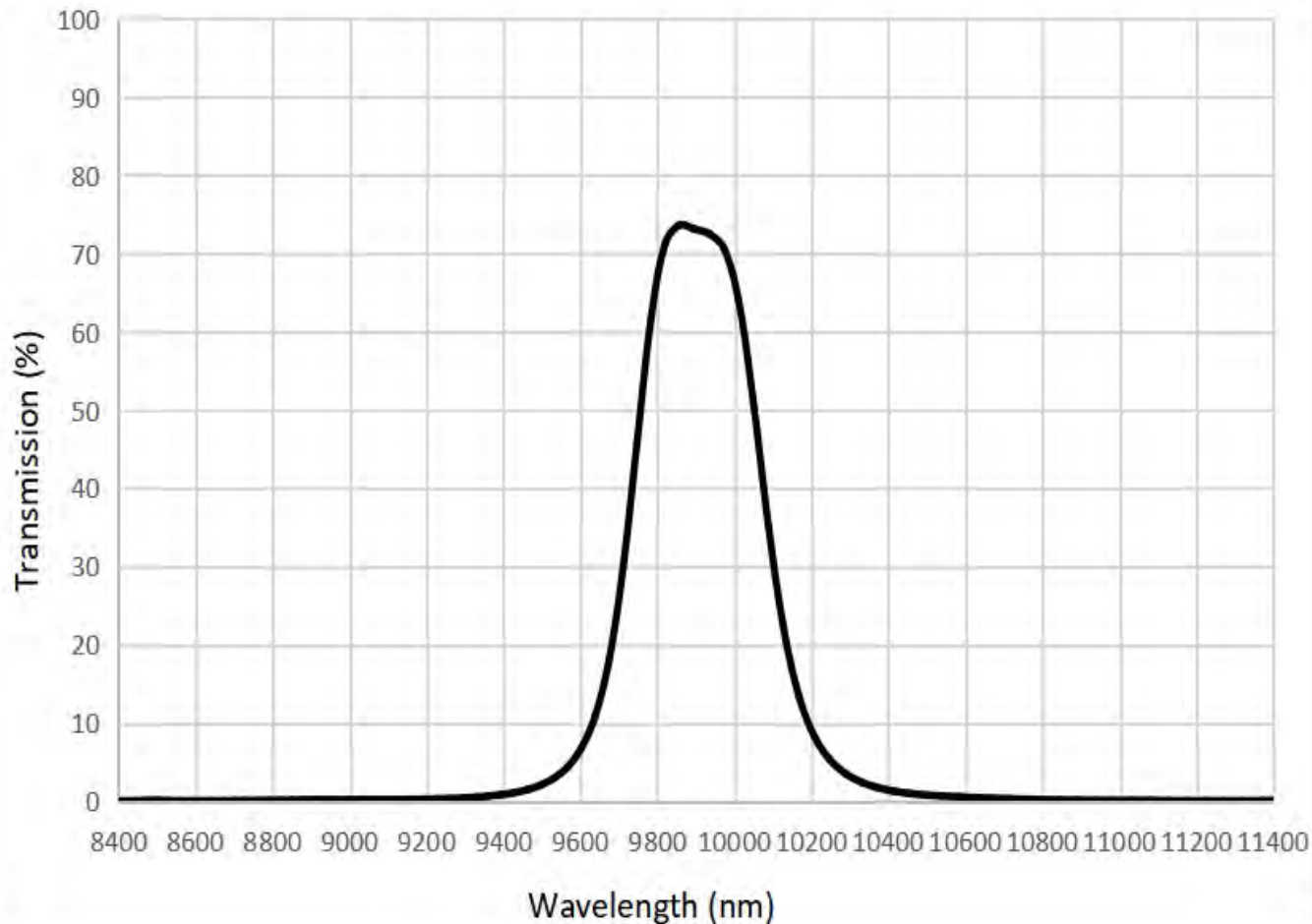
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



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Name: NBP 9900 370nm

Base material: single-crystal silicon

Center wavelength (CWL): 9900 ± 30 nm

Half wave width (FWHM): 370 ± 20 nm

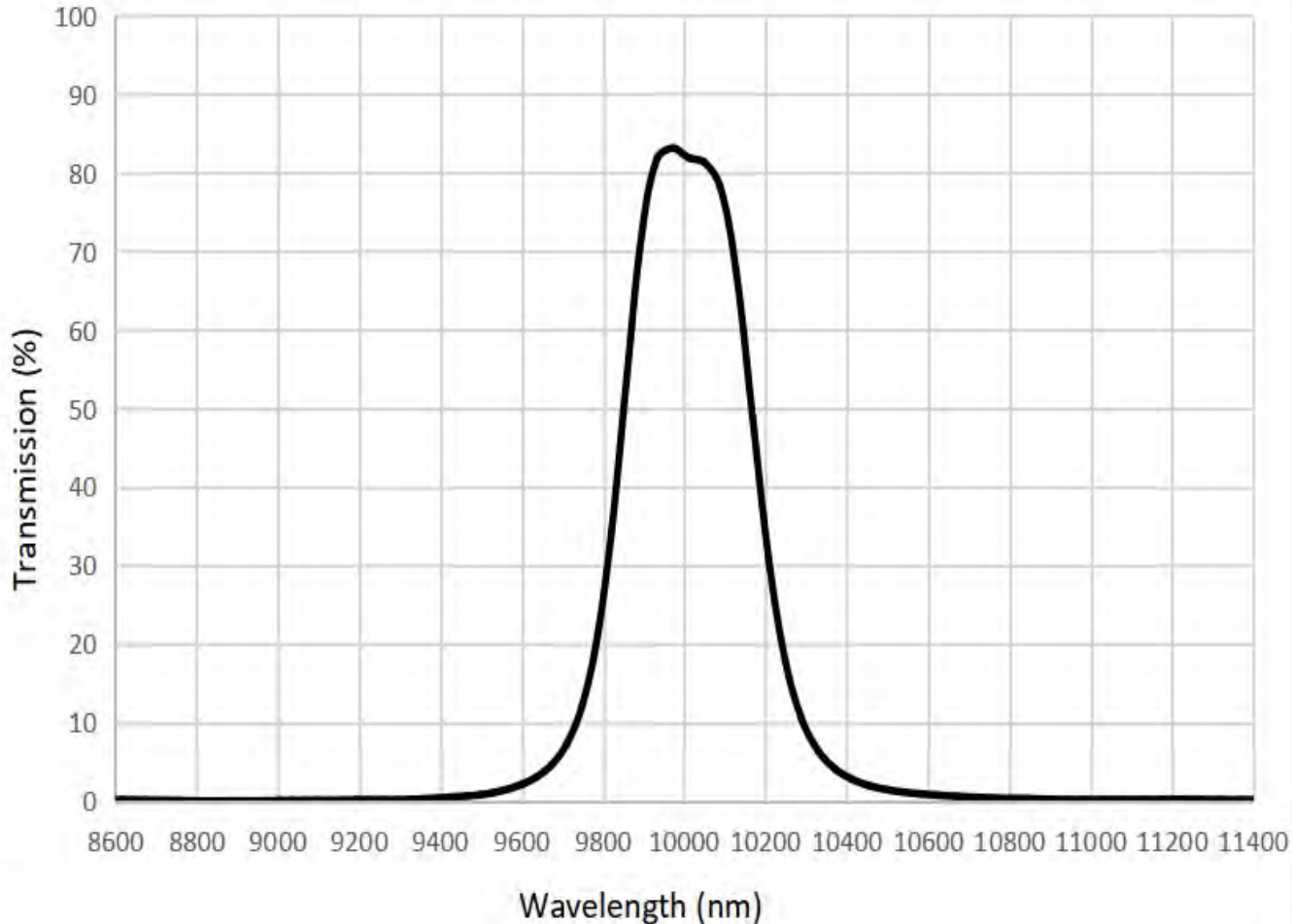
Peak Transmittance (T_p): $> 70\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 * 0.5$ mm

Cutting service available.



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Name: NBP 10000 370nm

Base material: single-crystal silicon

Center wavelength (CWL): 10000 ± 40 nm

Half wave width (FWHM): 370 ± 30 nm

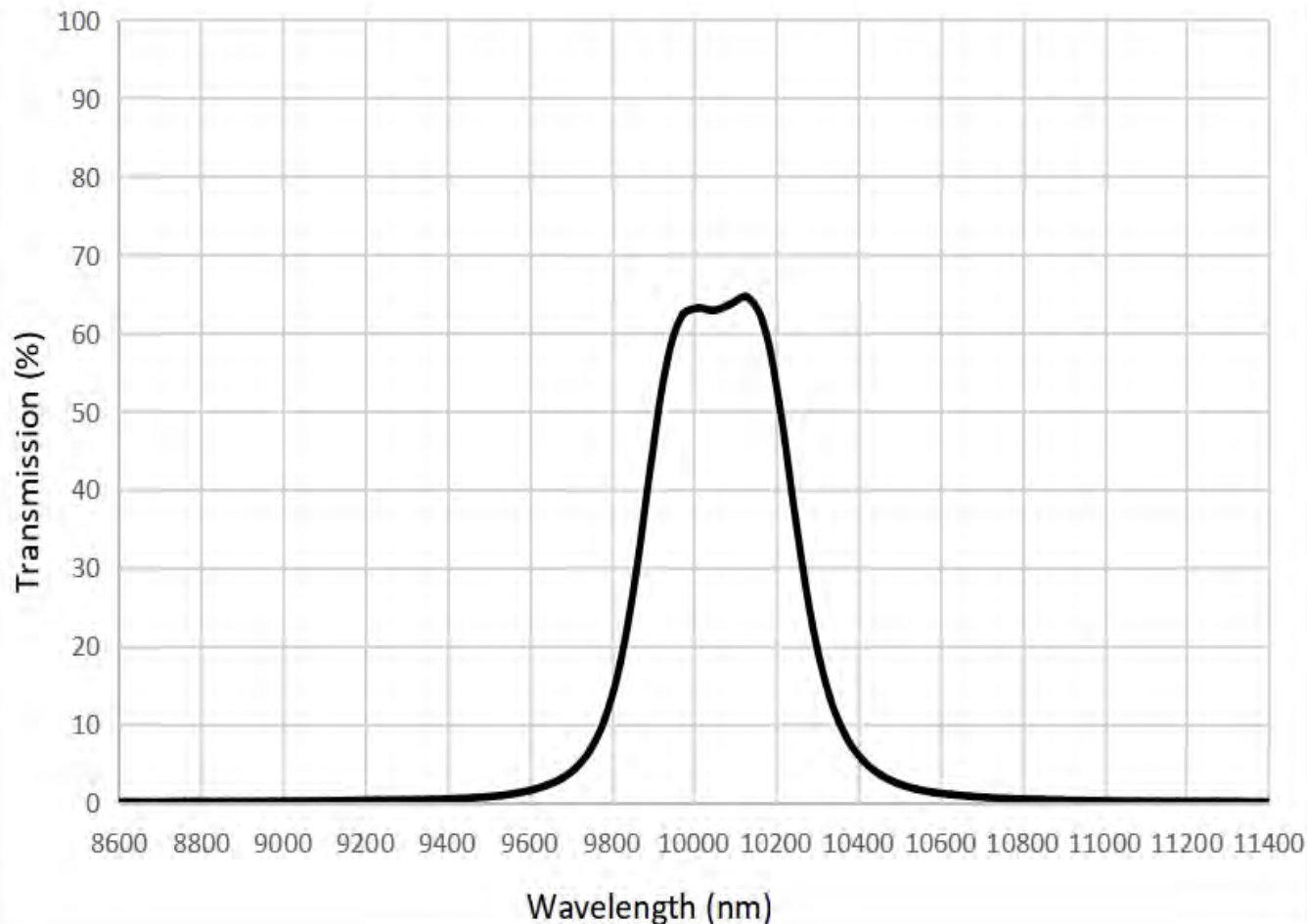
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 10050 370nm

Base material: single-crystal silicon

Center wavelength (CWL): 10050 ± 40

Half wave width (FWHM): 370 ± 30 nm

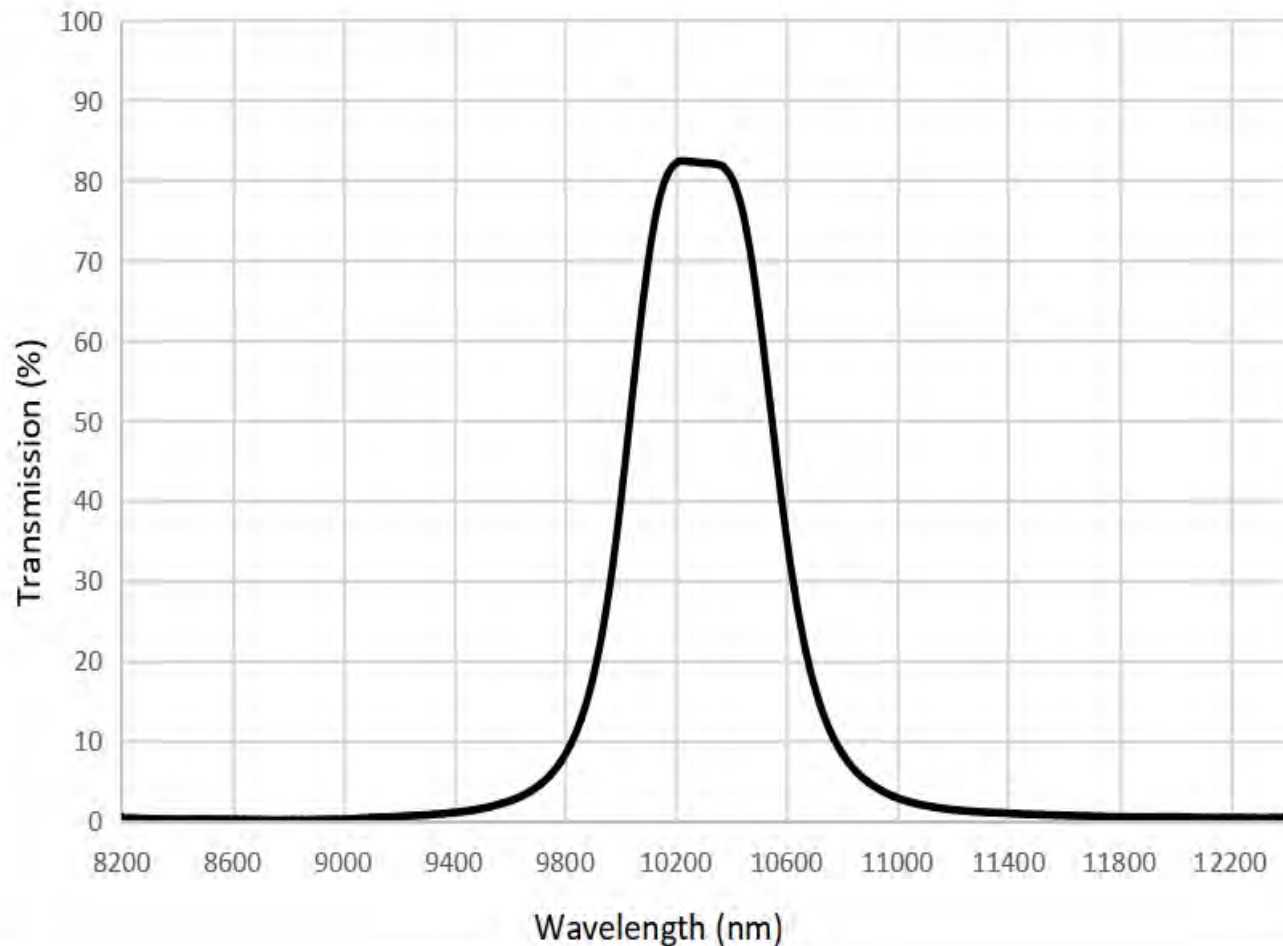
Peak Transmittance (T_p): $> 60\%$

Cutoff range (Except for passband): 400-16000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 10270 600nm

Base material: single-crystal silicon

Center wavelength (CWL): 10270 ± 40 nm

Half wave width (FWHM): 600 ± 30 nm

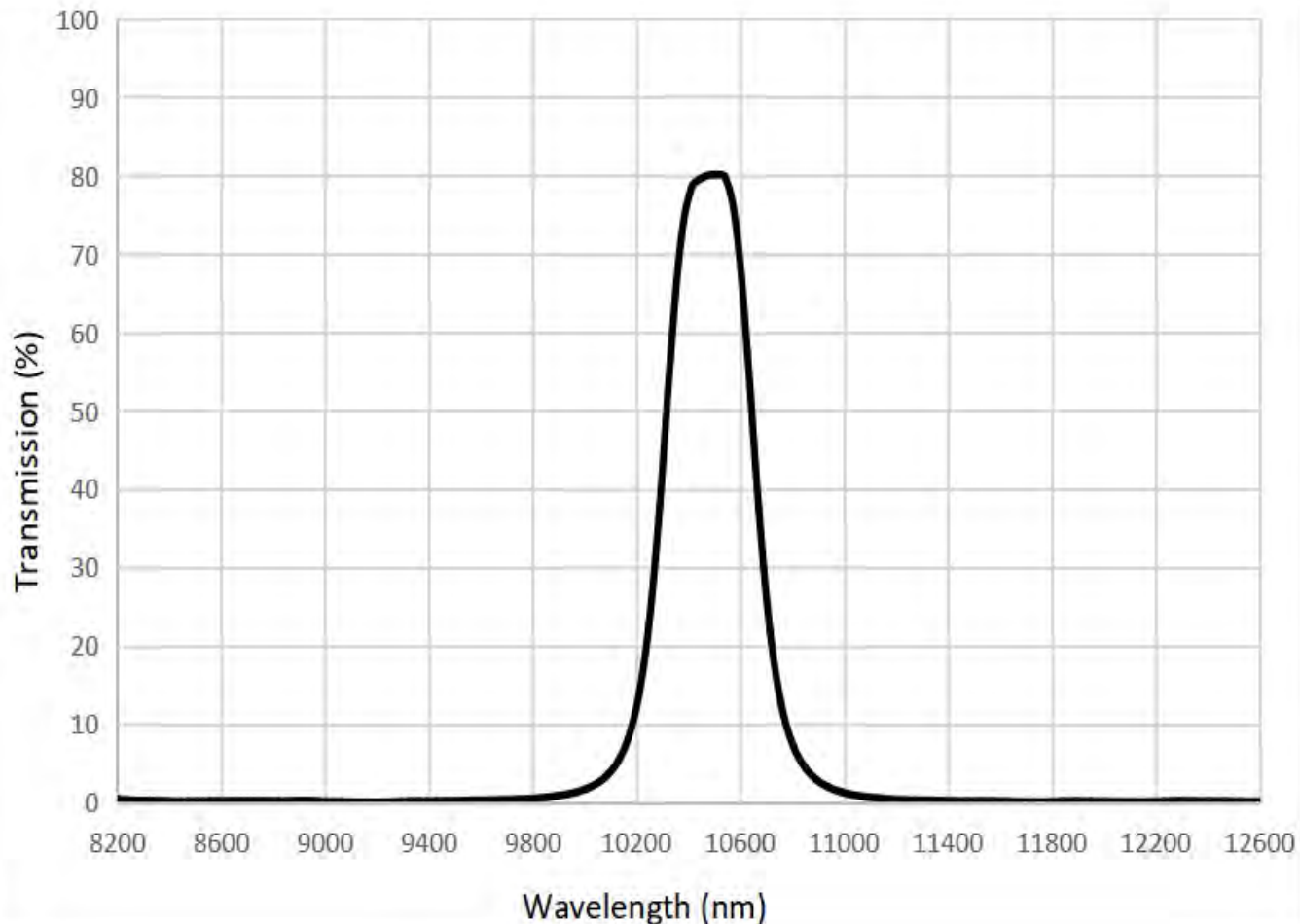
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-13500nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 10460 370nm

Base material: single-crystal silicon

Center wavelength (CWL): 10460 ± 40 nm

Half wave width (FWHM): 370 ± 30 nm

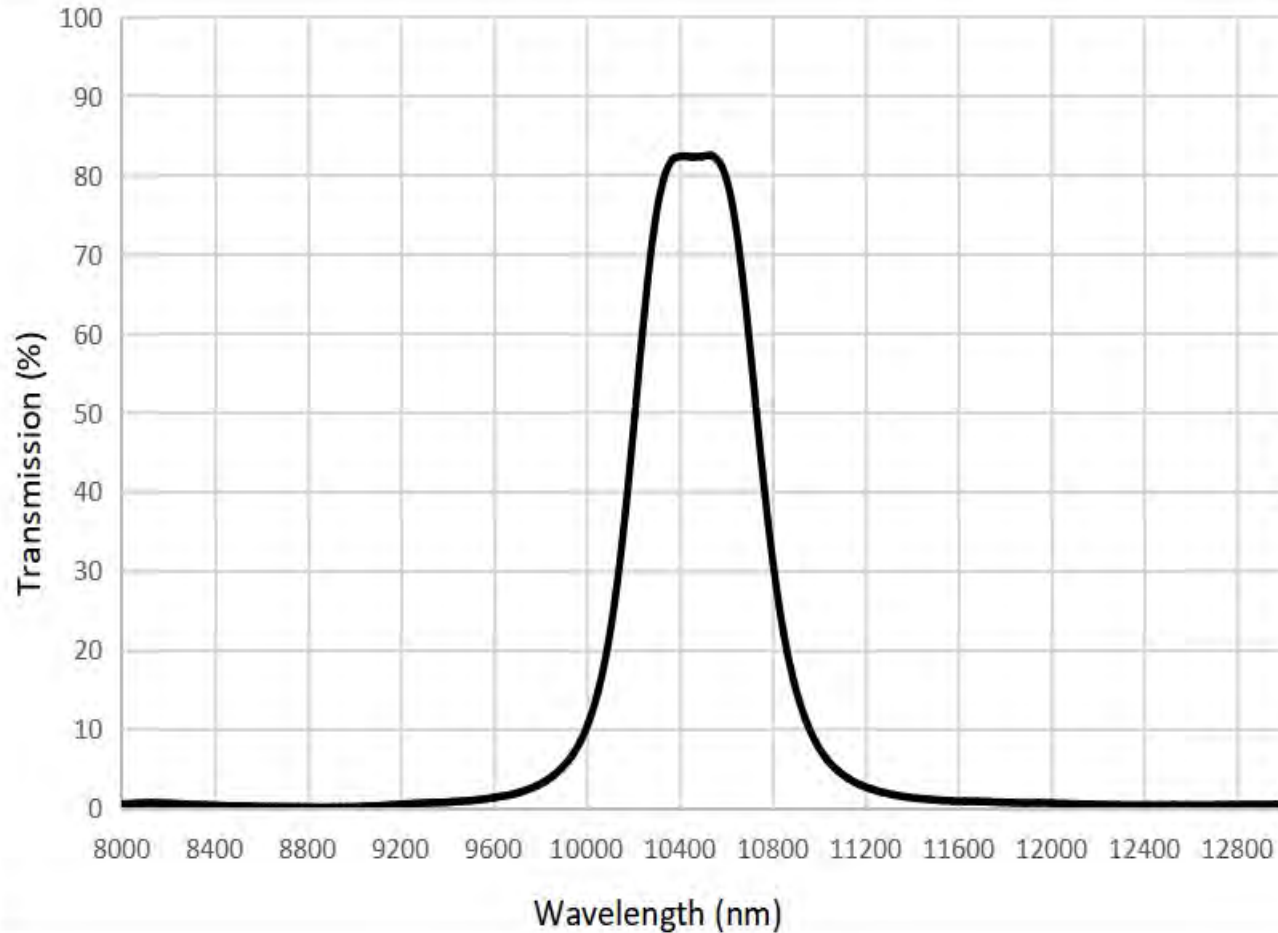
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-14000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 10500 600nm

Base material: single-crystal silicon

Center wavelength (CWL): 10500 ± 50 nm

Half wave width (FWHM): 600 ± 40 nm

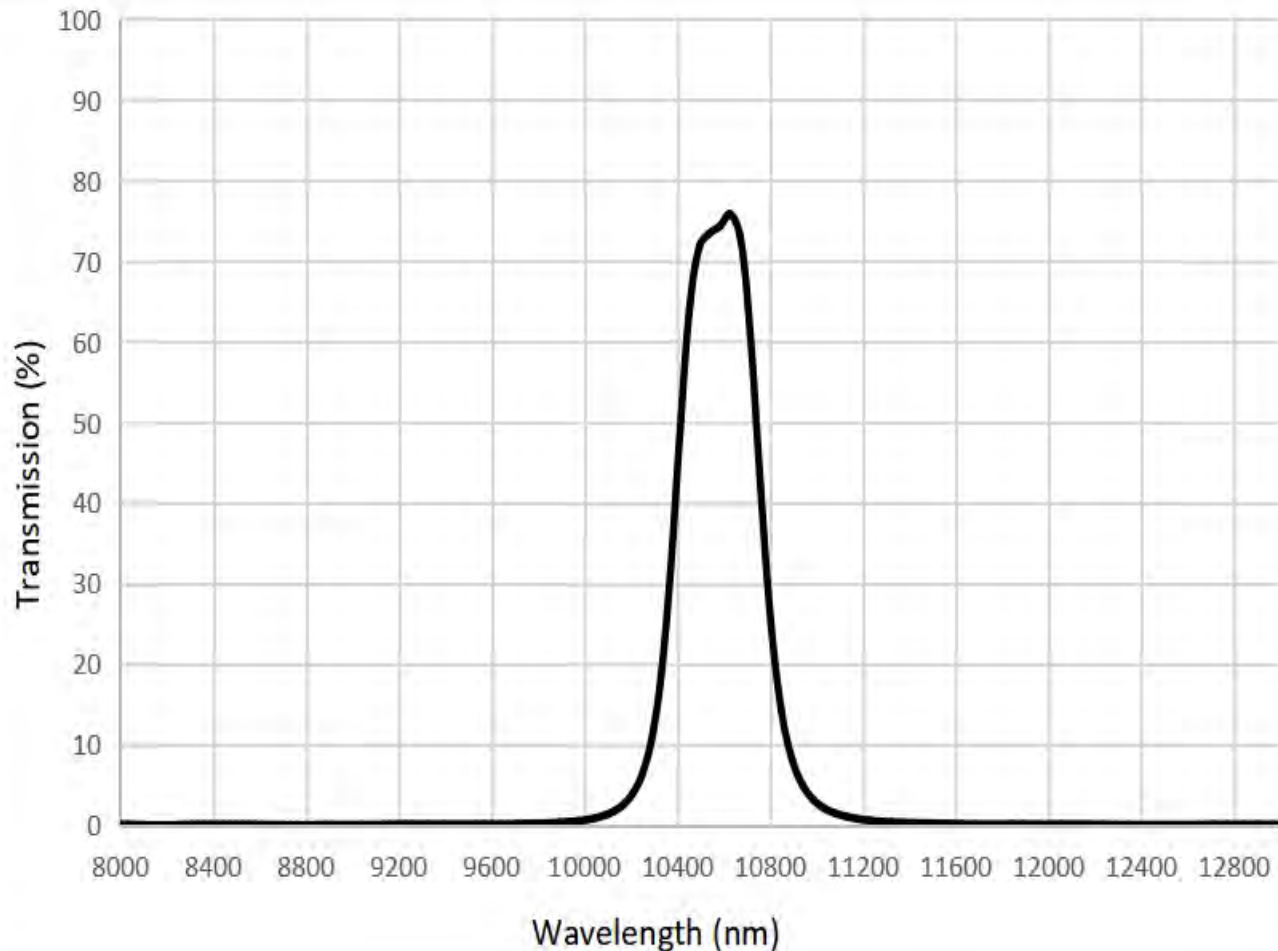
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-13500nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



Name: NBP 10560 370nm

Base material: single-crystal silicon

Center wavelength (CWL): 10560 ± 40 nm

Half wave width (FWHM): 370 ± 30 nm

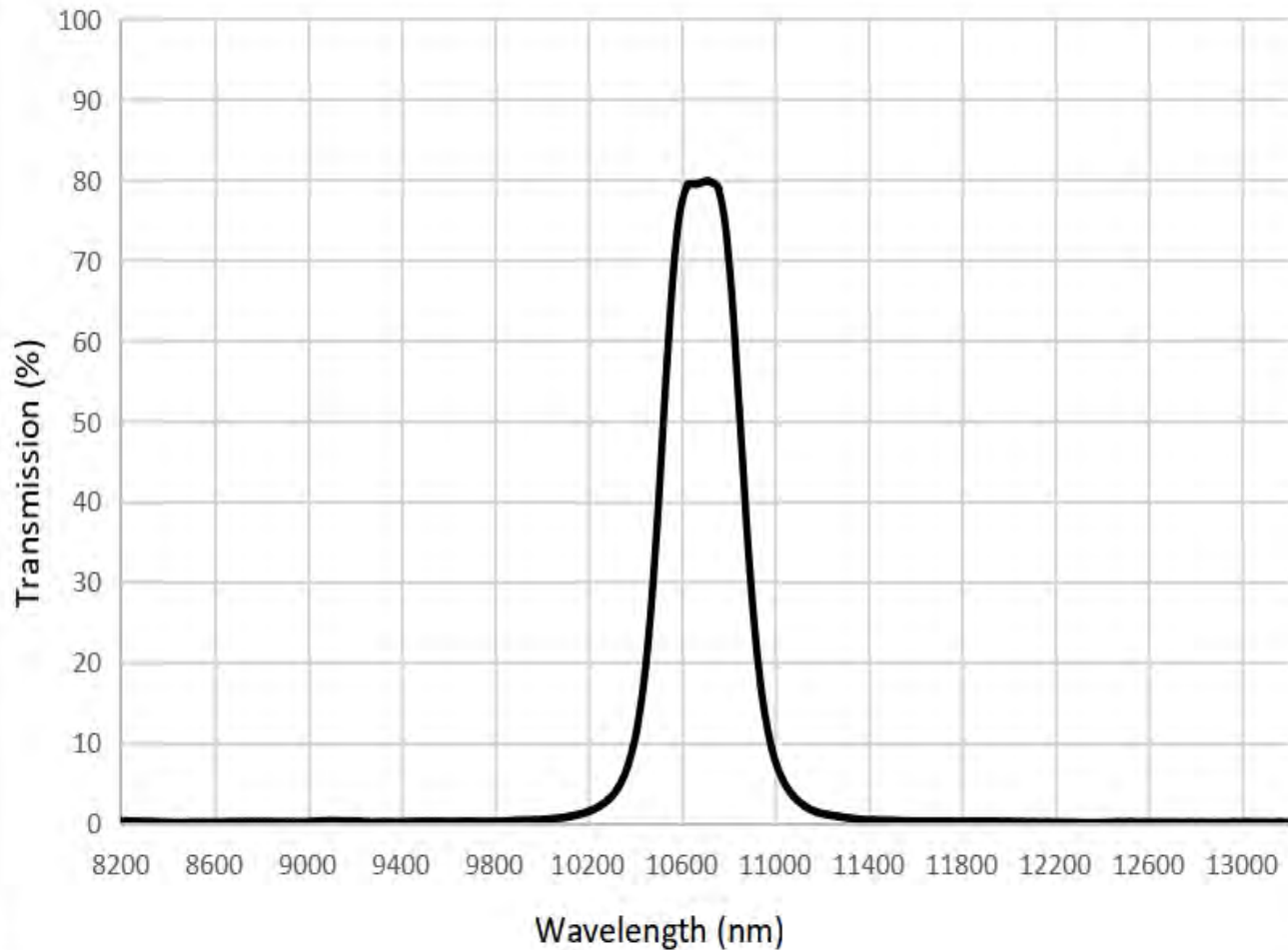
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-18000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



MFrontier
美思先端

Name: NBP 10700 370nm

Base material: single-crystal silicon

Center wavelength (CWL): 10700 ± 40 nm

Half wave width (FWHM): 370 ± 30 nm

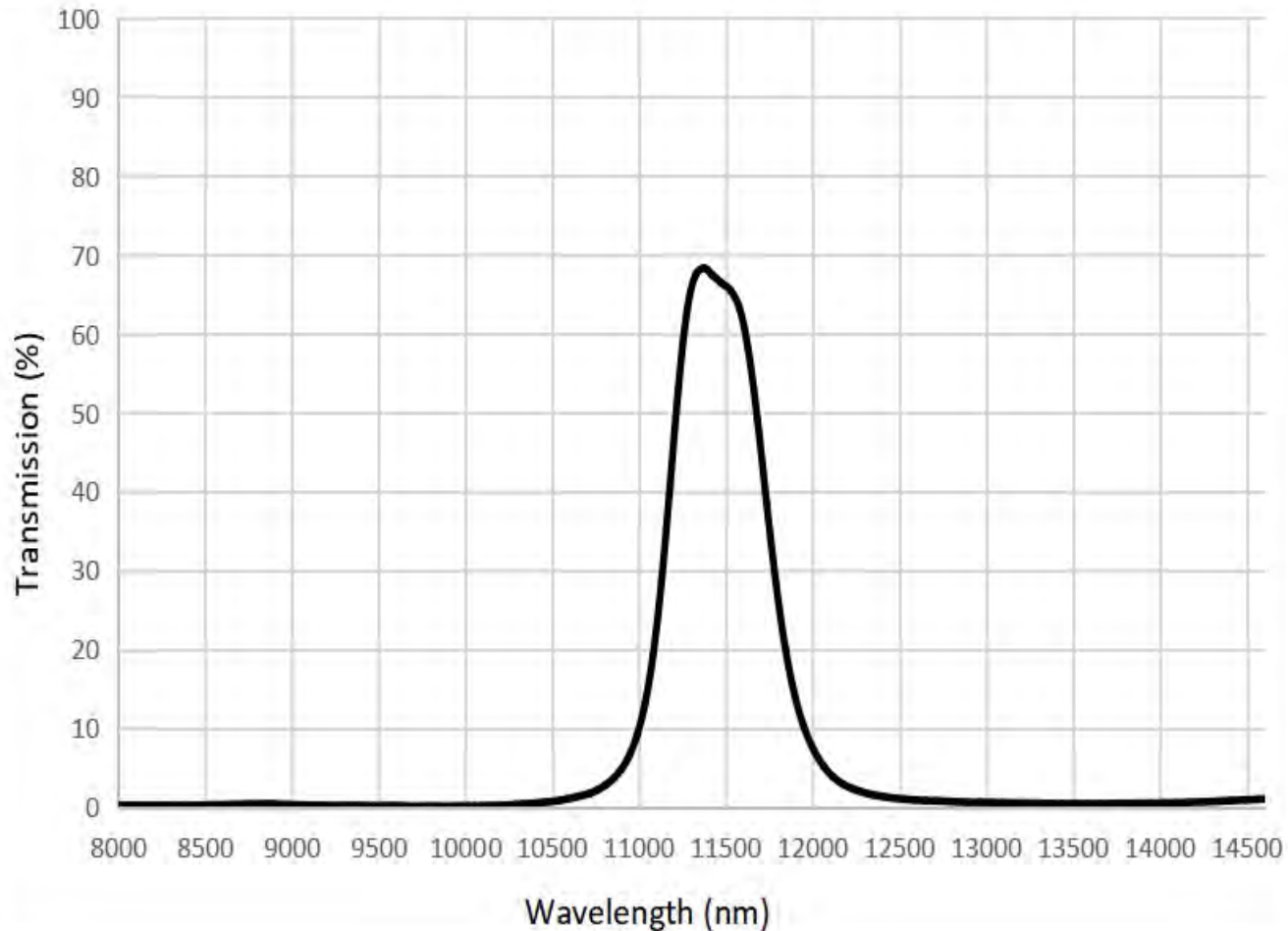
Peak Transmittance (T_p): $> 75\%$

Cutoff range (Except for passband): 400-14000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 100 \times 0.5$ mm

Cutting service available.



MFrontier
美思先端

Name: NBP 11500 600nm

Base material: single-crystal silicon

Center wavelength (CWL): 11500 ±50nm

Half wave width (FWHM): 600±40nm

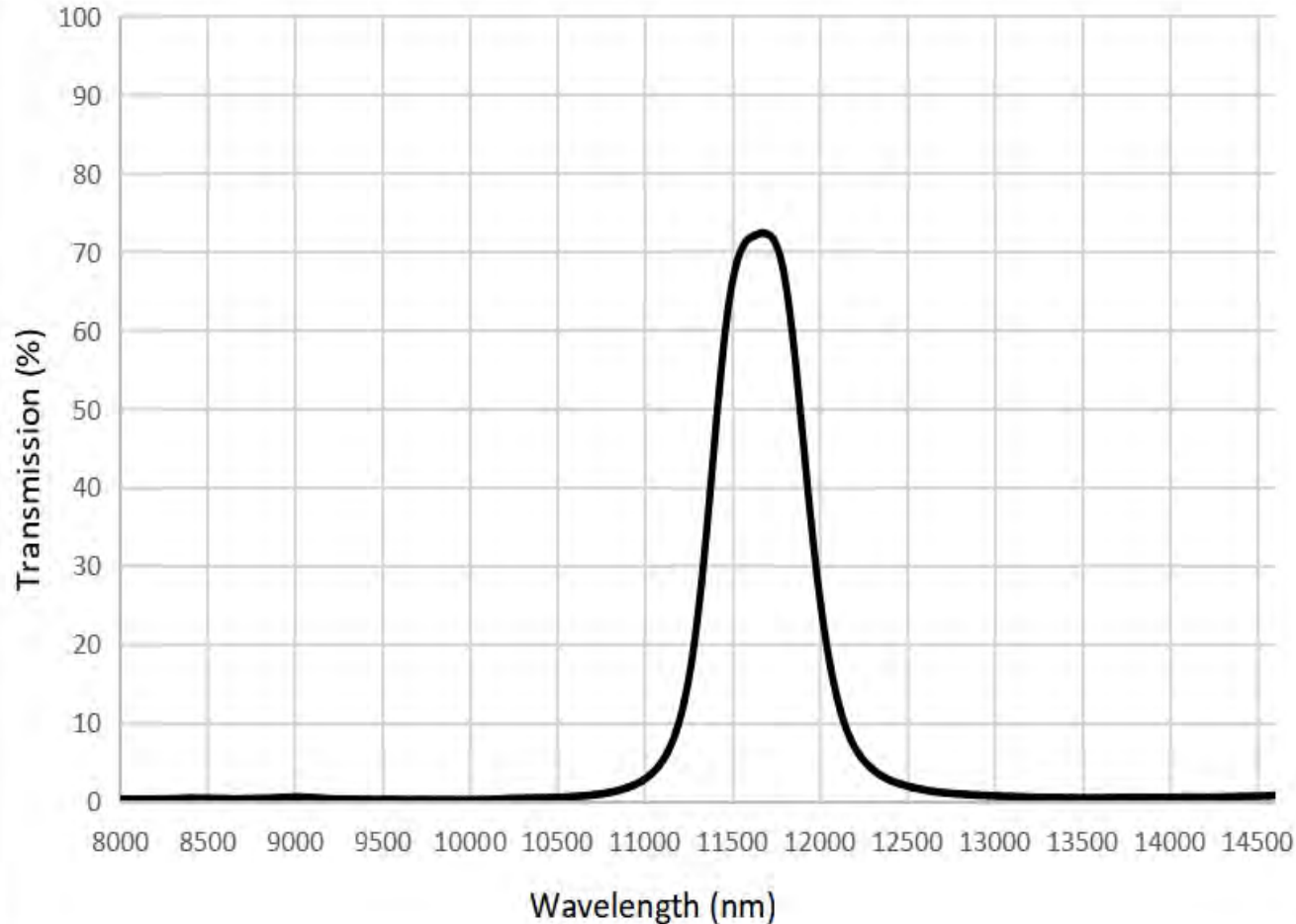
Peak Transmittance (Tp): > 65%

Cutoff range (Except for passband): 400-14500nm

Cut-off depth: ≤1%

Base material size: Φ100*0.5mm

Cutting service available.



Name: NBP 11700 600nm

Base material: single-crystal silicon

Center wavelength (CWL): 11700±50nm

Half wave width (FWHM): 600±40nm

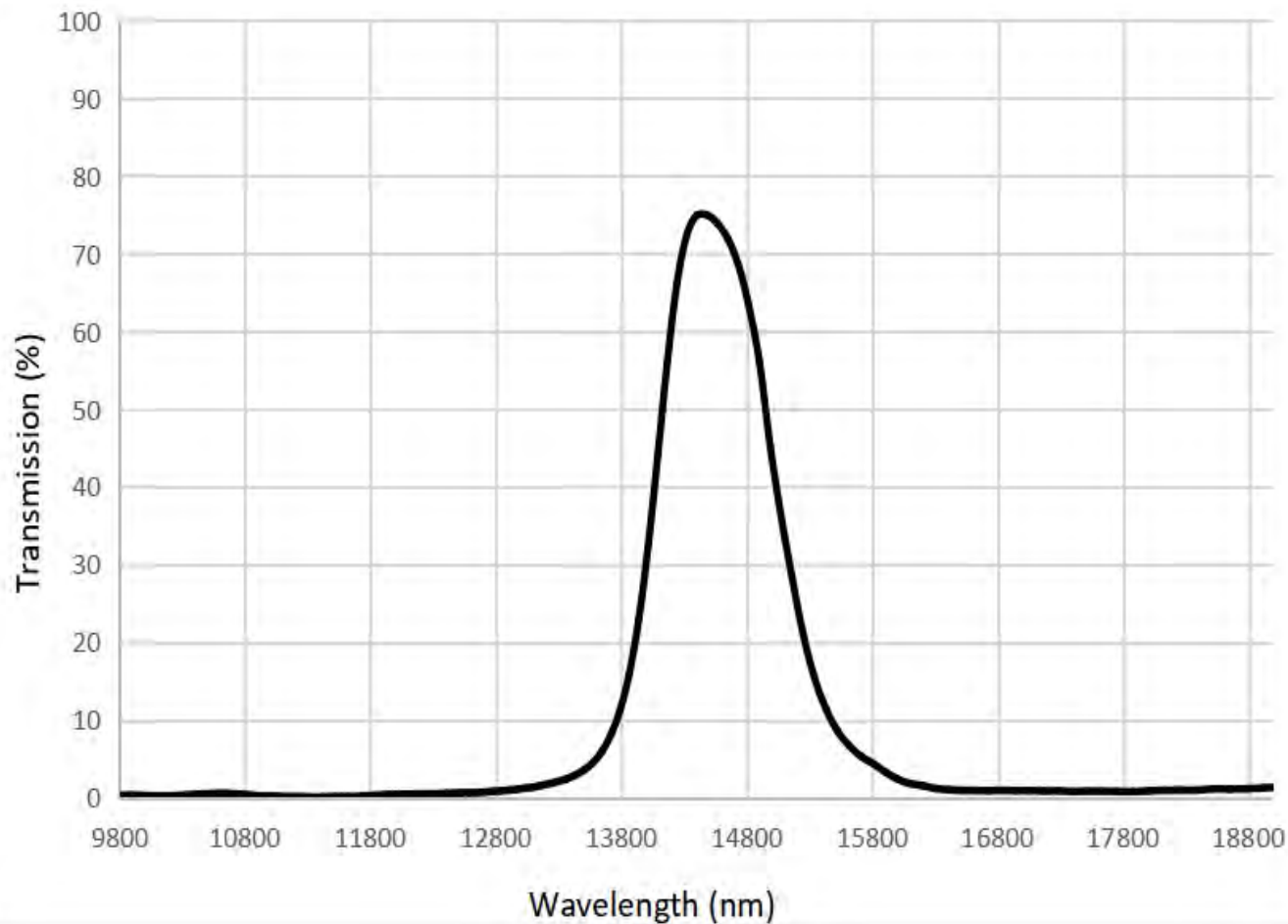
Peak Transmittance (Tp): > 65%

Cutoff range (Except for
passband): 400-14500nm

Cut-off depth: ≤1%

Base materials size size: Φ100*0.5mm

Cutting service available.



Name: NBP 14500 1000nm

Base material: single-crystal silicon

Center wavelength (CWL): 14500 ± 50 nm

Half wave width (FWHM): 1000 ± 50 nm

Peak Transmittance (T_p): $> 70\%$

Cutoff range (Except for passband): 400-19000nm

Cut-off depth: $\leq 1\%$

Base material size: $\Phi 25 \times 0.5$ mm

Cutting service available.